

(25%)

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-: HAND WRITTEN NOTES:-

OF

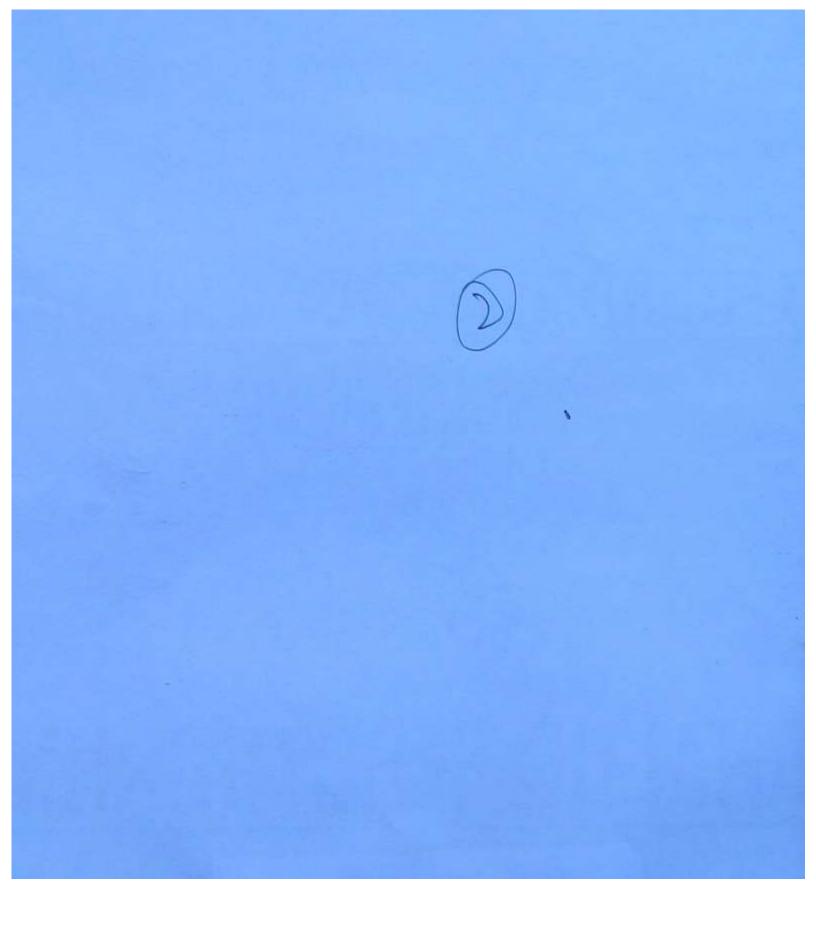
# ELECTRONICS & COMMUNICATION ENGINEERING



-: SUBJECT:-

# E ANALOG ELECTRONICS

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Syllabu :-

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1) Op-Amp

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2) Linear Wave Shaping circuit (Taub)

3> Schimitt Trigger

4> Waveform Generator

- Multihibrators

- Bistable Multivibrator.

- Monostable

- Astable 11 (Square Wave Generator)

- Triangular Wave Generator

5) Diode Circuits

- Rectifiers & filters

- Precision Rectifier

- Cliffer & chambers

- Voltage Doublers.

6> Bipolar Junction Translutors.

- Transistor Biasing & Stablisation

- Current Mirror Circuit

- Voltage Regulator

7) Muttivibrator by using BIT. (Toub)

8) Amplifiers—

- Lore frequency Analysis of 13.7.

- High "

- Multistage Amb.

- feedback

Low frequency analysis of FET

- Oscillators (Sinusoidal)

- Power Amplifiers

9).555 - Timer

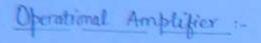
- Multivibrators

Books

- Millman - Halkias - Yellow Pad.

- Pulse Digital & Switching circult

- Millman & Taub

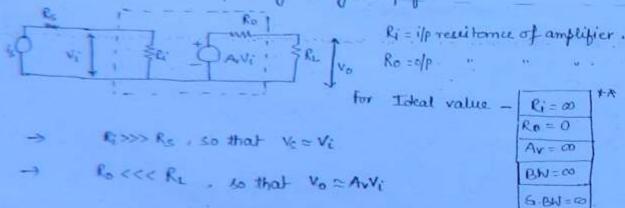




$$\Rightarrow V_i \longrightarrow V_{o} | V_{o} | V_{o} | V_{o}$$

$$\Rightarrow Av = \frac{V_{o}}{V_i} = Gain.$$

- Equivalent circuit for any voltage amplifier-



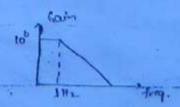
- \* To get Av 00, multistaging is done but the But will to
- of progressing the freq range for which goin is independent to the
- gain of practical of-Amp = 106.
- of Amp is a multistage Amplifeer.

- # BW cannot be @ due to the presence of CT & Col in multistage complifies.
- for fractical Of-Amp; Gr. BW = 106 Hz.
- Max fossible BW = 100 Hz for gain = 1.

Negative feedback will to the gain of the system and I the BAI and hence I the stability of the system.

Op-Amp Imp. Points -

- (i) It is a monstitue IC or a semiconductor chip fabricated with visi by using epitoxical method
- (ii) In epitaxial method, entire IC is fabricated on single crystal of Si.
- (iii) It is basically a voltage controlled device or voltage amplifier or vevs.
- (v) Popularly wed op-Amp is 10-741. For 10-741, maximum power supply is ±150.
- (v) Openp is versatite, predictable and economic system building block as small size, high reliability, reduced cost, loss offset voltage forment and loss power consumption.
- (vi) It is originally invented to execute the mathematical operations, hence called operations.
- (ini) It is a direct coupled high gain amplifier, ie, open loof gain is very high, therefore prequency stability of the signal is less and to compensate this small amount of ve feedback is added so that the gain is reduced & the prequency stability increases (since BN 1)
- (vin) Op-Imps are generally oferated under closed loop condition, is, by applying -ve feedback.
- (m) In an of rmp, Gam. & BW = constant.



#### Characteristic of Operational Amplifier

<u>O</u>	in	a	d	en	sta	3	
V	SP.	a	90	6	nin		,

- Vocinge gam, Ay
- Input Rajotonce, Ri
- output Raistance, Ro
- G. BN
- BW
- CMRR
- Slew Rate [SR]

Idea	L
m	

- 00
- n
- 00
- 00
- 00
- 00

## (6)

Practical

106

IMI

10-100 D.

106 Hz

106 Hz (for Gain=1)

106 or 100 dB

80 V/psec.

#### - It is also referred as Basic linear Integrated Circuit.

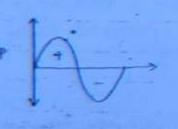
#### Symbol :-

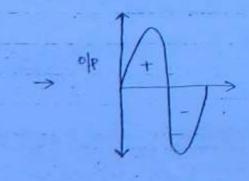
Inverting terminal (d=190°)

How invoting

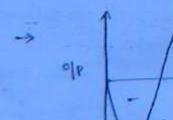
Vsat

\$ = phase shift

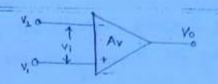




-, Non-inverting amplifier



-> Investing - Amplifier.



Case 1:- When  $V_1 \neq 0$ ,  $V_2 = 0$ , then  $V_0 > 0$ 

Cose2:- When  $V_1 \neq 0$ ;  $V_2 \neq 0$  and  $V_1 > V_2$ , then  $V_0 > 0$ .

case 3: When  $V_1=0$ ,  $V_2\neq 0$ , then  $V_0<0$ 

case 4: When  $V_1 \neq 0$ ;  $V_2 \neq 0$  and  $V_2 > V_1$ , then  $V_0 < 0$ .

Representation of Sain -

care 1- V2 -1 Av V0

 $V_i' = V_1 - V_2$ ;  $V_0 = A_V V_i' \Rightarrow 1$  We represent like this than  $= A_V (V_1 - V_2) \qquad A_V = 10^6 \text{ Hz.} \quad \text{i.e., } A_V > 0$ 

 $0 \text{ (ase 2)} V_i = V_2 - V_1$   $0 V_0 = A_V V_i = A_V (V_2 - V_1)$ 

then for this representation, Av = -106 ite, Av <0.

When  $A_V \rightarrow \infty$   $V_1$   $V_2$   $V_3$   $V_4$   $V_6$ 

 $V_1 = V_1 = V_2$  $V_0 = finide = 0$   $V_1 = V_0/_{00} = 0$ 

=> V1= V2.

-> There is finite of w/o any input.

-> 100, if we attach any voltage nounce at V, , the same will appear at V2 ( : V,=V2): but Ri = 00 (ideally) , hence they should be oc.

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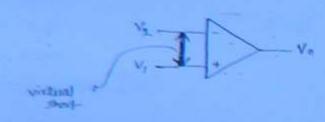
but they are behaving as so. This condition is called Virtual short, i.e., even though they are not physically short, they are behaving as short.



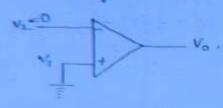
 $\tilde{K}_1 = \infty$ 

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Symbol for Virtual Short-

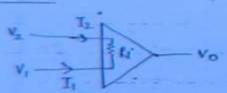


This is called virtual ground. It is a special case of virtual short.



Virtual Ground Process

→ When Ri=∞



for Ri=00,

I, -I2 = 0

- Internal power consumption ~ 0.

$$V_0 = 5V \text{ and } Av=10^{C}, R_1 = 10^{6} J_1$$

$$= V_1 = \frac{V_0}{Av} = 5\mu V \approx 0$$

$$I_1 = \frac{V_1}{R_1} = 5\mu N \approx 0$$

0 -> If the gain in the given forblem is 1 (very high), then we can use the 0 concept of virtual ground. It is an approximate concept. 0 0 0 ALL AV - open Loop system. 0  $A_{01} = A_{V} = \frac{V_{0}}{V_{1}} = \frac{V_{0}}{V_{0}}$ 0 0 Ø. Vi' = Vc+ BVo 0-) o 0 0 Vo= (Vs+ BVo). Av For the feedback -0 ACL = Vo = AV > AV - closed loop gain to the feedback 0 0 0 for me feedback û Aci = Vo = Av < Av -> closed loop gain for -re feedback 0 0 tre feedback is used in oscillators & re feedback is used in amplifier. Op-Amp with the feedback. Op-Amp with -ve feedback ō - ACL << AOL 0 > -> |Ace | >> |Aoe | we can assume AOL = AV -) co we can assure to - 00, but we coult assume Action, . Virtual Ground process is valid. ". Virtual ground forcess is invalid. Э

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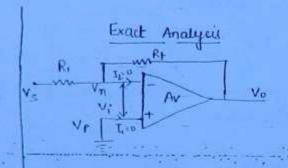
#### Mode of Operation



$$\frac{V_s - V_n}{R_1} = \frac{V_n - V_o}{R_1} + 0$$

$$\Rightarrow \frac{V_S}{R_1} = -\frac{V_0}{R_4}$$

$$\Rightarrow A_{CL} = \frac{V_0}{V_S} = \frac{-k_f}{k_1}$$



$$R_{f} = \frac{V_{n} - V_{0}}{R_{f}} + \frac{V_{n} - V_{s}}{R_{f}} = 0$$

$$R_{1} = \frac{V_{n} - V_{0}}{R_{f}} + \frac{V_{n} - V_{s}}{R_{f}} = 0$$

$$V_{n} = \frac{V_{n} - V_{0}}{R_{f}} + \frac{V_{n} - V_{s}}{R_{f}} = 0$$

$$V_{n} = \frac{V_{n} - V_{0}}{R_{f}} + \frac{V_{n} - V_{s}}{R_{f}} = 0$$

$$= \sqrt{V_0 R_1} + \frac{V_0 R_1}{R_1 + R_2} + \frac{V_0 R_1}{R_1 + R_2}$$

untinued

$$T_{\uparrow} = T_1 + T_2 + T_3$$

$$\frac{V_{n} - V_{0}}{R_{f}} = \frac{V_{i} - V_{n}}{R_{I}} + \frac{V_{2} - V_{n}}{R_{2}} + \frac{V_{3} - V_{2n}}{R_{3}}$$

$$= -R_{f} \left[ \frac{V_{1}}{R_{1}} + \frac{V_{2}}{R_{2}} + \frac{V_{3}}{R_{3}} \right]$$

When 
$$R_{\uparrow} = R_1 = R_2 = R_3$$
 -

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$$V_0 = -\left[V_1 + V_2 + V_3\right]$$

Applying KCI at non-inverting terminal -

$$\frac{V_{P} - V_{1}}{R} + \frac{V_{P} - V_{2}}{R} + \frac{V_{P} - V_{3}}{R} = 0$$

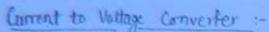
$$- \frac{1}{2} - \sqrt{p} = -\frac{\sqrt{p} + \sqrt{2} + \sqrt{3}}{3}.$$

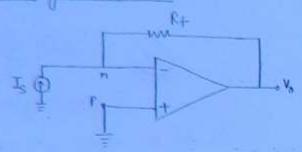
Now, 
$$\frac{V_0}{V_P} = \frac{1 + \frac{R_T}{R_I}}{\frac{R_T}{R_I}}$$

$$= \frac{V_0}{R_1} = \frac{\left(1 + \frac{R_1}{R_1}\right) \left(-\frac{V_1 + V_2 + V_3}{3}\right)}{R_1}$$

$$\phi = 0$$

$$V_0 = [V_1 + V_2 + V_3]$$

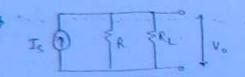






$$\frac{1}{2} \frac{V_p = V_n = 0}{V_n - V_0} = I_s = 0$$

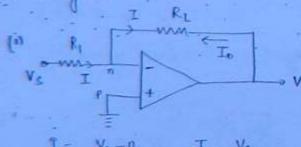
$$\boxed{V_o = -\mathbf{I}_S \cdot k_f}$$



= but this is not converting Is into a voltage source because Vo is dependent on Re. Hence, given circuit is not a converter.

#### Vettage to Current Converter !-

(a) Floating load -

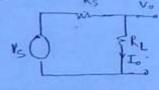


$$\hat{\mathbb{T}} = \begin{array}{cc} \frac{V_S - 0}{R_1} & \Rightarrow & \hat{\mathbb{T}} = \begin{array}{cc} \frac{V_S}{R_1} \end{array}$$

$$I_0 = -I = -\frac{V_S}{R_1}$$

7 It is standard convention to take load current. To in direction away from output voltage &

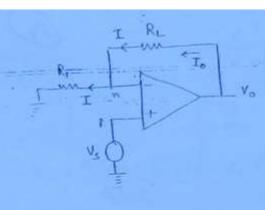
gie, In leaving from



$$\frac{V_o}{R_L} = I_o = \frac{v_s}{R_s + R_L}$$

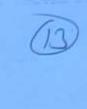
". To depends on Re, hence not a converter.

$$I_0 = -I = -\frac{V_S}{R_1}$$
  $\rightarrow I_0 = output current independent of  $R_L$ .$ 

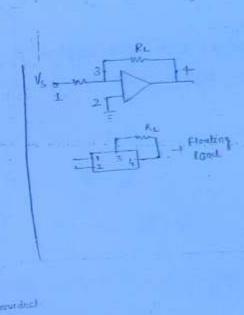


$$\frac{V_n = V_s - 0}{V_s - 0} = I$$

$$\frac{V_s - 0}{R_1} = I = \frac{V_s}{R_1}$$



Co

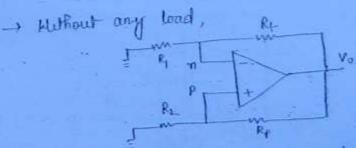


a above ext, eve as well by -ve feedback is present to the labelity system should have -ve feedlast and hence we feedback should be more than the feedback.

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B

0



$$V_n = \frac{R_1}{R_1 + R_1} V_0$$

Vn >Vp (-ve predback more than +ve predback) for Stability.

$$\Rightarrow \frac{R_1}{R_1 + R_2} \gg \frac{R_2}{R_2 + R_2}$$

Apple R.,
$$R_{2}' = R_{2} || R_{L} < R_{2}$$

$$V_{p}' = \frac{R_{2}'}{R_{2}' + R_{p}} || V_{0} = \frac{1}{1 + R_{p}' R_{2}'} || V_$$

Now R' < R2 and hence  $V_p' < V_p \Rightarrow$  the feather is which forourable for stability.

Hence, even after applying RL, if original conditions. Epids then the system will remain in -ve feedback.

Now, from gracet 1-

$$J_0 = \frac{v_P}{R_L} - 0$$

$$V_F = V_D - 0$$

plying the of broken amount -

$$\exists V_0 = \left[1 + \frac{R_F}{R_F}\right] V_p \qquad (3)$$

Kil at non-inverting terminal -

$$\frac{V_{P} - V_{S}}{R_{2}} + \frac{V_{P} - 0}{R_{L}} + \frac{V_{P} - V_{o}}{R_{P}} = 0$$

$$\stackrel{\text{d}}{=} V_{P} \left[ \frac{1}{R_{L}} + \frac{1}{R_{L}} + \frac{1}{R_{F}} \right] - \frac{V_{S}}{R_{2}} - \frac{V_{o}}{R_{P}} = 0 - - 0$$

$$\stackrel{\text{define}}{=} (3) \frac{1}{2} (9) - \frac{1}{2} (9) = 0$$

$$\Rightarrow V_{p} \left[ \frac{1}{R_{2}} + \frac{1}{R_{L}} + \frac{1}{R_{p}} \right] - \frac{1}{R_{p}} \left[ 1 + \frac{R_{p}}{R_{1}} \right] V_{p} = \frac{V_{c}}{R_{2}}$$

$$= V_{P} \left[ \frac{1}{E_{2}} + \frac{1}{R_{L}} + \frac{1}{R_{P}} + \frac{1}{R_{P}} - \frac{1}{R_{P}} - \frac{R_{F}}{R_{L}R_{P}} \right] = \frac{V_{S}}{R_{2}}$$

$$V_{p} = \left[ \frac{R_{1}R_{p}R_{L} + R_{1}R_{2}R_{p} - R_{f}R_{2}R_{L}}{R_{1}R_{p}R_{2}R_{L}} \right] = \frac{V_{e}}{R_{1}}$$

$$\frac{V_{P}}{R_{L}} = \frac{V_{S} R_{1} R_{P}}{R_{L} [R_{1}R_{p} - R_{2}R_{f}] + R_{1}R_{2}R_{P}}$$

or 
$$\frac{R_P}{R_2} = \frac{R_F}{R_1} \rightarrow \text{Balanced Bridge condition}$$

Then, 
$$T_0 = \frac{V_0}{R_2}$$

(ii) 
$$V_{s}$$
  $V_{r}$   $V_{r}$ 

Prove that if Rt = Rp

then 
$$I_0 = -\frac{V_s}{R_L}$$

Applying ker at Vp -VP ( R + 1 + 1 - Vo R - - 1)

Applying KCL at 
$$V_n - \frac{V_n - V_k}{R_1} + \frac{V_p - V_o}{R_+} = 0$$
 - (3)

$$= \frac{1}{R_1} + \frac{1}{R_+} = \frac{V_s}{R_1} + \frac{V_o}{R_+}$$

Fulling  $V_o$  from eqn (1) -
$$= -\frac{V_r}{R_+} = \frac{V_s}{R_+} + \frac{R_P}{R_+} \cdot V_r = \frac{1}{R_2} + \frac{1}{R_+} + \frac{1}{R_p}$$

On simplifying -
$$= \frac{-R_2}{R_1 R_2 R_p^2 + R_1 R_P} (R_p R_1 - R_2 R_P) - \frac{(4)}{R_1 R_2 R_p^2 + R_1 R_P} (R_p R_1 - R_2 R_P) - \frac{(4)}{R_1 R_2 R_p^2 + R_1 R_P} (R_p R_1 - R_2 R_P) - \frac{(4)}{R_1 R_2 R_P^2 + R_1 R_P} (R_p R_1 - R_2 R_P) - \frac{(4)}{R_1 R_2 R_P^2 + R_1 R_P} (R_p R_1 - R_2 R_P) - \frac{(4)}{R_1 R_2 R_P^2 + R_1 R_P} (R_p R_1 - R_2 R_P) - \frac{(4)}{R_1 R_2 R_P^2 + R_1 R_P} (R_p R_1 - R_2 R_P) - \frac{(4)}{R_1 R_2 R_P^2 + R_1 R_P} (R_p R_1 - R_2 R_P) - \frac{(4)}{R_1 R_2 R_P^2 + R_1 R_P} (R_p R_1 - R_2 R_P) - \frac{(4)}{R_1 R_2 R_P^2 + R_1 R_P} (R_p R_1 - R_2 R_P) - \frac{(4)}{R_1 R_2 R_P^2 + R_1 R_P} (R_p R_1 - R_2 R_P) - \frac{(4)}{R_1 R_2 R_P^2 + R_1 R_P} (R_p R_1 - R_2 R_P) - \frac{(4)}{R_1 R_2 R_P^2 + R_1 R_P} (R_p R_1 - R_2 R_P) - \frac{(4)}{R_1 R_2 R_P} (R_p R_$$

From eigenit-
$$T_{0} = \frac{V_{P}}{R_{L}} = \frac{-R_{2}R_{P}R_{+} \cdot V_{e}}{R_{1}R_{2}R_{P}^{2} + R_{L}R_{P}(R_{p}R_{1} - R_{s}R_{1})}$$

$$T_{0} = \frac{V_{P}}{R_{L}} = \frac{-R_{2}R_{P}R_{+} \cdot R_{L}R_{P}(R_{p}R_{1} - R_{s}R_{1})}{R_{1}R_{1}R_{1}R_{2}}$$

$$T_{0} = \frac{R_{1}R_{1}}{R_{1}} = \frac{R_{1}R_{1}}{R_{2}} = \frac{1}{R_{2}} = \frac{R_{1}R_{1}}{R_{1}R_{P}}$$

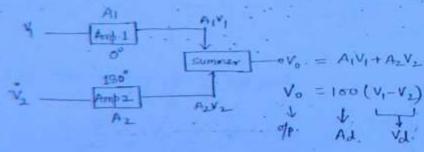
$$T_{0} = -\frac{V_{S}}{R_{1}}R_{P}} = -\frac{V_{S}}{R_{2}}$$

$$T_{0} = \frac{-V_{S}}{R_{1}R_{P}}R_{P}} = -\frac{V_{S}}{R_{2}}$$

#### Differential Amplytier:

Ldcal

melical



To write the above eqn, A and Az should be equal with 180° phase diff. But it is not possible to have identical amplifiers.  $V_0 = 100V_1 - 90V_2 = 90'(V_1 - V_2) + (10V_1) \text{ Noise}.$ 

If there is some noise signal is present at both terminal and ideally it should carried out but for unidentical amplifiers-

$$V_0 = 100 (V_1 + V_n) - 90 (V_1 + V_n)$$
  
= 90 (V<sub>1</sub> - V<sub>2</sub>) + (0V<sub>1</sub> + 10V<sub>n</sub>) Noise.



For Practical Amplifier,

where 
$$V_d = V_1 - V_2$$
  $V_d = V_1 - V_2$ 

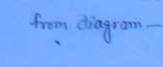
$$V_c = \frac{V_1 + V_2}{2} = common mode signal - 3$$

Dc = common mode gain

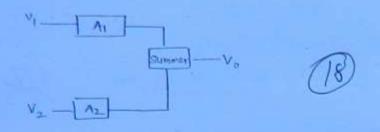
- Common Mode Rejection Ratio - .

-> Amp 1 is better than Amp 2.

- CMRR is figure of Ment of practical of amp.



$$V_{\delta} = A_1V_1 + A_3V_2 - Q$$



$$=$$
  $V_1 = V_c + \frac{V_d}{2} - (5)$ 

$$\Rightarrow V_2 = V_c - \frac{V_d}{2} - \bigcirc$$

Putti-

Pulting 5 & 6 in (4) -
$$V_0 = A_1 \left( \frac{V_c + V_d}{2} \right) + A_2 \left( \frac{V_c - V_d}{2} \right)$$

$$V_0 = \left[ \frac{A_1 - A_2}{2} \right] V_d + \left( \frac{A_1 + A_2}{2} \right) \cdot V_c$$

$$Ad = \frac{A_1 - A_2}{2} \qquad A_c = A_1 + A_2$$

by Here Az = -ve due to 180° phasediffand hence Ad >Ac.

#### and Method :-

Calculation of Ac -

$$\hat{F}_{\alpha,E} \cdot \hat{v}_i = \hat{v}_{\alpha} \quad \Rightarrow \quad \hat{V}_{C} = \quad \hat{V}_{S} \cdot \cdots \cdot \cdot \cdot$$

$$\Rightarrow A_c = \frac{V_0}{V_S}$$

#### Calculation of Ad :-

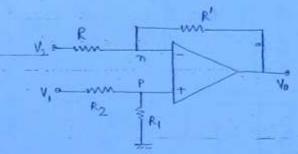
Our: The circuit shown is a differential amplifier using an ideal of amp

- (a) End the of voltage Vo
- (b) find CMRR

O

(e) Show that if CMRR=0 if  $\frac{R'}{R_2} = \frac{R_1}{R_2}$ .





$$V_{p} = \frac{V_{1}R_{1}}{R_{1} + R_{2}}$$

$$V_{01} = \left[1 + \frac{R^T}{R}\right]V_{P}$$

$$V_{01} = \left[ 1 + \frac{R^2}{R} \right] \left[ \frac{R_0}{R_0 + R_0} \right] V_0$$

$$V_{02} = -\frac{R'}{R} V_2$$

$$\therefore V_0 = V_{01} + V_{02} = \left[1 + \frac{R^1}{R}\right] \left[\frac{R_1}{R_1 + R_2}\right], V_1 - \frac{R^1}{R}V_2 \qquad \text{As } r$$

$$A_{C} = A_1 + A_2 = A_1 - A_2 = \left[1 + \frac{R^1}{R}\right] \left[\frac{R_1}{R_1 + R_2}\right] - \frac{R^1}{R}$$

$$Ad = \frac{A_1 - A_2}{2} \Rightarrow Ad = \frac{1}{2} \left[ \frac{R_1}{R} \right] \left[ \frac{R_1}{R_1 + R_2} \right] + \frac{R_1^2}{2R}$$

CMRR = 
$$\frac{1}{2}$$
  $\left[\frac{1}{R}, \frac{1}{R}, \frac{1}{R},$ 

(c) when 
$$\frac{R'}{R} = \frac{R_1}{R_2}$$

CMRR = 
$$\frac{1}{2}$$
  $\left[\frac{51+\frac{R_1}{R_2}}{\frac{1}{R_2}}, \frac{5}{2}, \frac{\frac{R_1}{R_1+R_2}}{\frac{1}{R_2}}, \frac{\frac{R_1}{R_2}}{\frac{1}{R_2}}, \frac{\frac{R_1}{R_2}}{\frac{1}{R_2}}, \frac{\frac{R_1}{R_2}}{\frac{1}{R_2}}, \frac{\frac{R_1}{R_2}}{\frac{1}{R_2}}, \frac{\frac{R_1}{R_2}}{\frac{1}{R_2}}, \frac{\frac{R_1}{R_2}}{\frac{1}{R_2}}\right]$ 

$$= V_2 \left[ \left\{ \frac{2R_1}{R_2} \right\} \div \left\{ 0 \right\} \right]$$

$$\frac{3}{2} - \left[ \frac{1+\frac{R^2}{R}}{R} \right] \left[ \frac{R_1}{R_1 + R_2} \right] = -\frac{\frac{R^2}{R}}{R} = 0$$

$$= 3 - \frac{R_1}{R_1 + R_2} + \frac{R^1}{R} \left[ \frac{R_1}{R_1 + R_2} - 1 \right] = 0$$

$$= \frac{R_1}{R_1 + R_2} - \frac{R_2 \cdot R'}{R(R_1 + R_2)} = 0$$

$$\frac{R_1}{R_2} = \frac{R^1}{R}$$
 Here forced

I'd method s

$$\mathbf{W_0} = \begin{bmatrix} 1 + \frac{R^1}{R} \end{bmatrix} \begin{bmatrix} \mathbf{e_1} \\ R_1 + R_2 \end{bmatrix} \mathbf{V_S} - \frac{R^1}{R} \mathbf{V_S} - \frac{1}{2} \mathbf{A_C} = \frac{\mathbf{V_0}}{\mathbf{V_S}} = \begin{bmatrix} 1 + \frac{R^1}{R} \end{bmatrix} \begin{bmatrix} \frac{R_1}{R_1 + R_2} \end{bmatrix} - \frac{R^1}{R}$$

For Ad, 
$$V_1 = \frac{V_c!}{2}$$
,  $V_2 = -\frac{V_c!}{2}$ .  $\Rightarrow$  Ad=  $\frac{V_o}{V_c!}$  and  $Ac = 0$ .

$$V_0 = \left[1 + \frac{R'}{R}\right] \left[\frac{R_1}{R_1 + R_2}\right] \cdot \frac{V_S'}{2} + \frac{R'}{R} \frac{V_C'}{2}.$$

$$A_{d} = \frac{V_{b}}{V_{s}^{*}} = \frac{1}{2} \left[ \left[ 1 + \frac{R^{1}}{R} \right] \left[ \frac{R_{1}}{R_{1} + R_{2}} \right] + \frac{R^{1}}{R} \right]_{a}.$$

Que:

$$Sol^{n}$$
: - + for objective, first check  $\frac{Rt}{R} = \frac{Rt}{R2}$ 

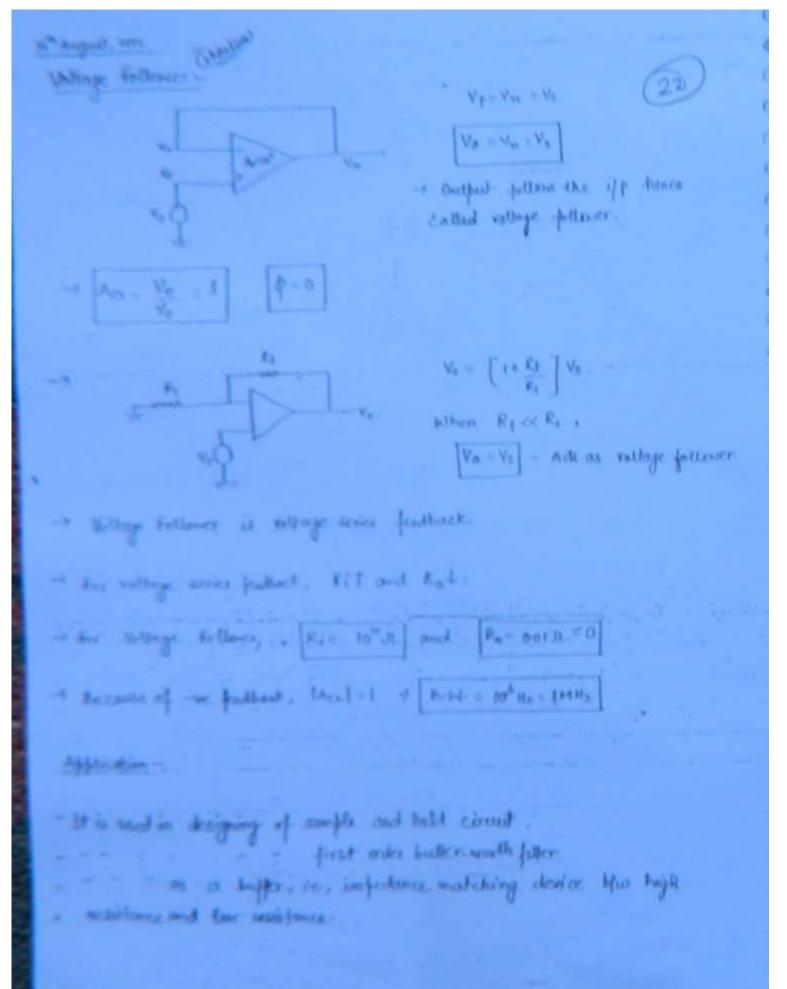
$$\Rightarrow \frac{100}{10} = \frac{10}{1} \Rightarrow \text{ since ratio is equal } \Rightarrow \text{ CMRR} = \infty$$

$$\Rightarrow A_{c} = 0$$

$$(4) \rightarrow V_0 = A_d V_d + A_c V_c$$

$$\frac{1}{2} \cdot \frac{V_0}{V_0} = \frac{1}{2} \cdot \frac{V_1 - V_2}{V_1 - V_2}$$

$$Ad = \frac{A_1 - A_2}{2} = \frac{10 - (-10)}{2} = 10$$



Application as a buffer-

$$\label{eq:vhamma} v_h = \frac{t_h}{r_h + r_h} \, V_h \quad \text{as} \quad V_h \qquad \text{a.s.} \quad r_h \approx r_h$$

$$T_L = \frac{V_L}{m_S + R_L} = \frac{10}{10 K} - \frac{1 m A}{10 K} - \frac{R_L \uparrow \text{ and } T_L \downarrow 0}{m_{CP} \text{ is localing}}$$

$$T_0 = (\underline{x} \otimes \underline{x} \otimes A)$$

Law Land Resistance :



$$\forall : \; P_{k} >> R_{k} \quad \text{as} \quad V_{k} \simeq V_{b}$$

Other Buffers -

### Linear Wave Shaping circuit:

- High Pass RC - Differentiator.

The process where by form of a non-sinusoidal signal is altered by transmission through a linear new is called linear wave shaping

#### 1) High Pass RC circuit -

Gain 
$$A = \frac{V_0}{V_i}$$

$$V_0 = \frac{R}{R + \frac{V_0}{C_3}}$$

$$V_0 = \frac{R}{R + \frac{1}{2}c^3} \cdot \frac{Vc^3}{c^3}$$

$$\frac{1}{V_i} = \frac{1}{1 + \frac{1}{RCs}} = \frac{1}{1 + \frac{1}{RCs}}$$

$$\Rightarrow \frac{V_0}{V_1} = \frac{1}{1 + \frac{1}{RCS}} \Rightarrow A = \frac{1}{1 - \frac{j}{\omega_{RC}}} - (1)$$

$$\Rightarrow \left[ |\Lambda| = \frac{1}{\sqrt{1 + 1/\omega^2 R^2 C^2}} \right]$$

$$|A| = \frac{1}{\sqrt{1+1/\omega^2R^2C^2}}, \quad \left[ \phi \text{ shift} = -\tan^{-1}\left(\frac{1}{\omega RC}\right) \right] - (3)$$

- Since of shift = +ve, it is called leading circuit.

$$\Rightarrow$$
 At  $\omega=\omega_L$ ,  $|A|=\frac{A_{max}}{\sqrt{2}}$ ;  $\omega_L=\frac{A_{max}}{\sqrt{2}}$ ;  $\omega_L=\frac{A_{max$ 

$$A = \frac{1}{1 - j/\omega_{ARC}}$$

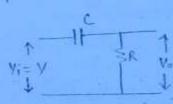
$$A = \frac{1}{1 - j/\omega_{\kappa}Rc} \Rightarrow A = \frac{1}{1 - j \frac{\omega_{\kappa}}{\omega_{\kappa}}} = \frac{1}{1 - j \frac{f\kappa}{f}}$$

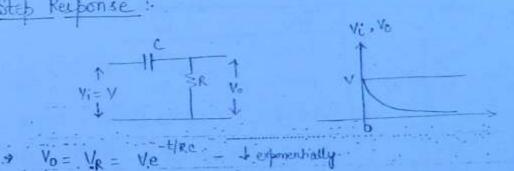
$$f = 0 ; |A| = 0$$

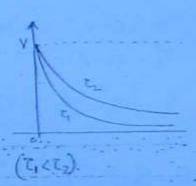
$$f = fL ; |A| = 1/5L$$

$$f = \infty ; |A| = 1$$

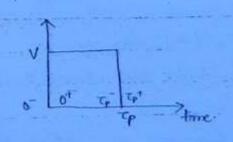
#### Step Response:







#### Pulse Response



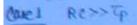
$$\Rightarrow$$
  $V_i(o^+) = 0$  ,  $V_i(o^+) = V$   
 $V_i(\tau_i) = 0V$  ,  $V_i(\tau_i^+) = 0$ 



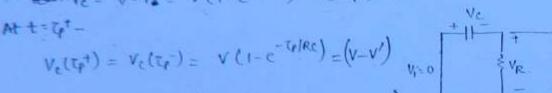
Voulted

Vo

O



→ Ve will start discharging till oct < Tp. 10=4



$$V_{R} = 0 - V_{c}' + - V(1 - e^{-t_{f}Rc}).$$
 $V_{c} = (v - v') e^{-t_{f}Rc}.$ 
 $V_{c} = (v - v') e^{-t_{f}Rc}.$ 
 $(t' = t - \tau_{f})$ 

Ę				indi a	Jak Kar		
>	Mhen	there is	sudden.	change	in	ile, -	

-	If the out	bu input is	maintaining some
	constant	level, then	outsut will

tend towards	zero. G (	between	o to to)	and from	(4 to a)	, the opp is
Honding towar						

$V_0 = -V_c = -(v-v')e^{-v^2-v^2}$	OCTUTE VO=Ve.
ting tipe of the Applicability of a second of the State o	t= tp - V'= Ve - telec
> When there is sudden change in 1/p,	t= 70+ [V-V1]
the same change will occur at the off.	t > To - EXMANDED HIKE - [v-v'] e-t/rc
If the output input is maintaining some	(V-V ) ε t'= t-τρ
constant level, then output will	
tend towards zeroify (between o to tp) and	from (To to a), the off is

Time

1 < 0

Area of the pulse = 
$$Vtp = + re = average Ac level$$
.

For output,  $A + avea = \int_{0}^{\infty} Ve^{-HRC} dt$ ,  $A = \int_{0}^{\infty} (V - V')e^{-t} dt$ 

At =  $A = (as charging = discharging)$ 

- Value of C should be high so 1800 for DC Rel= as =) DC will be blocked.

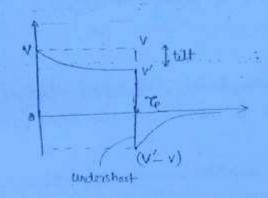
W'= AC+DC.

=> dc level or argenel of o/p=0 -1 Potal ofp area =0 =1 A+ = A - -

any value of signal

-, Peaking

-> Avg. level of off in high has RC signal is always a irrespective of the arg. level of ilp.



Tilt - at the top of pulse in Undershoot + at the end of fulse

+ se peak | spries | pipe

Case 2 . Re << Tp.

$$V_c(e^+) = 0 = V_c(e^+) = y \quad V_0 = V$$

At t=t,-: ...

At t= Tp",

At t = Tpt, Ve=V , Messaw

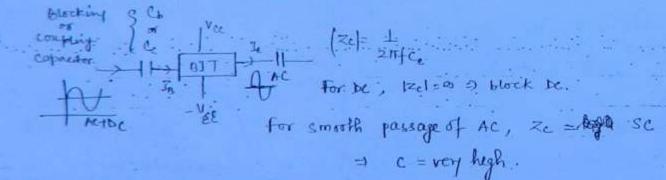
Now, & capacitor will start discharging, Ve = Ve VR = V0 = - Ve-t/AC. -> (+1 = +-7)

At  $t = t_{2}$ ,  $V_c = 0$  and  $v_R = V_0 = 0$ .

Positive spike of amplitude 'V' at the beginning of pulse and -ve of same size at the ending of pulse. This process of converting pulse into spike by ocens of a high bass RC circuit of short time constant is called Peaking

#### For HPF -

- Average level of is always zero, independent of average level of ifp,
- When input changes discontinuously by amount V', The output changes descentinuously by an equal amount and in same direction.
- During any finite time interval, when input maintains a constant level, ofp decays exponentially towards o'voltage.

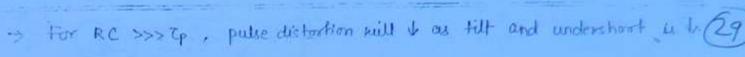


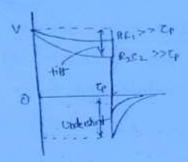
But 4 AC - 20Hz - 20KH2.

The low freq. components will not pass smoothly as for low frequencies 121 = high . Hence—there will be distortion in the ofp. Whocas, the high freq component will be received accurately at the ofp.

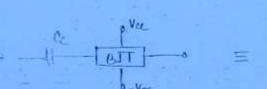
- This capacitor provides DC isolation to the BIT. The DC is blocked as it will enterfore with the blasing condition of the

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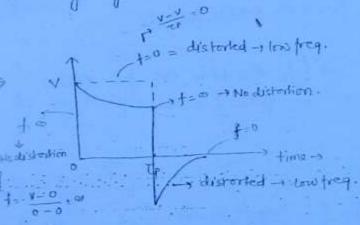
R,C1 > R2C2. If we keep 1 RC, distortion will keep to Tilt and undershort are distortions.

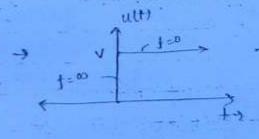


distortion. (same as previous discussion).

Ce 3 Ri should also be high.

- For better coupling or minimum distortion, Ri and Ce, toth should be very high.





and hence it is preferred as test signal.

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$$x = \frac{t}{Rc} = \text{very small}$$
  
 $e^{-x} = \frac{1-x+\frac{x^2}{2!}-\frac{x^3}{3!}}{2!}$ 

$$\Rightarrow V_0 = V \left[ 1 - \frac{t}{RC} \right] - 0$$

Tilt at 
$$t=t_1 = v-v'-\Theta$$

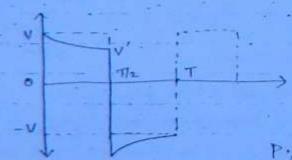
$$V' = V \left[1 - \frac{t_1}{RC}\right]$$
  $\Rightarrow V - V' = \frac{V + C}{RC}$ 

$$\Rightarrow \frac{V-V'}{V} = \frac{t_1}{RC}$$

$$\Rightarrow \boxed{P./. = \frac{t_1}{Rc} \times 100^{-1}} \xrightarrow{\text{When } Rc \text{ is } \uparrow \text{, titt will } \downarrow \text{.}}$$

P/ = 211fit, ×100/. The should be 1500 for smaller -tilt.)

It for symmetrical square Wave -



$$\Rightarrow \boxed{P' = \pi\left(\frac{tr}{t}\right) \times 100\%}$$

- When time constant, RC, is very very small as compared to time period of input signal, the circuit is called differentiator.

Criteria for good differentiator-

- Ideally, RC=0.

$$\frac{V_0}{V_1} = |A| = \frac{1}{1 - i / \omega_R c}$$

$$|A| = \frac{1}{\sqrt{1 + \frac{1}{1 + \frac{1}{$$

for Vi= Vmsinwt

for ideal differentiator,  $\phi = 90^{\circ}$  =) were = 0. (which is fractically not possible).

Tideal Diff. 90° 0.01

Best Diff. 89.4° 0.01

Sood diff 84.3° 0.1

-1 Vo = (0.01) Vm 8m (w++894) -> Amplitude is very small effects
differentiation.

→ To get amplitude, Vm, we have to follow it with a high gain amplifier

→ A high fast RC differentiation is always followed by a high your emplified of the www.raghul.org

#### LOW Pass RC circuit :-

$$V_0 = \frac{1}{R + \frac{1}{l + RCs}}$$

$$\Rightarrow A = \frac{1}{1 + RCs}$$

$$\Rightarrow A = \frac{1}{1 + j \omega RC}$$

$$\Rightarrow |A| = \frac{1}{\sqrt{1 + \omega^2 R^2 C^2}}; \quad \phi = -\tan^{-1}(\omega RC) \rightarrow (\text{lagging})^*$$

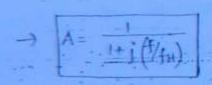
$$\phi = -ve \quad \text{circuit}$$

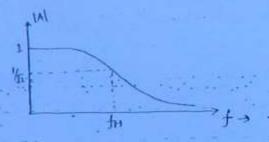
$$\rightarrow \quad \text{for} \quad \omega = 0 \quad ; \quad |A| = 1 \quad ... \quad \omega = \infty \quad ; \quad |A| = 0 \dots$$

$$\Rightarrow \text{ At } \omega = \omega_{\text{H }} \text{ } 1 \text{ } 1 \text{ } 1 = \frac{1 \text{ Amax}}{\sqrt{12}} = \frac{1}{\sqrt{12}}$$

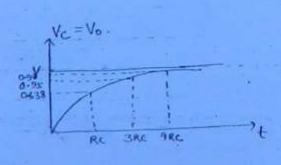
$$\Rightarrow \omega_{\text{H}} = \frac{1}{RC} \qquad \text{ or } 1$$

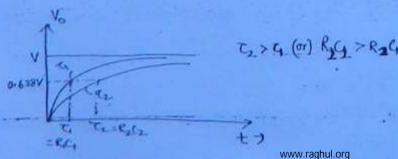
$$\Rightarrow$$
  $w_h = \frac{1}{RC}$  or  $2\Pi_H = \frac{1}{RC} \Rightarrow \int_{H} \frac{1}{2\pi RC} \rightarrow \frac{3d8}{pequency}$ 





#### Slep Response:





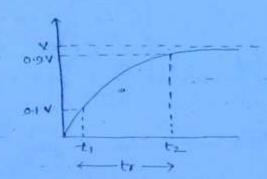
O

(3)

Č.



- It is the time taken by the signal to rise from 101 to 90% of its final . Value.



Rise time = 
$$t_2 - t_1 = 2.2 \text{ RC}$$

$$0 \rightarrow \omega_{H} = 2\pi f_{H} = \frac{1}{Rc}$$

$$\frac{1}{2\pi} \cdot \frac{1}{2\pi} = \frac{2\cdot 2}{2\pi} \Rightarrow \frac{1}{4\pi} = \frac{0.35}{4\pi}$$

D > Rise time of the circuit should be low for fast response.

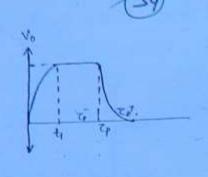
$$V_c(\mathfrak{o}^+)=V_c(\mathfrak{o}^+)=0\,\forall\,\cdot$$

~ Vo(0+)=0



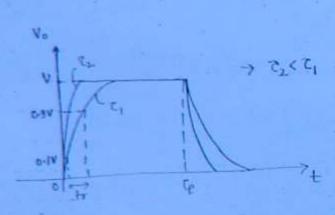
When RC-small, rate of charging is very fast.

Vc = V and will remain V till t- To



 $V_c(\tau_r) = V_c(\tau_r^*) = V$  and now the capacitor will start discharging through R.

Vo = Vc. = Ve (t-20)/RC for t>2p



charge instantly and fulle shape will be preserved if

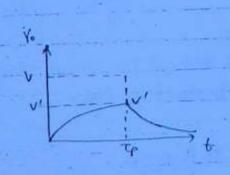
ideally (practically-very small)

$$\frac{1}{2} \frac{1}{\sqrt{4}} = \frac{1}{2} \frac{1}{\sqrt{4}} = \frac{1}{2$$

RC is high, hence rate of charging is very slow.

After t= Tp, Ve mill start dictarging,

Vo = V' = (t-2r)/Re for t7 Tp.

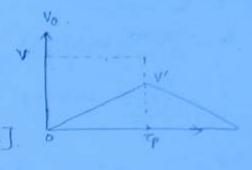


When RC is very high, then 
$$x = \frac{t}{RC} < << 1$$

$$x = \frac{t}{Rc} < < < 1$$

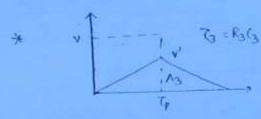
$$\therefore e^{-x} = 1 - x + \frac{x^2}{2l} - \frac{x^3}{31} = ...$$

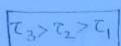


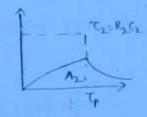


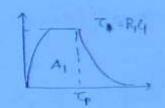
$$V_0 = V' \left[ 1 - \frac{t'}{RC} \right] - \left( linear eq^2 \right)$$
.

\* RC low for circuit will act as an imagrator when RC is very high.







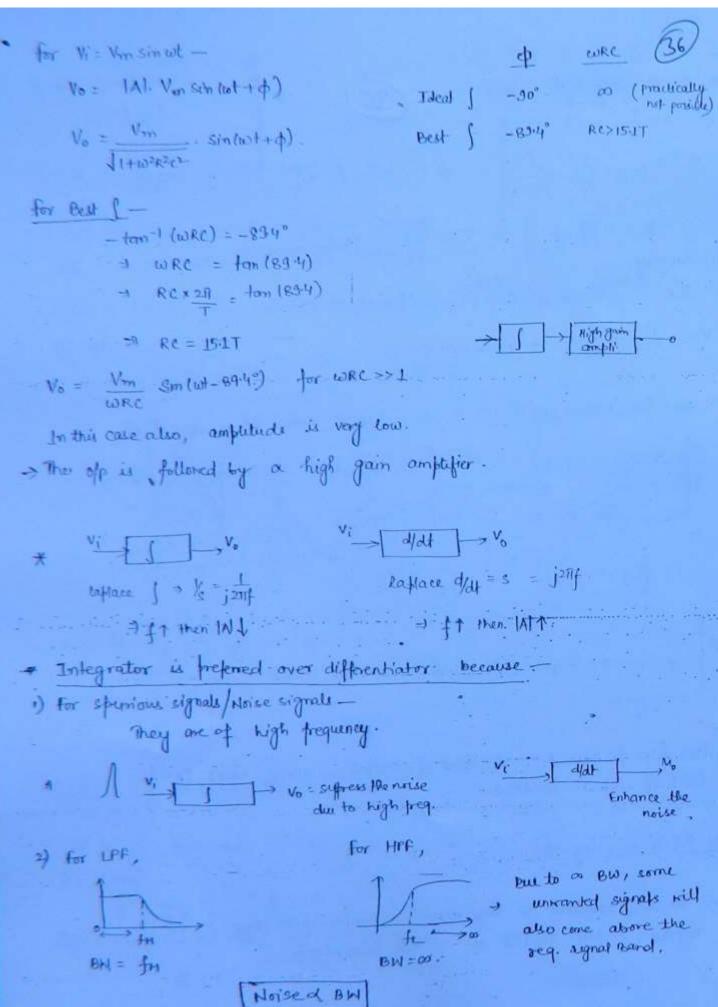


$$V = A = V \cdot Tp = +ve \Rightarrow de level or avg. devel$$

for los pais RC circuit, de level of outfut is always equal to de level of input de level-

#### Low Pass RC as an integrator

> When the time constant is very large as compared to time period of if signal, the circuit is called integrator.



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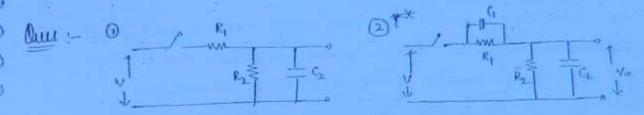
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> LPF is a placed at the last stage of multi-stage amplifier so as to prevent the noise to reach the output.

- Integrator is almost preferable over differentiator for following reasons—

  O since gain of S & with f, whereas gain of off 4 with f

  therefore, it is easier to stablise S—thom off writ spenious oscillations (high freq. moise).
  - (2) As a result of its timited Bus, on S is less sentitive to offer noise voltage than a diff.



Switch is closed at to. Vo(0+)=?

 $S_0|^{N}$ , (1) At  $V_c(0^{\circ})=0=V_c(0^{\dagger})=1$   $V_0=0$  at  $t=0^{\dagger}$ .  $\frac{9}{3}$   $T(0^{\dagger})=\frac{1}{2}V_{R_1}=\frac{1}{2}$  finite  $\frac{7}{3}$   $\frac{1}{2}V_0(0^{\circ})=\frac{1}{2}V_{R_2}/R_1+R_2$ 

(2) Capacitor does not allow sudden clarge in valtage but only for finite value of current

 $V_{c_{1}}(0^{-}) = 0 = V_{c_{1}}(0^{+}) . \Rightarrow V_{c_{2}}(0^{-}) = 0 = V_{c_{1}}(0^{+}) . \Rightarrow V_{c_{2}}(0^{+}) . \Rightarrow V_{c_{2}}(0^{+}) = 0 = V_{c_{1}}(0^{+}) . \Rightarrow V_{c_{2}}(0^{+}) . \Rightarrow V_{c_{2}}(0^{+}) = 0 = V_{c_{1}}(0^{+}) . \Rightarrow V_{c_{2}}(0^{+}) . \Rightarrow V_{c_{2}}(0^{+}) = 0 = V_{c_{1}}(0^{+}) . \Rightarrow V$ 

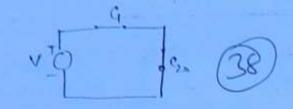
Konce KVL is violated.

Due to -V = 0, the current in the circuit will be

for Vo = 0 & Vo = 0, Vo = Ilot) = 0. For Plot) = 0, there will be

a finite eathers in Capacitors,

of 14th = 9(0+) = finite. Current & home a will allow sudden change of Villy



$$V_{a}(b^{\dagger}) = V_{C_{2}}(b^{\dagger}) = \frac{q(p^{\dagger})}{C_{2}}$$

$$V_0(0^{\dagger}) = \frac{C_1}{C_1 + C_2}, V_{-}; \quad V_2(0^{\dagger}) = \frac{Q(0^{\dagger})}{C_1} = \frac{C_2 V}{C_1 + C_2}$$

a) voltages will be distributed assess blow C1 and C2.

$$V_o = \frac{R_1}{R_1 + R_2} V$$

Concluion -

at +=0

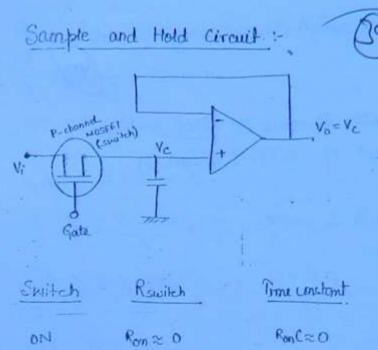
As input changes aboutly by amount V, then vollage across 4 and 5 must also change discontinuously but voltage across capacitor cannot change inclantamentally if current remains finite and hence an impulsive current brost flow in the vircuit

I delivered to each capacitor and capacitor allows sudden change of voltage

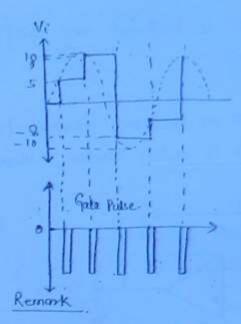
Que.

= v= 5x0 = 0 = impulsive voltage.

Hence it will allow sudden change in current.



on  $R_{on} \approx 0$   $R_{on} C \approx 0$ of  $R_{off} \approx \infty$   $R_{off} C \approx \infty$ 



Capacitor will suddenly charge upto instantaneous value of Vi.

C will hold the value of Vi.

off Vi Rote=00

IC I Ri=00

 $V_{i} = SV$   $V_{$ 

\* When Vi is < the value hold by capacitor.

In that case a will discharge or a will .

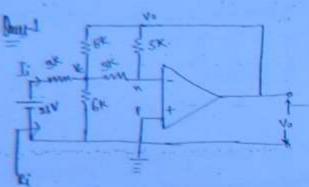
charge towards value of v; which is smaller than its frevious value

\* -ve triggered P-mosfet is used as trigger because -vely triggered fulles will not generate spites. I noise.

The of-amp is used (voltage follower) because it will make the Ri=00 which will help capacitor to hold the value, and c will not discharge through it. ( If Ri= some finite value, the hold value will discharge through it).

40)

- MOSFET makes on excellent enopper (switch) because its offset voltage (\$ =5 \tu V) is much smaller than that of BJT. (4 = 0.5 V).



find Ve, Ii and Ri

$$\begin{split} - \mathcal{V}_0 &= \frac{R_2}{R_1} \, \mathcal{V} + \left[ R_2 \mathcal{C} + \frac{L}{R_1} \right] \frac{d\mathcal{V}}{dt} \\ &+ L \mathcal{C} \, \frac{d^2 \mathcal{V}}{dt^2} \; . \end{split}$$

101 (2) : By applying virtual ground, Vp = Vn = 0.

$$\frac{Y_n = \hat{V}}{Z_{\ell_1 C}} + \frac{Y_n - V_o}{Z_{\ell_2 L}} = 0$$

$$\frac{1}{Z_{0,1}} + \frac{V_0}{Z_{0,1}} = 0$$

$$\frac{V}{\left(\frac{R_1 \cdot V_{CS}}{K_1 + V_{CS}}\right)} + \frac{V_0}{R_2 + L_S} = 0$$

$$\frac{V(1+R_1CS)}{R_1} + \frac{V_0}{R_2+L9} = 0$$

$$\Rightarrow -V_0 = \frac{VR_2}{R_1} + \left[\frac{L}{R_1} + R_2C\right] \leq V + LC \leq^2 V$$

$$\Rightarrow -V_0 = \frac{R_2}{R_1} V + \left[ \frac{L}{R_1} + R_2 C \right] \frac{dV}{dV} + \frac{LC}{dV^2}$$

$$\frac{0 - V_c}{3} + \frac{0 - V_o}{5} = 0 \Rightarrow 5V_c + 2V_0 = 0 - 1$$

Applyind KCL at Va -

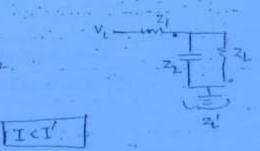
$$\frac{V_c}{3} + \frac{V_c - 21}{3} + \frac{V_c}{6} + \frac{V_c}{8} = 0$$

: 
$$T_i = \frac{21 - V_C}{3K} = 50 \text{ mA}$$
 ;  $V_0 = \frac{-5}{3} \times 6 = -10V$  ;  $R_i = \frac{V_i}{T_i} = \frac{21}{5} = 4.2 \Omega$ 

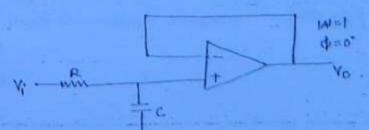
17th August, 2012

First order Buttersworth Filler:

$$V_1 = \frac{R = Z_1}{T}$$



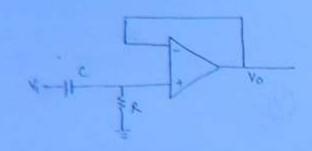
or I' will keep on I as I is I. Kence, there will be loading effect and farameters of futer will change. To avoid this, voltage follows circuit is used.



- first order buttersworth Filler.

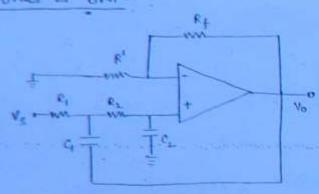
LPF

0





2nd order LP BWF-



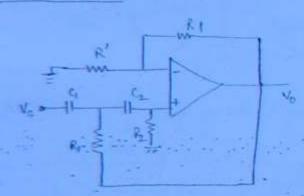
$$f_{C} = \frac{1}{2\pi \sqrt{R_{1}R_{2}C_{1}C_{2}}} = \frac{1}{2\pi R_{1}C}$$

$$i_{1}^{2} R_{1} = R_{2} = R$$

$$f_{1} = R_{2} = R$$

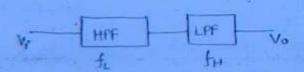
$$f_{1} = R_{2} = R$$

2"d order HP BHF-

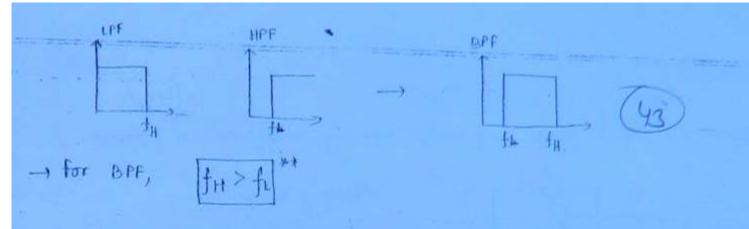


fc = same as above.

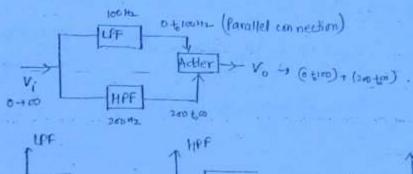
Band Pass filler:

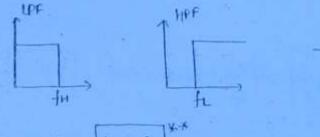


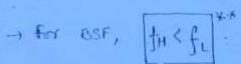
> series connection or cascading.



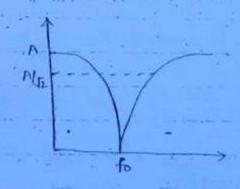
Band Reject (or stop or Rejection) filler







Notch Filter :-



Narrow band Band stop filter

BSF

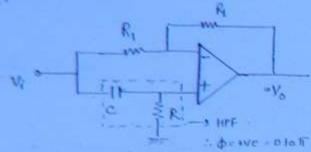
- Used in communication systems. to climinate fower supply noise

- Notch frequencies are 5012, 1001/2, co 42 etc.

- Also used to remove harmonics

#### All-Pass Alter:

-It allows all input signal peg to of who any amplification or attornect Lim -

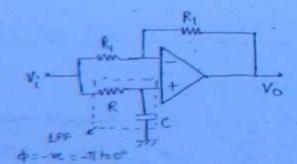


Applying superpositionfor non-inverting terminal-Yp = R+1 Yi

for inverting terminal - 
$$V_{01} = \begin{pmatrix} 1 + \frac{R_1}{R_1} \end{pmatrix} V_P = 2^V P$$
.  
 $V_{02} = -\frac{R_1}{R_1} \cdot V_1^* = -V_1^* \cdot - 2 \cdot ...$   $V_{01} = \frac{12 \cdot RCs}{RCs + 1} \cdot V_1^* \cdot ... = 0$ .

$$= V_0 = V_{01} + V_{02} = V_1 \left[ \frac{2RCs}{1+RCs} - 1 \right] \ge \left[ \frac{-1+RCs}{1+RCs} \right] = \frac{V_0}{V_1}$$

$$\frac{1}{2} A = -\frac{1 - RCs}{1 + RCs}$$
 3 |A|= 1



$$A = \frac{1 - RCS}{1 + RCS}; |A| = 1$$

$$\phi = -2 + \tan^{-1}(\omega RC)$$

$$\omega \to 0$$
  $\phi = 0$ 
 $\omega \to \infty$   $\phi = -180 \text{ in - TI}$ 

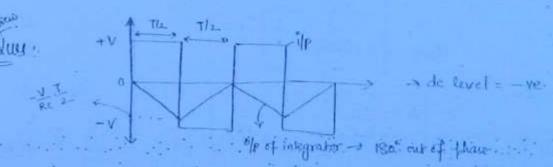
E Range of 
$$\phi = -11$$
 to 0"

$$\frac{c d(V_m - V_o)}{dt} = \frac{V_s - V_m}{R}$$

$$= \frac{V_s}{R} = -c \frac{dV_o}{dt}$$

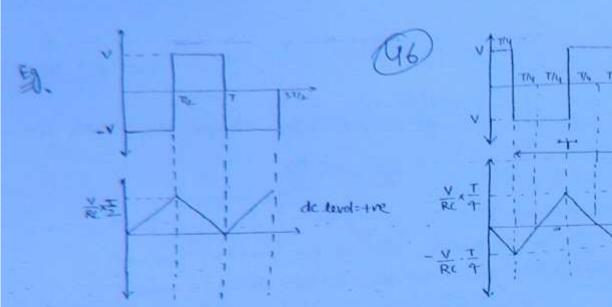
\* Linear charging of capacitor is fossible when we are providing constant current in the circuit and this can be achieved through current mirror circuit.

$$\frac{dV_0}{dt} = -\frac{V_s}{RC} \Rightarrow V_0 = -\frac{1}{RC} \int_0^t V_s dt + V_0(0^t)$$
initial value



$$\frac{dV_0}{dt}$$
 rate of change of of = slope =  $\frac{-V_s}{Rc}$ 

for 
$$V_{S}=\pm V$$
 =)  $\frac{dV_{0}}{dt}=\frac{-V}{RC}$  =>  $V_{0}$  \$\psi\$



- Time period of output = time period of input in all the three cases.

- only change is in the de levels of op.

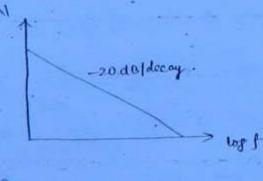
Swing =  $\frac{V}{RC} \times \frac{T}{2}$  is some in all the three cases.

$$\Rightarrow$$
 Swing =  $\frac{V}{2RCf}$ 

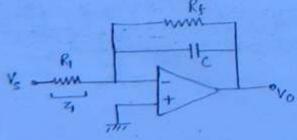
$$A = \frac{-2f}{Z_1}$$

$$A = \frac{-1}{R_1CS} = \frac{1}{j\omega RC}$$

bence one freq. stability. This is called foll off problem.



Practical Integrator :-



Tleading

V = 90° out of

de level

$$x_f = x_{cllR_f} = \frac{R_f \cdot V_{cs}}{R_f + V_{cc}} = \frac{R_f}{1 + R_f cs}$$

$$Z_1 = R_1$$
;  $A = -\frac{L_1}{Z_1}$ 

$$= A = -\frac{R_f/R_f}{1 + R_fCs}$$

$$\Rightarrow A = \frac{-(R_f/R_i)}{1+j\omega R_f C}$$

$$\rightarrow |A| = \frac{R_f/R_1}{\sqrt{1+\omega^2R_f^2C^2}}$$

-) At 
$$\omega=0$$
,  $IA I_{max} = \frac{R_f}{R_f}$ .

$$\frac{1}{R_1^2} = 1 + \omega_b^2 R_1^2 C^2 \qquad \Rightarrow \omega_b^2 R_1^2 C^2 \approx \frac{R_1^2}{R_1^2} \qquad \text{? Neglecting 1.}$$

$$\Rightarrow \left[\omega_b = \frac{1}{R_t C}\right]$$

$$\frac{1}{2\pi R_1 C} = \frac{1}{R_1 C} \quad \text{or} \quad \begin{cases} f_b = \frac{1}{2\pi R_1 C} \end{cases} \text{ and } \begin{cases} \frac{(?)}{1} & \text{find } 1 \text{ or } 1 \text{ or$$

-> Circuit acts as integrator between to and to

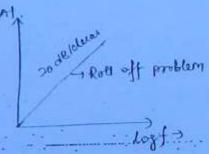
#3 
$$fa < fb =  $\frac{1}{2\pi R_{f}C} < \frac{1}{2\pi R_{f}C} \Rightarrow R_{1} < R_{f}$$$

$$V_P = V_n = 0$$

$$I = I_{\uparrow}.$$

$$c \frac{d}{dt} (v_s - v_n) = \frac{v_n - v_o}{R_{t,t}} \Rightarrow \frac{c \frac{dv_s}{dt}}{R_t} = \frac{-v_o}{R_t}$$

$$A = -\frac{R_f}{6Z_f} \Rightarrow A = -R_f Cs. = -j\omega R_f C.$$

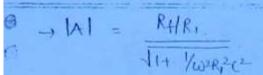


### Practical Differentiator :-

$$A = \frac{-R_f}{R_1 + \frac{1}{C_S}} = \frac{-\frac{R_f}{R_1}}{1 + \frac{1}{R_1}C_S} \Rightarrow A = \frac{-\frac{R_f}{R_1}}{1 - \frac{1}{2}\frac{1}{W_1}C_1}$$

$$z_1 = R_1 + V_{CS} = \frac{R_1 Cs + 1}{cs}$$

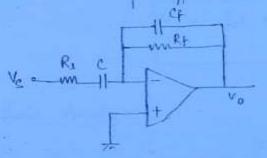
$$\Rightarrow A = \frac{-R_1/R_1}{1 - J/\omega R_1 c}$$

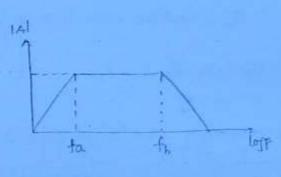


2010 (Rt) 2010 o delders st.

-> circuit is stable at high frequency.

$$\Rightarrow fa = \frac{1}{2\pi R_1 C}$$



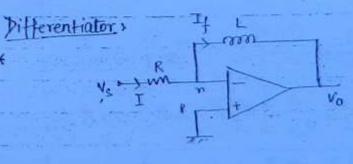


9

9

3

0



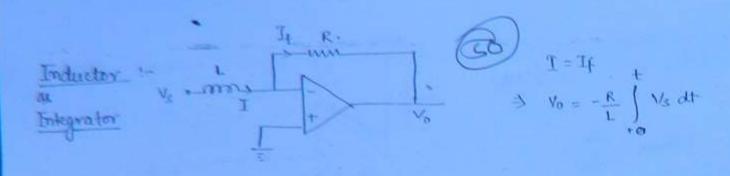
$$V_{P} = V_{n} = 0$$

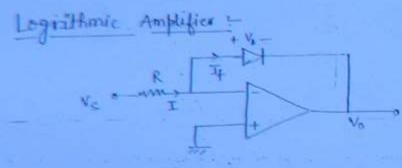
$$I = I_{F}$$

$$V_{S} = -\frac{1}{L} \int V_{0} dt$$

$$\Rightarrow \begin{bmatrix} -\frac{L}{R} \frac{dV_S}{dt} = V_0 \\ \end{bmatrix}$$

Library and Heavy due to L.





$$I_{P} = I_{\Phi} \left[ e^{\sqrt{P} | \lambda_{A} \lambda_{L}} - 1 \right]$$

$$I_{P} = I_{\Phi} \left[ e^{\sqrt{P} | \lambda_{A} \lambda_{L}} - 1 \right]$$

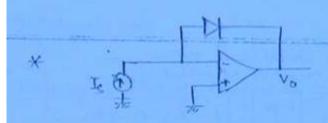
In = reverse saturation current

$$V_D = V_D - V_0 = -V_0$$

$$I = I_b$$

$$\frac{V_s}{E} = I_b \left[ e^{-V_0/\eta V_1} - 1 \right]$$

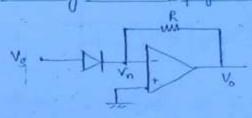
$$\Rightarrow \frac{V_s}{T_0 R} + 1 = e^{-V_0/\eta V_T} \Rightarrow \frac{V_0}{\eta V_T} = -\ln\left[\frac{V_s}{T_0 R} + 1\right]$$



$$\Rightarrow \qquad \boxed{V_0 = - \gamma V_T \ln \left( \frac{T_c}{T_0} \right)}.$$



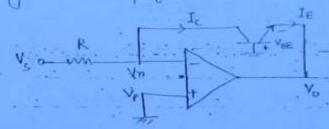
Anti- lognithmic Amplifier

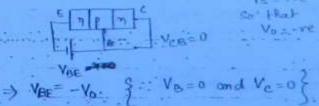


$$V_D = V_S - V_n = V_S \cdot j \qquad I = I_f = I_D$$

$$I_0 \cdot \left[ e^{V_S / \eta V_f} - 1 \right] = \frac{V_m - V_0}{R}$$

Logrithmic Amplifier:





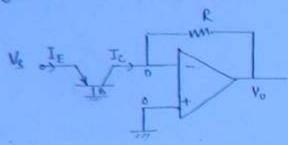
$$T_{b} = T_{c} \simeq T_{e} = I_{co} \left[ e^{\sqrt{e_{e}}/\eta V_{T}} - I \right] = \frac{V_{s}}{R}$$

$$= V_T \ln \left[ \frac{V_s}{I_{co}R} + 1 \right]$$

$$V_0 = -V_T \ln \left[ \frac{V_S}{I_{Co}R} \right]$$

$$= \left( \frac{V_S}{R} \right)_{\ell}$$





$$\Rightarrow I_{co} \left[ e^{V s / \eta V_1} - 1 \right] = \frac{o - Y_0}{R}$$

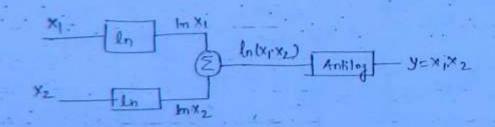


Tr. should be in active region, hence = Vs=tre.co that VEB = +ve

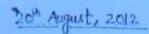
$$V_0 \cong - I_{co} R$$
 antilog  $\left(\frac{V_S}{\eta V_T}\right)$ 

### Applications

- Log and Antilog amplifies are used in designing of multiplication, division, square root and squaring circuits.



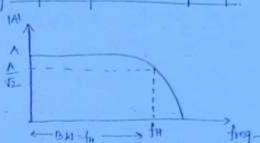
amplifier with gam=1.



6

8





$$(Z_c) = \frac{1}{2\pi f c}$$
 ;  $f \uparrow$ ,  $iz_c | \psi$ 

Slew Rate (SR) -

-> It is the time rate of change of closed look amplifier of prottage under large signal condition. (Typical value = the IV/µcec). Buit., V/µcec.

$$0 \rightarrow SR = \frac{dV_0}{dt} \Big|_{MAX} \Rightarrow SR = \frac{dV_0}{dV_1} \times \frac{dV_1}{dt}$$

$$\frac{dV_1^2}{dt} = \chi_m \omega \cdot \cos \omega t$$

$$\omega_{\rm m} = 2\pi f_{\rm m} = SR$$

IAcul Vm

SR = IACL X VmWm

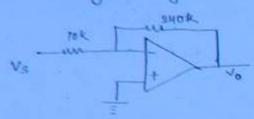
$$0 \Rightarrow for f \leq frn \rightarrow op without distribution  $0 \Rightarrow f \leq frn \rightarrow \cdots$  with "$$

Due - for an operational amplifier faving a SR of 2V/1620. For the What is the most elected loop vollage join that can be used when if

signal changes by our in 10 piece?



that can be used by taking  $SR = 05 \text{ V/}\mu\text{sec}$  and  $V_{\text{m}} = 0.02 \text{ V}$ .



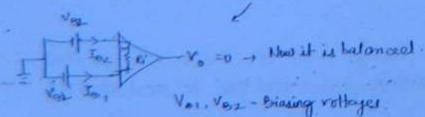
$$\therefore SR = |A_{CL}| \times \frac{dV_1}{dt}$$

$$\frac{\Delta n}{(2)}$$
  $|\Delta l| = \left| -\frac{240}{10^{11}} \right| = +24.$ 

NOR I Hal is not given, take hal 1.

"- Show rak is timited by internal capacitances of op-amp, hence it is not as.

Offset voltages and currents :-

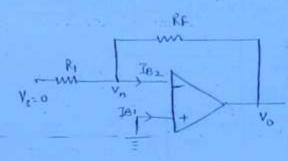


$$\Rightarrow$$
 ip bias current =  $I_B = \frac{I_{0,1} I_{0,2}}{2}$  when  $V_{0,2} = 0$ .



-> ilp offset current = Ito = Ie1-Ina when vo=0.

> ip offset voltage = Vio = Iio. Ri = Ve, -Vez volen Vo=0.



$$R_{1}^{l} = \begin{cases} V_{n} \\ \vdots \\ V_{k=0} \end{cases} R_{1} = 0$$

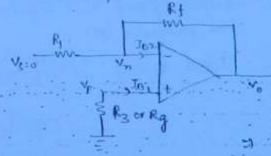
$$R_{1} = R_{1} + R_{2} = R_{1} + R_{2} = R_{3} + R_{4} = R_{4} + R_{5} = R_{5} + R_{5} = R_{5} + R_{5} = R_{5} = R_{5} + R_{5} = R_{5$$

$$|V_n| = Req. T_{\theta \perp} = T_{\theta \perp} [R_1 || R_f]$$
  
 $|V_p| = 0$ 

in Prinftifier is again unhalanced when vs=0 (ic wilkout signal) & feedback is connected.

-> Normally, Io, = IB2.

-. To balance the op-amp, R3 is connected to non-inverting terminal.



\* To minimise the effect of Up hias current, one should place in non-inverting terminal, a resistance equal to do recistance seen by inverting ferminal.

$$Z_c = \frac{1}{2\pi fc}$$
  $\Rightarrow$   $Z_c = \infty$  for  $X_c$ 

> Rg = [RI+0] HRf = Rf. AM

# Transfer Characteristics of Op-Amp :-



É

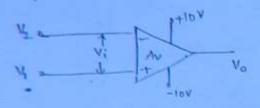
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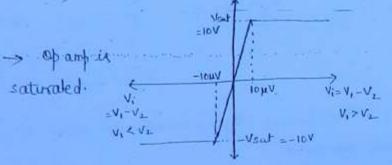
i) Practical Ob-amb :-



 $A_{V} = 10^{6}$   $V'_{1} = V_{1} - V_{2}$   $V_{0} = 10^{6} (V_{1} - V_{2}). \quad - 0$ 

Naw, I

- (i)  $V_1 = 10 \mu V$  ,  $V_2 = 9 \mu V$  $V_0 = 1 V$
- (a)  $V_{1} = 100 \,\mu\text{V}$ ,  $V_{2} = 90 \,\mu\text{V}$ =)  $V_{0} = 10 \,\text{V}$
- (ii)  $V_{j=120\mu V}$  ,  $V_{2}=160\mu V$ 
  - > 40 = 20 V but > 10 HV -
  - > Vo = 10 MV



 $V_{i} = V_{i}$   $V_{i} = V_{i}$   $V_{i} = V_{i}$   $V_{i} = V_{i}$ 

Practical op-amp with sufficient +ve feedback. (or)

Ideal op-amp , it, [Au = 0]

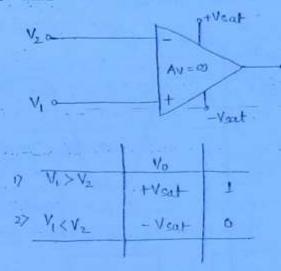
- As late 1, for a very small i/p, outfut will shook up to +Veat or -Veat depending on +Veat V1-V2 to be +ve or -Ve.
- > In a practical of amp, of voltage cannot exceed its biasing voltage, ie, range of of pvoltage is from Vsat to +Vsat.
- → of am) can enter into caturation when 
  (a) targe if signals are affilied. (> than few µV).

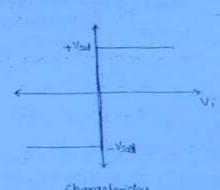
(1) When sufficient the feedback is footbed.



#### Comparator:

Ideal comparator:



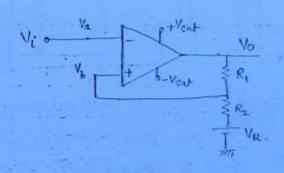


Characteristics

-> It is operated under open loop condition

# Practical Comparator:

### Schmitt - Trigger



$$\frac{V_b > V_a}{V_b < V_a} + \frac{V_{sat}}{V_{sat}} = 0$$

$$\Rightarrow V_{b} = \frac{V_{0} R_{2}}{R_{1} + R_{2}} + \frac{V_{R} R_{1}}{R_{1} + R_{2}}$$

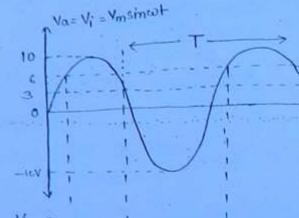
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$$V_{h_1} = \frac{V_{\text{sat}} R_2}{R_1 + R_2} + \frac{V_R \cdot R_1}{R_1 + R_2} = V_{\text{uth}} \rightarrow \text{Upper Threshold}$$

$$V_{b_{2}} = -\frac{V_{\text{sat}} R_{2}}{R_{1} + R_{2}} + \frac{V_{R} R_{1}}{R_{1} + R_{2}} = V_{LTH}$$

- lower Threshold.

Assumption = let Vom=Vy=GV > These are set, before applying VLTH : Vhz = 34. Vison the bould of Vm = lov. #Vent PVR ...

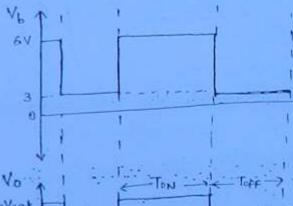


#### ( At t=0 ,

$$\label{eq:Vb} \mathcal{L} = V_b = V_{bi} = \mathcal{L}^V.$$

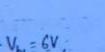
$$V_{i=V_a} = 0$$
  $\Rightarrow$   $V_b > V_a \Rightarrow V_o = \pm V_s a +$ 

Rena, car assumptions are right.



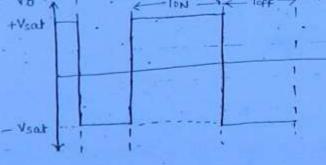
#### let Vo = - Veat

Hene out assumption was wrong Vo = + Veat



1) Vit; Va1 & when Va > Vb1 = 6V; then No switches from + Veat to - Vent

"\_ +6V " +3V . and VL



(2) Vil; Val 4 when Va 5 Vb2 = 3V,

then Vo shutches from - Vsat to + Veat.

" " +3v to +6Y.

Thus these two steps mull be repealed.

\* Necessary condition -



(a) Vi should I and cross Vum .; so that No switches from +Vest to - Yest

(b) Vi should be and cross Verne; ... vo ...

" - Veat " + Veat.

\* Time period of ofp . To = Ton+Topp = T= time period of i/P. 6

0

(3) 0

0

>> 50 % , > Asymmetrical square wave

0 > It is a equare wave converter.

()·

Vo = +V cat always.

0 1

0

0

: Vo = - Vsat always.

0



9

(2) Vi= 4 to 5.

Vo depends on initial condit of It West then will remain + Yes " - Veal- "

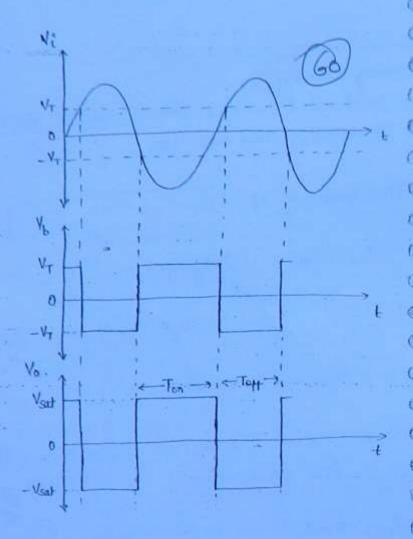
for b= 50%, VR=0.

$$V_{b_1} = \frac{+V_{\text{cat}} \cdot R_2}{R_{\Gamma^{\dagger}} R_2} = +V_{\Gamma}$$

Duty cycle :-

> Time benied of ofp = came as time period of ifp and hence by changing Ve he cannot change the prequercy of outbut, we can only change the duty cycle, in turn, the avg. de level (tre area) of ofp will change

7	VR = + Ve	D> 501.	
	VR = 0	D=50/1	
	VR = - WE	D < 50%	4

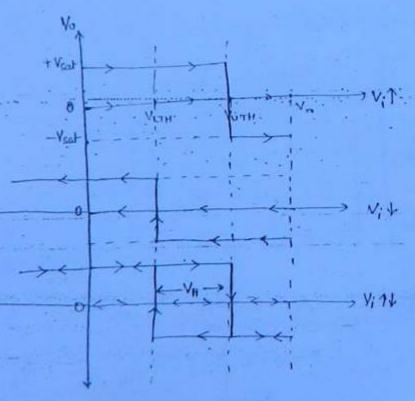


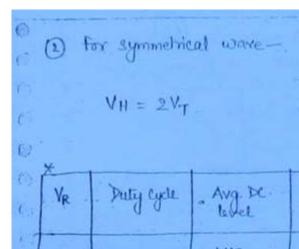
# Hysterisis Loop -

1) For Asymmetrical Ware -

VH = Hysterisis vallage

= VUTH - VLTH.





)	Y6	1		
_	- \v_1	G > YT	> Vm	→ VC'
		- Vsat		
	+	o !		-> Vit
<b>→</b> ←	-	Ys. Ir		
	_	0 4	>-	Vitt
	4 15	Veat		

-> This table is valid only for the circuit discussed contier.

$$\rightarrow V_{\overline{K}} = \frac{R_2}{R_1 + R_2} \cdot V_{5} \alpha + = \ll V_{5} \alpha + \frac{1}{3} \quad \alpha = \frac{R_2}{R_1 + R_2} < 1 \cdot \frac{1}{3}$$

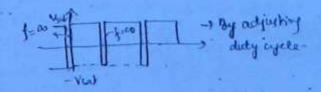
tystericis 100p

Hence, on non-inverting terminal, we are getting attenuated aquare wave

=) 
$$V_{H} = \frac{2 V_{\text{Sat}} \cdot R_{2}}{R_{1} + R_{2}}$$
 =)

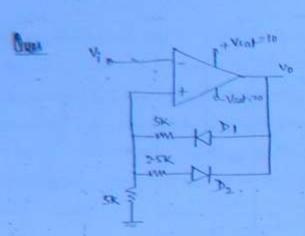
=) VH = 2 Vsat. R2 => | Hysterisis voltage is independent of VR; only the position of loop will change

- A slow moving waveform (sint) can be converted into a fast moving waveform (square wave) by using schimit trigger.



- By adjusting - slew Rate should be high so that the triggering pulse reaches It Year or - Vest very fast.

Hunce, SR 1 for triggering op-amp.

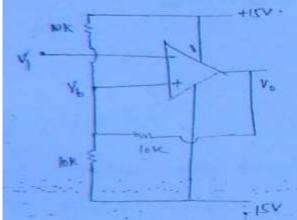


Consider schmidt bi

(62)

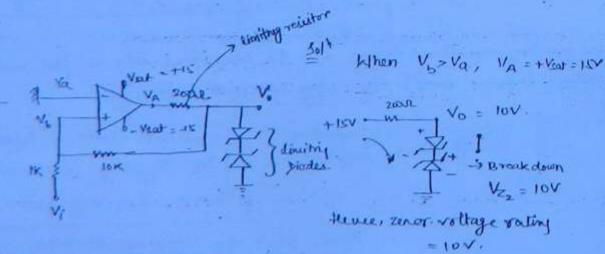
$$V_{b_2} = \frac{-10\times5}{7.5} = -6.67 \text{ V}$$
 $V_{b_2} = \frac{-10\times5}{7.5} = -6.67 \text{ V}$ 
 $V_{b_3} = \frac{-6.67 \text{ V}}{7.5}$ 
 $V_{b_4} = \frac{-10\times5}{7.5} = -6.67 \text{ V}$ 

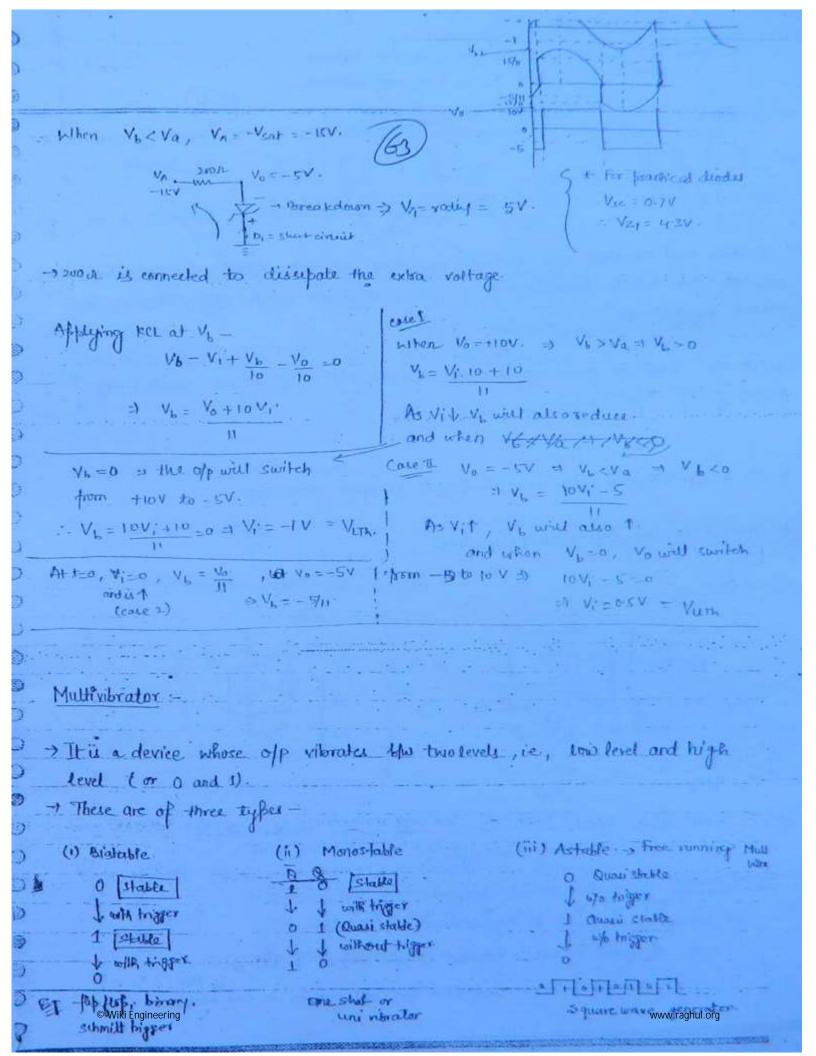
applied to inverting if of opening. Assume that of swings from -12 to + 12 v is to +15 v. The voltage at non-inverting if switches Hw.



$$V_{b} \left[ \frac{1}{10} + \frac{1}{10} + \frac{1}{10} \right] - \frac{15}{10} + \frac{15}{10} - \frac{V_{0}}{10} = 0$$

$$3 V_{b} = V_{0}$$



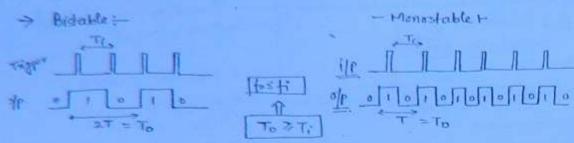


with vi not vay high.

\* without vit then volt and vice versa > -ve feedback.

" Vit - Vot and " = +ve feedback.

(64)

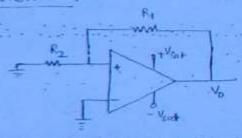


- -> Bictable and Montstable are a simply convertors and not square wave generators whereas for Astable Multivibrator, no need of an input / trigger to gammate square wave.
- > Fastest ofp mill be given by a stable multivibrator as it is not limited by frequency of input trigger.

- Adable multivibrator is often used as fastest wavefrom generator.

Multivibrator by using operational Amplifier:

Bistable Multivibrator :-



$$V_{\parallel} = \frac{R_2}{R_1 + R_2}, V_0 =$$

Tritally . Vo=0, Vb=0, Va=0

=) Vi=0=1 Vb=0 (Idealy).

but because of noises

> Ve again I due to Vo and it will keep on I till it st the peaches + Vsat. and then elect will remain in one stable state.

-> Recause of noise, of pinitially can be at +Vest or - Vest depending on initial

Eg Let R, = R2 and Veat=10V =) Vb = 5V.

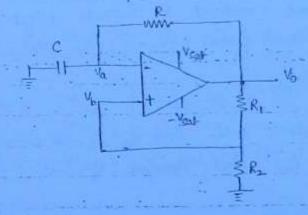
Now, to change the stable state of Vb from + Vert to - Year -

- (a) Positive toigger can be applied at Va (orr)
- (6) Negative " " " " Vb and Ingger value should be more than the present Vb value (ie, more than sv)

switch of to its other stable state

- It has volable memory i.e., memory is lost where power supply is interrupted.

Astable Multivibrator / Square Wave Generator =



$$\frac{V_{k} = R_{2}}{R_{1}tR_{2}} = V_{5} = -0$$

At t=0, Vo = +Veat ( by noise). Vb = R2Veat = VT

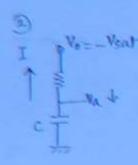
 $V_b > V_a \Rightarrow V_b = + V_{cat}$   $\Leftrightarrow$  but  $V_a = V_c = 0$ 

9

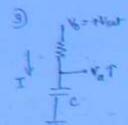
> capacitor nive stort charging and the voltage of terminal

Va will stort increasing. As soon as Va reaches. Vt,

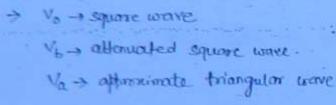
Vo will switch to - Veat.



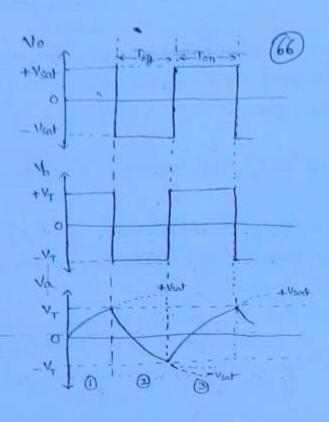
> capacitor will startdischarging or startarmying towards - Vest



+ capacitor will again
start changing towards
+ Vsat.



-) Swing of  $V_0 = TV_{\text{sat}} t_0 + V_{\text{sat}}$ ...  $V_0 & V_b = -V_T t_0 + V_T$ 



- At initial condition, emsider  $V_0 = + V_{Sat}$ ,  $V_1 = + V_T$  and  $V_2 = V_0 = 0$ .

  Now, capacitor will charge by time constant RC lowerds  $+ V_{Sat}$ .

  Capacitor will charge upto  $+ V_1$  at this point  $V_2 = V_1 = + V_T$  and  $V_3 = V_4 = + V_7$  and  $V_4 = + V_7$  and  $V_5 = + V_7$  and  $V_6 = + V_7$  and  $V_7 = + V_7$  and  $V_8 = + V_8$  and  $V_8 = + V_8$
- When the capacitor further changes above + 47 then 1/2 / Yb as a result of which vo south over to -1/2 and therefore 1/6 = -1/7.
- How, experitor starts discharging from +V<sub>T</sub> to -V<sub>T</sub> towards -V<sub>Set</sub> . with time constant RC. Thus, when expector discharge upto -V<sub>T</sub>, then Va=V<sub>b</sub>= -V<sub>T</sub> and of omp comes set of saturation. When the capacitor further discharges below -V<sub>T</sub>, then Va<V<sub>b</sub>, as a result of which Vowill switch over to +V<sub>Set</sub> and again Y=+V<sub>T</sub>. and thus, the expell will adject.

Derivation of Ton:

capacitor charges from -VT to VT in time Ton.

$$V_c = V_a = V_f - [V_f - V_i]e^{-t/c}$$

 $V_t = -V_T$  at t=0,  $V_f = +V_{\text{sat}}$  at  $t=\infty$ .

At t = Ton -

Derivation of Top: - capacitor discharges from YT to -YT in lime Topp.

$$V_t = V_T$$
 at  $t = 0$ ,  $V_f = -V_{SQF}$  at  $t = \infty$ .

$$V_c = -V_{sat} - \left[-V_{sat} - V_T\right]e^{-t/Rc}$$

$$\Rightarrow \overline{T_{\text{off}}} = RC \ln \frac{V_{\text{sat}} + V_{\text{T}}}{V_{\text{sat}} - V_{\text{T}}}$$

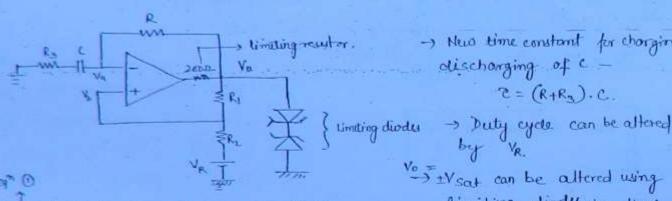
2 Square wave Generator.

(62)

-> Astable rullivibrator alocs not has any stable stated due to continuous changing & dicharging of c.

Time period, 
$$T = 2RC \ln \frac{V_{Sat} + V_T}{V_{Sat} - V_T}$$
 [eqh 0]
$$V_T = \frac{R_2}{R_1 + R_2} V_{Sat} \implies T = 2RC \ln \left[ 1 + \frac{2R_2}{R_1} \right]$$

> | f = 1 - > frequency of . Square wave generated.

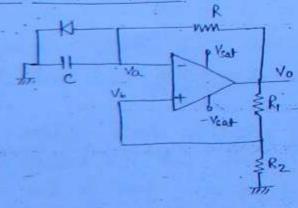


\* Time berived / charging of cis non linear, to make it linear, we can use a current mirror circuit in place of R'.

-> New time constant for charging/ discharging of c -2= (R+R3).C.

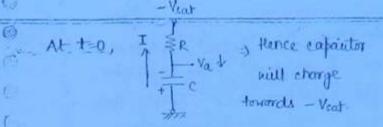
Vo = ±Vsat can be altered using limiting diods , ie, final Voltage states of changing & dischanging of c can be changed.

Monostable Multivibrator

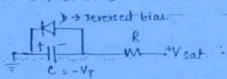


t <0. - ckt is in stable state. Let Vo = + Vsat > Diode -> ON > Va=Vc=0  $V_b = \frac{R_2}{R_1 + R_2}$ ,  $V_{sat} = +V_T > V_a = 0$ 

- At to, I at b is given. so that Vb<Va > 1/6 = - Vsat and Diode = Off



Once, Vc reaches - VT, Vo will switch to + Veat but capacitor closs not allow sudden change of voltage and it will start charging toronds + Veat, since Diode will be off.



0

and it will stook, stop charging.

a 1/0

· Veal

V

-47

stable Quaristable

Ve = Va + Dan 1 Does Does Does

22nd August, 2012:-

Derivation of Tp - (Pulse width) 
C ducharges from 0 to - VT.

Vc = Va = -Vsat - [-Vsat - 50]e 
> Vc = Vsat [++ e-t/Rc]

At 
$$t = T_{P}$$
,  $V_{C} = -V_{T}$   
 $= -V_{T} = -V_{SQL} \left[1 - e^{-t/RC}\right]$ 

+hen 
$$R_{x}=R_{1}$$
,

then  $T_{p}=Rc \ln 2=0.63Rc$ 

- Wash

withen 
$$R_1 = R_2$$
,  $T_2' = RC \ln (3/2)$ .

Circuit Sention



- For TCO, eirouit is in stable state with Vo=+Vsat, Nb=+VT, Ve=Va=0.

Since Vo=+Veat, diode is forward biased of skort ext the capacitor, therefore capacitor will not charge and ext will remain in stable state.

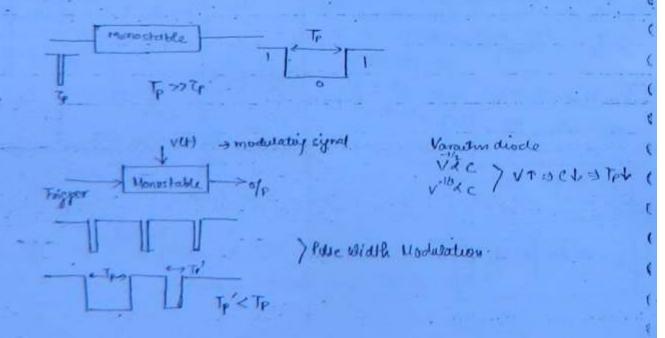
New we apply we trigger at to and for efort interval, Volva and Vo will write from + Voto - Vo. How diede is revose blood and capacitor will discharge below O towards - Veat-with a time constant RC.

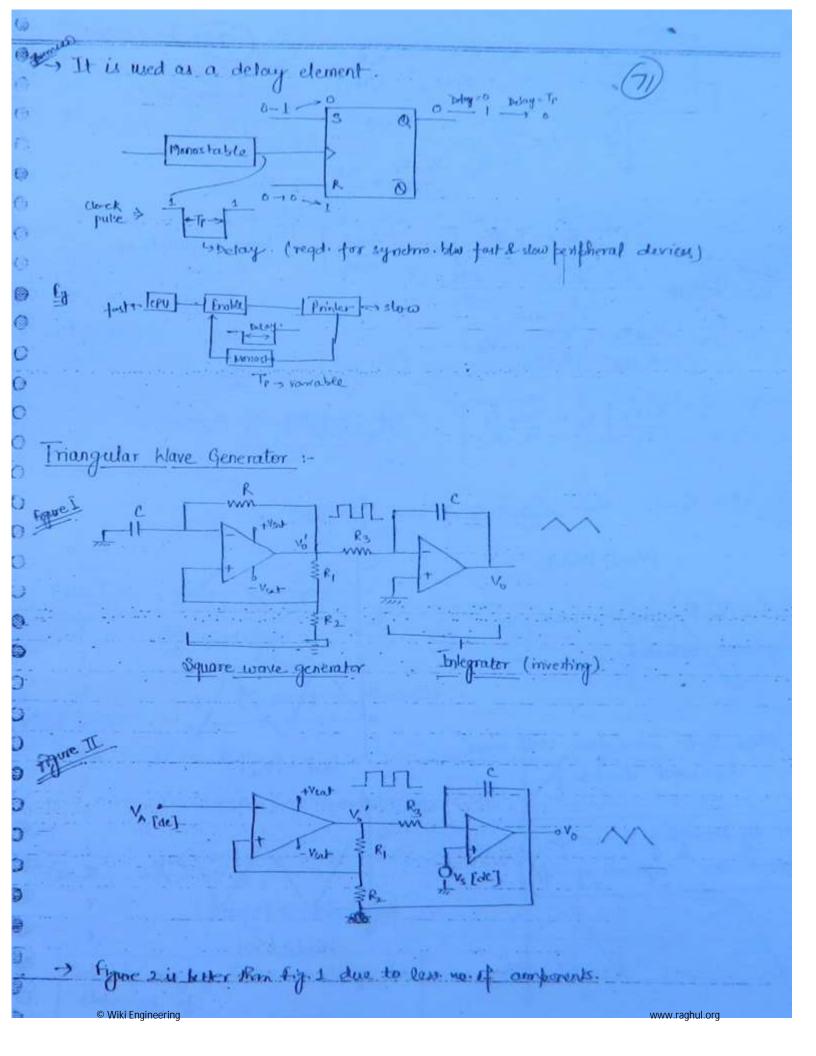
- When copacitor discharged upto - 47, then  $V_a = V_b = -V_T$  and of-amp comes out of saturation, when capacitor further discharges below -  $V_T$ , then  $V_a < V_b$  as a result of which  $V_0$  switch over to +  $V_{sat}$  and again  $V_b = +V_T$ .

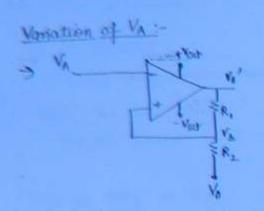
Nowithe Capacitor will charge above -Vy towards +Vsat but capacitor can charge and pite a becomes forward biased and se the capacitor.

#### Aplication:

It is used as Palse strether circuit.







$$\frac{V_b = \frac{V_b' R_2}{R_1 + R_2} + \frac{V_b R_1}{R_1 + R_2}$$

$$\geq V_{h_1} = \frac{V_{SA} + R_2}{R_1 + R_2} + \frac{V_0 R_1}{R_{rt} R_2} = VA$$

= 
$$\frac{1}{N_0} = \frac{R_1 + R_2}{R_1} \left[ V_A - \frac{V_{\text{sat}} R_2}{R_1 + R_2} \right] = \frac{\text{lower amplitude of}}{\Delta \text{ wave}}$$

$$\Rightarrow V_{b_{2}} = -\frac{V_{500}R_{2}}{R_{1}+R_{2}} + \frac{V_{0}R_{1}}{R_{1}+R_{3}} = V_{A}$$

$$\Rightarrow V_0 = \frac{R_1 + R_2}{R_1} \left[ V_A + \frac{V_{00} + R_2}{R_1 + R_2} \right]$$

= upper amplitude of \( \Delta \) wave-

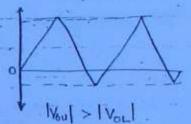
$$\underline{\underline{Case T}} - \text{ when } V_{A} = 0, \quad V_{od} = \frac{R_2}{R_1} V_{Sat}, \quad V_{oL} = \frac{-R_2}{R_1} V_{Sat}$$

|Vou = |VoL .

hither Va 1, waveform will more. Voi

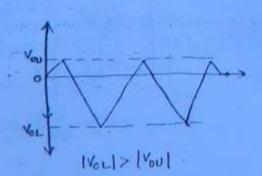
- in upward direction.

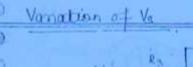
IVail = IVaul



buell when VAI, wave form will more in dam word direction -

Hence, by changing Va, we can control the amplitude of o/p.





1

(8)

$$V_{p} = V_{n} = V_{s}.$$

$$I_{f} = I.$$

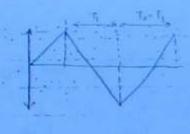
$$C \frac{d}{dt} (V_{3} - V_{0}) = \frac{V_{0}' - V_{s}}{c}$$

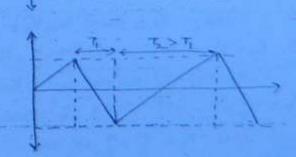
) Since 
$$V_2 = dc = 1$$
  $\frac{dV_5}{dt} = 0$   $\Rightarrow$   $\frac{dV_0}{dt} = \frac{V_0' - V_2}{R_3}$ 

$$\Rightarrow \frac{dV_0}{dt} = \frac{-\left[V_0' - V_0\right]}{R_3C} \qquad \boxed{D}.$$

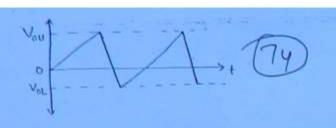
$$\frac{dV_0}{dt} = -\frac{V_{\text{sat}}}{R_3C} ; \qquad \frac{dV_0}{ctt} = \frac{+V_{\text{sat}}}{R_3C}.$$

$$\Rightarrow | \mathcal{I}_{\text{stope}}| = | \uparrow_{\text{stope}}|.$$

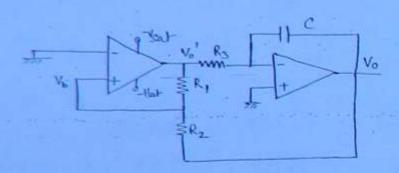




G for VA = 2V , Vs = -2V. > : VA = +ve > |Vou| > |VoL| Ve=- 12 => 1 stope > 1 stope



Symmetrical Triangular Wave (with VA=0 and Vs=0):



1) If 
$$V_0' = + V_{\text{sat}}$$
,  $V_0$  will I will slope  $\frac{dV_0}{dt} = \frac{-V_{\text{sat}}}{R_3C}$  with  $V_0 = -\frac{R_2}{R_1} V_{\text{sat}}$ .

tet Risky and real = 10V.

$$V_b = \frac{R_b}{R_1 + R_2} \cdot V_0' + \frac{R_1}{R_1 + R_2} \cdot V_0 \cdot = \frac{V_0'}{2} + \frac{V_0}{2}$$

producto notice.

let at t=0, Vo = + Veat = 10 V

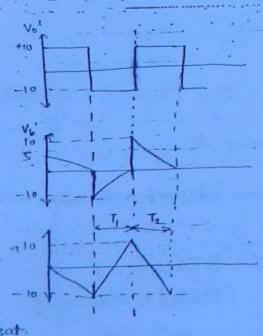
1. V1 = 5 V > Va = 0 => 1/2 + Mah

" Vo = + Vsat, Vo & and in turn Vs ...

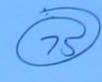
when  $V_0 = V_{0L} = -10 \, \text{V}$ ,  $V_b = \frac{10}{2} - \frac{10}{2} = 0 \, \text{V}$ .

Nos; " Vb s Va, Vo' Switches from + Vsat-to - Vsat.

1/6 = -10 -10 = -10v. and : "V' = Vsat, =) Vo will 1 and What and when Vo=Vor=lov then Vb = -10 + 10 = 0V and : Vb = Va; Vo! switches from - Vgat-to + Vgat and cycle will be repealed.



Calculation of Tr and T\_ -



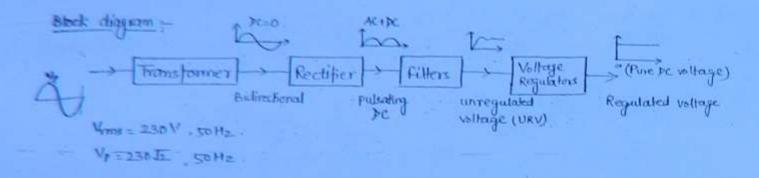
$$\Rightarrow T_1 = \frac{V_{OU} - V_{OL}}{dV_O/dt} = \frac{R_2/R_1 V_{Sat} - \left(-\frac{R_2}{R_1}\right) \cdot V_{Sat}}{V_{Sat}/R_3C} \Rightarrow T_1 = \frac{2R_2R_3C}{R_1}$$

$$\overline{J_2} = \frac{V_{OL} - V_{OU}}{dV_0/dL} = \frac{-\left(\frac{R_2}{R_1}\right)V_{\text{cert}} - \left(\frac{R_2}{R_1}\right)V_{\text{cert}}}{-V_{\text{cat}}/R_3C} \Rightarrow \overline{J_2} = \frac{2R_2R_3C}{R_1}$$

-> Time period = 
$$T = T_1 + T_2 \Rightarrow \left[\frac{4R_2R_3C}{R_1} = T\right]$$
 or  $\left[\frac{f}{4R_2R_3C}\right]^{\frac{1}{2}}$ 



\* Rechiliers :-



- Basic perfose of a rectifier is to convert a bidirectional voltage or current waveforms.

Important terms :-

- Average of DC level, 
$$I_{dc} = \frac{1}{2\pi} \int_{0}^{2\pi} I(t) dt\omega t$$
.

Ros value , 
$$T_{RMS} = \begin{bmatrix} \frac{1}{2\pi} & \frac{2\pi}{3} & \frac{2\pi}{3} \\ \frac{1}{2\pi} & \frac{1}{3} & \frac{2\pi}{3} \end{bmatrix}^{\frac{1}{2}}$$

Mille Voltage :

de = de value of ofp

Name = RMS value of ac component

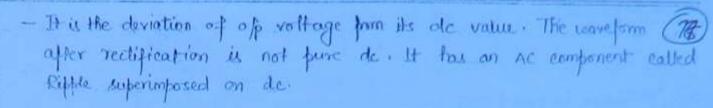
let Volc = 8 V and Vacous = 3V & Vacous 35-

(V= 8+352 Smult Ritple (Variation of ofe vollage () from force de)

- Matternatical actives

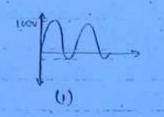
hy s. is actual representation.

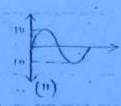
(Rupple superimposed on de.)



form factor:-
$$f = \frac{V_{rms}}{V_{dc}} \Rightarrow r = \sqrt{F^2 - 1}$$
- Ideally,  $f = 1$ 

- It should be as low as possible





should be preferred since peak is it and circuit elements will have to be designed accordingly.

> Peak Inverse Voltage (PIV)

- It is the max voltage across the diade in neverse direction, ie., when the diade is reverse blased.

- Diode is selected on the basis of PIV rating.

- PIV should be as low as possible.

- We can 1 PIV of ckt by caseading twoor more objects in series.



## Transformer Utilization factor (TUF) :-

- It indicates how much is the utilization of transfermer in the circuit

- It should be as I as possible.

Types of Rectifiers.

D Half wave Rectifier (2) full wave rectifier - (a) Center teapfed transformer type

(b) Bridge Rectifier.

### Workbook

Chab-10

1) 
$$(Av)_{da} = 20 deg Av = 80$$
  
=)  $Av = 10^{4}$ .

Alternate

find the point where 20d Bldec. is inkreaching frequ

$$\frac{10k}{1K} = \frac{10k}{1k} \Rightarrow CMRR = \emptyset \Rightarrow A_C = 0$$

$$\Rightarrow V_0 = A_1(V_1 - V_2)$$

$$\Rightarrow V_0 = 0$$

$$49 \quad V_0 = \left(1 + \frac{4 \cdot N_1}{10}\right) \cdot V_p = \int_2^{\infty} V_p = \left(\frac{V_{CS}}{P + V_{CS}}\right) \sin t = \left(\frac{1}{1 + j}\right) \sin t$$

=) 
$$V_0 = \frac{\int_{z=1}^{z} \sin(t)}{(1+i)}$$
 =>  $V_0 = \frac{1}{2} \sin(t-1)/4$ .

5> (c). 6> 
$$V_0 = \left(1 + \frac{2R}{R}\right) \left[\frac{3in(100t) + 2 - 2}{2}\right] = \frac{3}{2} \cdot sin(100t)$$

6.

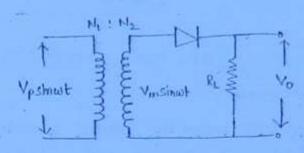
1 =

0

0

0

## Half-Wave Rectifier :-

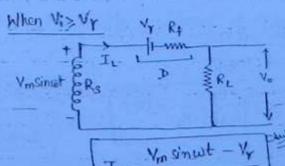


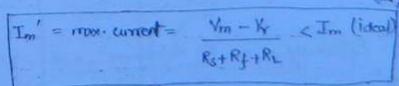
$$\bigcirc \longrightarrow V_0 = \mathbb{I}_L \cdot R_L = \quad \forall_{rn} \cdot \text{s'mut} \quad (\text{ideal case}) \ .$$

$$(\bigcirc -)$$
 When  $b \to c + F$ ,  $I_L = 0 + \Rightarrow Y_0 = 0$ 

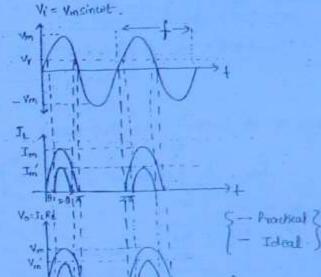
$$\Rightarrow$$
 Conduction angle  $\phi = 11$  or 180".

RS+R++RI





$$\frac{V_P}{V_m} = \frac{N_1}{N_{2}}$$





? Ripple frequency will remain same as ideal case

$$\Rightarrow \text{ Conduction angle } \phi = 11 - 20 \cdot \left\{ < 180^{\circ} \right\}$$

$$V_{m} \sin \theta = V_{\gamma} \Rightarrow \left[ 0 = \sin^{-1} \left( \frac{V_{\gamma}}{V_{m}} \right) \right]$$

Average or de level - ( For Half waxe )

$$I_{cle} = \frac{1}{2\pi} \int_{0}^{\infty} I_{cm} \sin \omega t \ d(\omega t). \Rightarrow \left[I_{cle} = \frac{I_{rm}}{\Pi}\right] - \text{for Ideal}$$
Similarly.
$$V_{cle} = \frac{V_{m}}{\Pi} - \text{for Ideal}$$

- RMS value - ( for Half ware).

$$I_{mos} = I_m$$
,  $V_{mos} = \frac{V_m}{2}$ 

- form factor = 
$$\frac{V_{rms}}{V_{dc}}$$
  $\Rightarrow$   $\boxed{f = 1.57}^{*X}$ 

- Riphle factor = 
$$\frac{V_{acmu}}{V_{dc}} = \sqrt{F^2 - 1} \Rightarrow \sqrt{T = 1 \cdot 21}$$

$$-\boxed{PIV = +V_{m}} \quad \left( \text{ Drop censes } R_{L} = 0 \right), \quad : I_{L} = 0 \right). \Rightarrow \boxed{\eta = \frac{4}{\pi^{2}} \cdot \frac{R_{L}}{R_{L} + R_{S}} \cdot \times 100 / .}$$

- Rectifier Efficiency, 
$$\eta = \frac{\sigma f r}{r} \frac{de + fower}{r} \times 100\%$$
  $\Rightarrow \eta = \frac{Tat. R_L}{I_{mis}} \frac{100\%}{(R_L + R_S)}$ 

$$\Rightarrow \boxed{\eta = \frac{4}{\pi^2} \cdot \frac{R_L}{R_L t R_f + R_S} \cdot \times 100^{-1}}$$

=) 
$$\eta = 0.406 \times \frac{1}{\frac{R_s + R_f}{R_L} + 1} \times 100\%$$



metal, means only 40%. ac power is converted to de

-) If the efficiency is 10%, it means that 40% of ac fower is converted into de and remaining 60% (approx) power is in form of riffle (ac component at ofp).

## The venin's equivalent of Half Wave Rectifier

$$V_{th} = \begin{cases} \frac{R_{th} - T_{de}}{V_{th}} & T_{de} = \frac{V_{th}}{R_{th} + R_{L}} \\ V_{th} = T_{th} = R_{L} \end{cases}$$

$$\underline{T}_{de} = \frac{v_{m_1}}{R_{m_1} + R_L} - \underline{0}$$

$$I_{dc} = \frac{1}{2\pi} \int_{0}^{\pi-0} I_{L} d\omega t \quad ; \quad \theta = Sin^{-1} \left( \frac{vl_{Y}}{v_{m}} \right) \quad ; \quad I_{L} = \frac{V_{m} sin \cot - V_{Y}}{R_{L} + R_{f} + R_{L}}$$

Let 
$$V_{T} = 0$$
,  $\Rightarrow 0 = 0$ ,  $T_{L} = \frac{V_{m} \sin \omega t}{R_{C} + R_{T} + R_{L}} = T_{m} ' \sin \omega t$ .

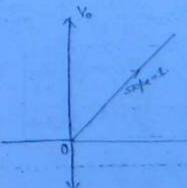
$$\frac{1}{2\pi L} = \frac{1}{2\pi L} \int_{0}^{\infty} \frac{1}{2\pi L} \int_{0$$

\* RTA is the ofp resistance of ext & it represents the losses occurring at off.

Transfer Curve:

Ideal :

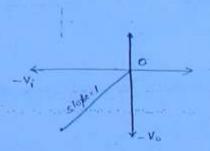
D	Vo
off	0
OH	Vi
	oft.



Vi	D	Vo
VisVy	OFF	$T_{L}R_{L} = \frac{\left(V_{i-}V_{r}\right)}{R_{d}+R_{L}+R_{d}} \times R_{L}$
W > VY	ON	ILRL = (Vi-Vr) XRL

slepe = 
$$\frac{R_L}{R_S + R_L + R_f}$$
 < 1

\* If diode polarity is reversed, then chance will come into III quadrant



- 1 Max, average and rms value of current
- 3 De value of ofp voltage
- 3 Efficiency.

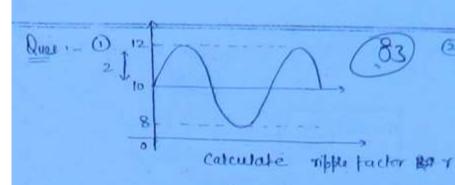
$$Sole V_{min} = \frac{230}{3} \text{ Vm} = \frac{230 \text{ Jz}}{3} \text{ V.} = 108.4 \text{ V}$$

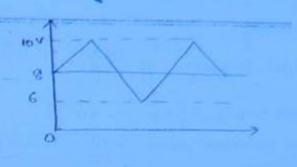
$$Im = \frac{V_{10} - V_{1}}{R_{2} + R_{1} + R_{2}} \approx \frac{230 I_{2}}{3 (10 \text{ K})} = \frac{23 I_{2} \text{ mA}}{3} = 10.84 \text{ mA}$$

$$I_{2} = I_{2} = I_{3} = \frac{I_{3}}{II} = \frac{23\sqrt{2}}{3\pi}, \quad mA = 3.45 \quad \forall_{dc} = I_{dc} \times R_{L} = \frac{23}{3\pi} = 34.5 \vee R_{dc} = \frac{23}{3\pi} = 34.5 \vee R_{dc} = \frac{23}{3\pi} = 34.5 \vee R_{dc} = \frac{23}{3\pi} = \frac{23}{$$

$$\frac{3664}{34064} = \frac{239}{34064} = \frac{334064}{34064} = \frac{3406 \times 106}{1064} = \frac{40.6.1}{1064}$$

$$I_{mg} = \frac{I_m}{2} = 5.42 \text{ m/s}.$$





$$0) \quad F = \frac{\sqrt{3m_3}}{\sqrt{dc}} = \frac{\sqrt{10^2 + (2/J_2)^2}}{10} = \frac{\sqrt{102}}{10}$$

$$\therefore \gamma = \sqrt{F^2 - 1} = \frac{1}{5J_2}$$

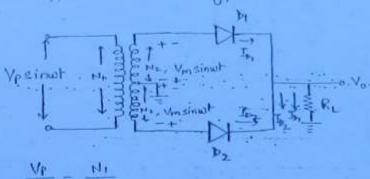
$$Y = \frac{V_{acms}}{V_{dc}} = \frac{(2/5)}{10}$$

$$Y = \frac{1}{512}$$

① 
$$T = \frac{V_{acmg}}{V_{clc}} = \frac{(2/13)}{8} = \frac{1}{415}$$

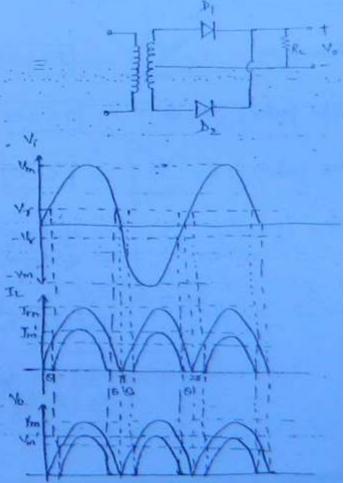
## Full Wave Rectifier :-

a) Center Taffeel Transformer Type:



$$\frac{V_P}{V_{PR}} = \frac{H_1}{H_2}$$

Ideally: 
$$I_L = \frac{V_{msinwt}}{R_L} = I_{msinwt}$$
;  $I_{m} = \frac{V_{ra}}{R_L}$ 



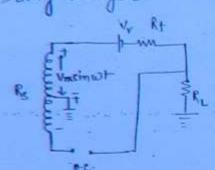
## Practically:

- -> Ripole beguency, +======
- -) for cirait, φ = 211-40 for individual diade , \$ = TT-20.



$$0 = \sin^{-1}\left(\frac{V_r}{V_m}\right)$$

During we cycle-



$$T_{L} = \frac{V_{m}sin\omega t - V_{\gamma}}{R_{\zeta} + R_{L} + \frac{R_{\zeta}}{2}}; \qquad T_{m}' = \frac{V_{m} - V_{\gamma}}{R_{\zeta} + R_{L} + \frac{R_{\zeta}}{2}}$$

$$I_{m}' = \frac{V_{m} - V_{\gamma}}{R_{f} + R_{L} + \frac{R_{\zeta}}{2}} \left( \xi I_{m} \right)$$

$$V_{dc} = \frac{2 \cdot V_m}{\pi}$$

$$\Rightarrow \boxed{I_{mny} = \frac{I_m}{\sqrt{2}}} ; \qquad \boxed{V_{mny} = \frac{V_m}{\sqrt{2}}}$$

$$\Rightarrow$$
 form factor,  $f = \frac{V_m/2}{2V_m/n} \Rightarrow f = 1.11$ 

$$\rightarrow$$
 Great factor;  $C = \frac{V_{rn}}{V_{rn}/J_2} =$   $C = \sqrt{\Sigma}$ 

$$\Rightarrow \text{Rectifier Efficiency}, \quad \eta = \frac{dc}{ac} \frac{o/p}{power} \times 100\%$$

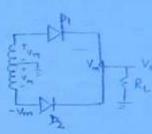
$$\Rightarrow \eta = \frac{0.812 \times 100\%}{\left(1 + \frac{Rt}{R_L} + \frac{Rs}{2R_L}\right)}$$

$$\Rightarrow \eta = \frac{I_{dc}^2 \cdot R_L}{I_{pns}^2 \left(\frac{R_s}{2} + R_f + R_L\right)} \times 100^{1/3}$$

$$\Rightarrow \eta = \left(\frac{0.812 \times R_L}{\frac{R_S}{2} + R_{f} + R_L}\right) \times 100^{-1}$$

$$\Rightarrow \eta = \frac{0.812 \times 100 \%}{\left(1 + \frac{R_{\rm L}}{R_{\rm L}} + \frac{R_{\rm S}}{2R_{\rm L}}\right)}$$



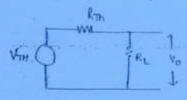


$$V_{b_2} = V_{P} - V_{P1} = -V_{P1} - V_{P1}$$

$$\Rightarrow V_{b_{2}}^{2} = -2V_{m} \qquad ; \text{Swhen } V_{b} \geqslant 0 \quad D \rightarrow FB$$

$$\Rightarrow PIV = 2V_{m} \qquad V_{b} \leq 0 \quad D \rightarrow RB$$

## Thevenin's Equivalent: of FWR :-



$$R_{Th} = \frac{R_S}{2} + R_T^*$$

$$V_{TH} = \frac{2V_m}{\pi}$$

### Transfer curve :

Danal			
			٠
TORUL	~~	н	ł

V:	Dr	D <sub>2</sub>	V <sub>b</sub>
VLCO	off	010	$-V_t$
Vi>o	on.	off	.Vi.

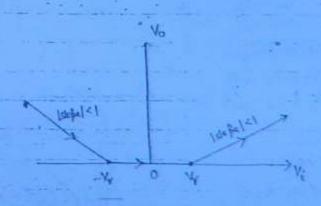
Vi	Di	- b <sub>2</sub>	Vo.
Yis-Yr	off	ON	Vo!
Ves Vis Ve	off	off	0
$V_i > V_v$	on	off	V.

1 Vo = 1V1

$$V_0' = I_L R_L = \frac{V_1 - V_V}{\frac{R_S}{2} + R_L + R_L} \times R_L$$

$$V_{6}' = I_{L}R_{L} = \frac{V_{1} - V_{Y}}{\frac{R_{5}}{2} + R_{f} + R_{L}} \times R_{L}^{-1}$$

$$globe = \frac{R_{L}}{\frac{R_{5}}{2} + R_{f} + R_{L}} (< 1)$$



> [slope]<1

> If the polarity of directed is reversed, thus transfer curve will be present in III and IV quadrant.

86)

In practical condition, it is not possible to rectify very small signals using centre tapped Trouter rectifier.

foreg. V:= 5 simult mV >> Vm = 5 mV = 0.005 V << Vy , hence .0/p

herkbook (thap-10).

@ t

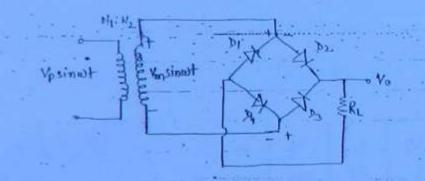
24th August , 2012

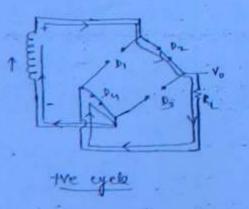
Bridge Rectifier .

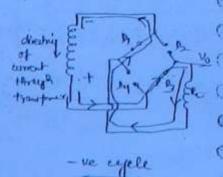
$$\frac{V_{f}}{V_{m}} = \frac{H_{1}}{N_{2}}$$

for positive half-D1 & D3 Off. D2 & D4 OH

for the half-D, ED3 ON D, ED4 OH.







- The current through transformer evil is bidirectional, hence any de component is

TUF is maximum for bridge reclifier due to above mentioned neason.

- Zero de frevents the Eddy current, hydroisis losses and saturation of xnon.

$$\frac{\text{Toleally}}{\text{Tole}}$$

$$\frac{\text{Volc}}{\text{Tr}} : \text{Tole} = \frac{2 \text{Tm}}{\text{Tr}}$$

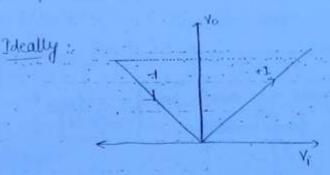
$$\frac{\text{Toleally}}{\text{Tr}} : \text{Tole} = \frac{2 \text{Tm}}{\text{Tr}}$$

$$\frac{\text{Toleally}}{\text{Tr}} : \text{Tole} = \frac{2 \text{Tm}}{\text{Tr}}$$

$$\frac{\text{Volc}}{\text{Tr}} : \frac{2 \text{Tm}}{\text{Tr}} : \text{Volc} = \frac{2 \text{Tm}}{\text{Tr}}$$

- Individual diode, \$= 11

Fransfer Curve



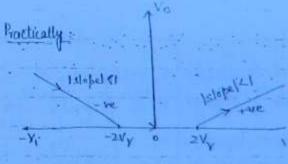
Practically.

$$\rightarrow J_L = \frac{V_{vn} \sin \omega t - 2V_{y}}{R_S + 2R_f + R_L}$$

$$\rightarrow \boxed{\eta = \frac{0.812 \times \frac{1}{R_c + 2R_f} \times 100\%}{R_L}} \times 100\%$$

$$\rightarrow \left[ \phi = 2\pi - 40 \right]; \quad \theta = \sin^{-1} \frac{2V_{T}}{V_{m}}$$

→ Individual disde, = TT-20.

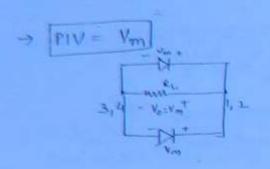


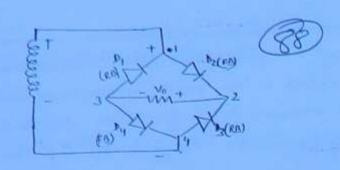
Slope: 
$$R_L = \frac{R_L}{R_{S}+2R_L} (\leq 1)$$

Theyenin's Equivalent:

$$V_{1h} = \frac{2V_{m}}{\pi} \begin{bmatrix} 1 & 0 & 0 \\ 0 & 0 & 0 \\ 0 & 0 & 0 \end{bmatrix} R_{L} \quad V_{0}$$

Pm = Rc+ 2Rf





> TOF = 0.812

## Advantages of Bridge Rectifier

- TUF is highest.

- Transformer can be replaced by ac source it step uplatown of voltage is not required.

- PIV is smaller as composed to contestate.

- Voltage required to deliver some bower is smaller cort half ware rectifier, tence to do so, no of turns is more in HWR, hence the size of transformer used in Bridge rectifier is smallest.

Prisodiontage -

-It cannot be used for sectification of small signals as cutoff beg. for response

Vm	21/4	loss
2	_ 1 · _	701.
JoV.	1	lot.
20V -	-1	51.

By Sir : - Advantages:

(i) The current in both primary of secondary of xirch is present for entire cycle and honce for a given power ofp, power xirch a small . Size and less cost may be used.

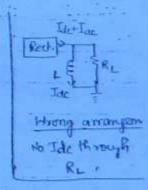
- -> No centre-tap is required in "K" secondary, hence whenever fossible, ac voltage can directly be applied to bridge.
- >. The current in secondary of xmer is in opposite direction in two half cycles and hence met de component through x mer coil in zero. . Which reduces the losses and reduces the danger of saturation =
- -) As two diodes conduct in series, in each half cycles, inverse voltage appearing across the disde get shared more the circuit can be used for high voltage applications. (since PIV is ever)

### Filter Circuits :-

- To minimise ripofle (accomponent) at the off, filter circuits are used. We one using inductor & capacitor in files circuite

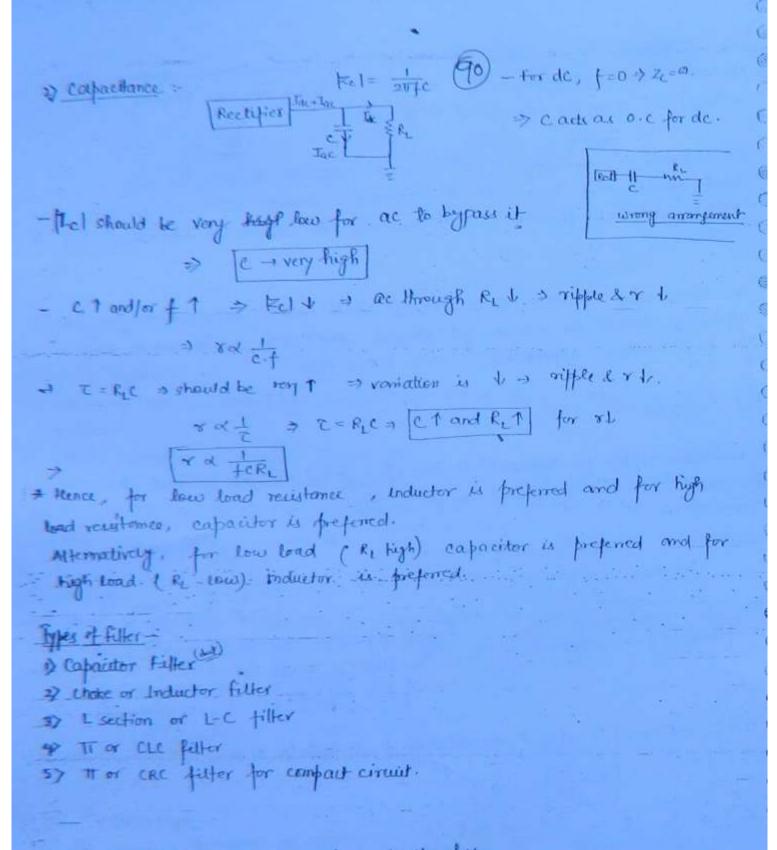
D Inductor - 1 | | | = WL = 211fL

Et very high

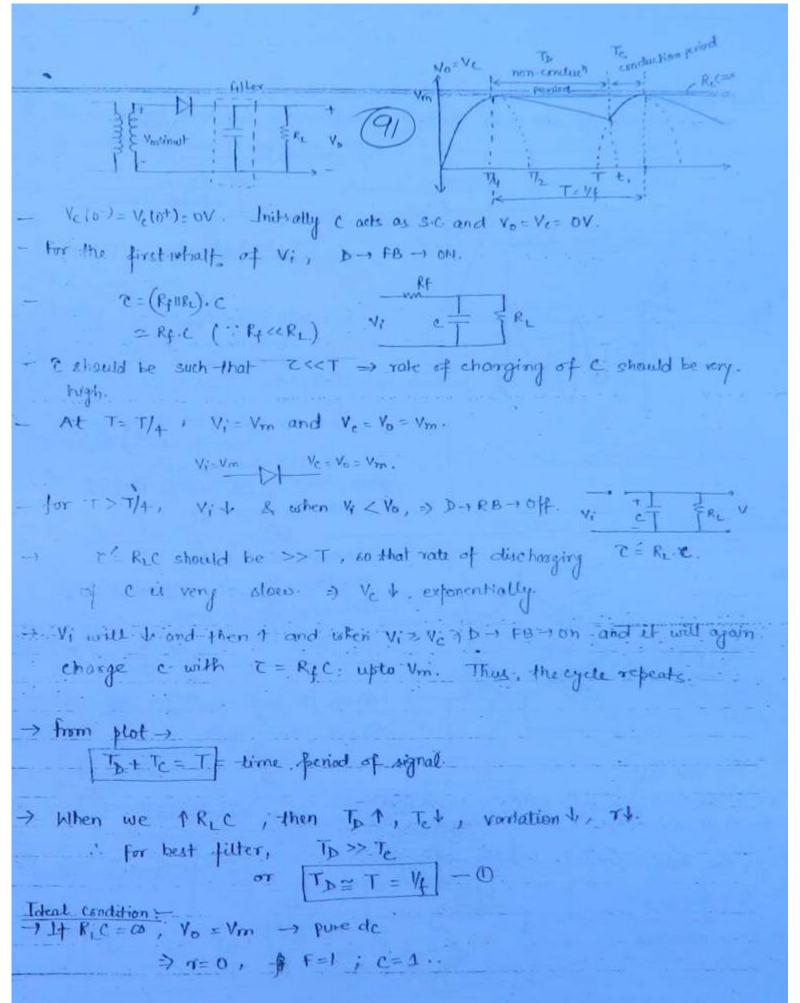


→ LT, and lor ft = |zylT > acatofp + > Ripple + => rb

 $\rightarrow \tau \uparrow \Rightarrow \frac{L}{R_L} \uparrow \Rightarrow L \uparrow \text{ and } R_L \downarrow$ > variation in current V.

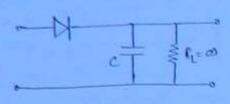


> Capacitor filter :- HWR with capacitor filter

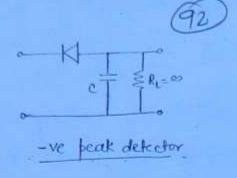


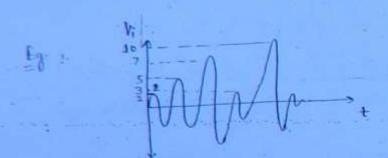
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### Peak Detector :-



the Peak defector





Vo = will change up to

(i) 2V and hald

Hid-18V and hald

(ii) 5V ...

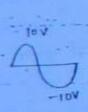
(iii) 7V ...

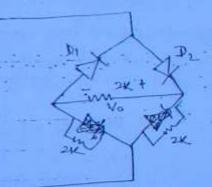
(iv) 3V ... do not change -> 7V

(dirde will be RB).

teence, the ofp will always hold the max value of ilp.

## Ques :-





Assume ideal dister

1 - Draw the ofp woveform.

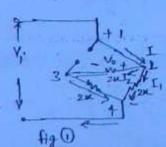
1 - find of de level

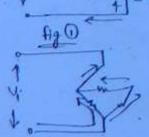
3 - find Piv.

(1) of p de level = 
$$\frac{2 \times Vm}{\pi} = \frac{10}{\pi}$$

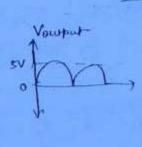
Soln for the half-
$$V_2 y = V_{23y} = 10V$$

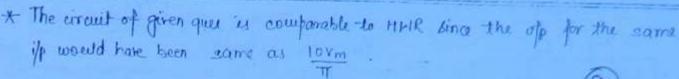
$$V_0 = \frac{10}{2} = SV$$
During we half
$$Qrain V_0 = 10 \text{ as}$$





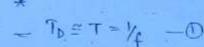








Approximate solution



- During 
$$T_D$$
, c will discharge  $V_0 = V_c = V_m e^{-t/R_c l c}$ 

$$V_{C} \cong V_{m} \left[1 - \frac{t}{R_{L}C}\right] = \left\{ -R_{L}C \text{ resy high} \right\}$$

$$- V_{d\hat{c}} = \frac{V_{m+} V_{min}}{2}, \qquad - \bigcirc$$

- : 
$$V_{dc} = V_{m} - \frac{V_{r}}{2}$$
 - 3

- Vr = Yrn-Vmin = change in Va during time To.

$$\frac{1}{2} dc = \frac{1}{2} \left( \frac{V_{mn} + V_{mn}}{RL} \right) = \frac{V_{dc}}{R_1}$$

$$\frac{1}{c} \quad \frac{V_{T}}{c} = \frac{I_{dc} T}{c} \Rightarrow V_{T} = \frac{I_{dc}}{c \cdot t} \quad \text{or} \quad \frac{V_{T}}{c} = \frac{V_{dc}}{R_{c} \cdot c \cdot t}$$

$$\frac{V_{dc} = V_{m} - \frac{I_{dc}}{2fc}}{2fc}$$

$$V_{rr} = \frac{I_{dc}}{c \cdot f}$$

Comparing with last egn-

Riffle factor :-

$$V_{across} = \frac{V_{P}}{J_{5}} = \frac{V_{T}}{2J_{3}}$$

$$= \frac{J_{dc}}{2J_{5}f_{c}} = \frac{V_{dc}}{2J_{5}f_{c}R_{L}}$$

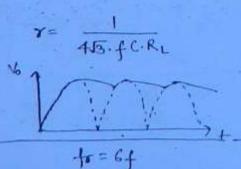
$$\begin{cases} 1 & \text{if } = V_{P-P} \text{ and } \frac{V_{P-P}}{2} = V_P \end{cases} \Rightarrow \forall r = \frac{V_{acmy}}{V_{dc}} \Rightarrow \forall r = \frac{1}{2\sqrt{3} \cdot f.c.R_L}$$

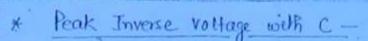
$$\Rightarrow r = \frac{V_{acms}}{V_{dc}} \Rightarrow r = \frac{1}{2\sqrt{3} \cdot f.c.R_L}$$

	HWR with C.
1 fr 1	A
- Ripple	Jackfe
Voltage, V	V. V. – Tac
- Vac	Vac = Vm - Ide 2fc
_Thereaddy	+ dy= - 1/2
equivalent	1 - Vm = Vm , Rm = 1/2 fc
- "	8 = 1 = 1 = 1 = 1 = 1 = 1 = 1 = 1 = 1 =
- Waveform.	Vo 1
2	

fr = 31

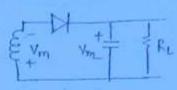
FWR with C ( Bridge / contor tapped) Ide/2fC Vdc = Vm - Ide VIH = Vm , RIH = 1+fc





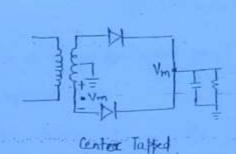
93)

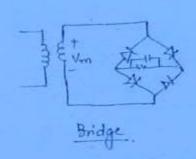
HUR C- max charged

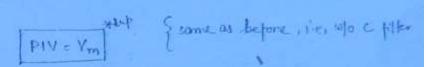


$$V_{D} = V_{CM} - (-V_{TD})$$
$$= 2V_{TM}.$$









# Surge Current or Peak Diede Current :-

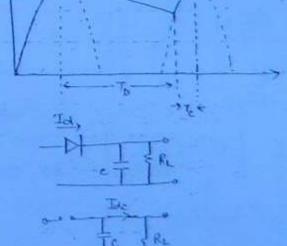
During To - 1 C duchange

Aldischarge) = Ide . To.

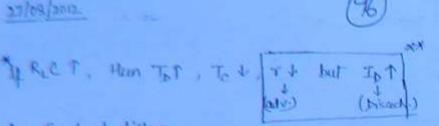
During To - Diode - ON - Guill charge

( ) (charge) = Id. Tc.

According to law of conservation of Q\_ ID. To = Ide To







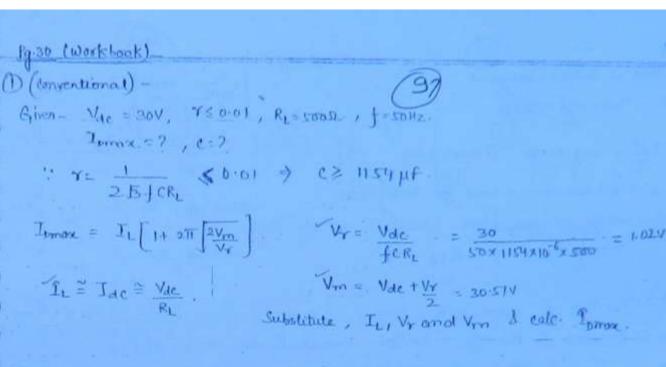


by for best filter,

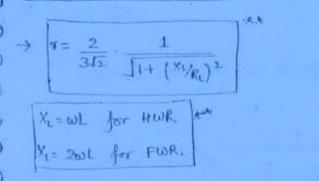
) Conduction Angle = 
$$\phi = \omega T_c = \sqrt{\frac{2V_T}{V_{th}}}$$

$$\phi = \omega T_e = \sqrt{\frac{2V_I}{V_m}}$$

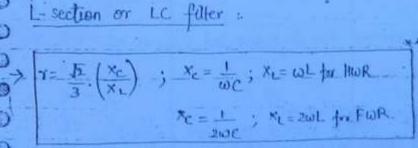
$$\rightarrow I_{DMM} = I_L \left[ 1+ 2\pi \sqrt{\frac{V_m}{2Y_V}} \right]$$

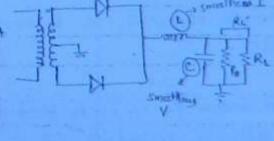


Inductor Filter (or) Choke filter-



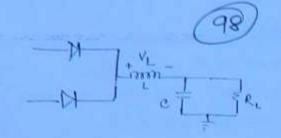






$$R_{B} = Elector Resistance of Relation o$$

\* Won those is sudden change in surrect - then  $\frac{dI}{dt}$  - large.



:. Vi = Ldf - very large. -> Back emf.

This the will act as reverse bias for both diodes,

This sudden change occurs when circuit is ON who RL.

$$R_{L} = \frac{L}{R_{L}} = 0 \quad \left( \begin{array}{c} R_{L} e \phi = 0 \\ 0 \\ \end{array} \right)$$

T=0, then off large = VL = large.

Hence, Rosis attached in the ofp. so that even if  $R_L = \omega$ . (0.c) effective resistance.  $R_L' = R_B \times M$  and hence  $Z = \frac{L}{R_L'}$  is never equal to 0. Therefore, no sudden change of current.

> When Re is attached across a capaintor, it helps C to discharge through it when supply and Re are removed.

The basic reg. of this fater is the current through choke must be continuous. An interrupted current through choke may develope large back emf which may be in excess of 170 ratings of diode.

and for more voting of capacities.

<sup>·</sup> To diminate back ent, a bleder resulance RB is connected across of p

<sup>+</sup> Anther reason for Ro is to bleed off voltage stored in filer capacitor when suffly is turned off.

Potential birder > pifferent of s from diff. points from Re.



manching contents

maintains yettings

$$T = \frac{\sqrt{2} \cdot X_{C_1} X_{C_2}}{R_{L_1} X_{L_2}} = \frac{12 \cdot (X_{C_1})^2}{R_{L_1} X_{L_2}} \left\{ c_1^{\frac{1}{2}} c_2 \right\} = \left\{ \frac{1}{2} \cdot \frac{1}{2} \cdot$$

$$\Rightarrow X_C = \frac{1}{2\omega C}$$
;  $X_L = 2\omega L$  for FWR.

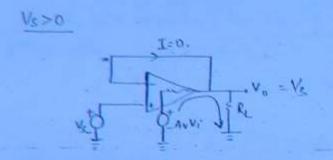
$$r = \frac{\sqrt{2} \cdot x_{c_1} \cdot x_{c_2}}{R_{L} \cdot R} = \frac{\sqrt{2} \left(x_{c}\right)^2}{R_{L} \cdot R} \quad (\text{for } c_1 = c_2). \quad \begin{cases} \frac{1}{2} & \text{otherwise} \\ \frac{1}{2} & \text{otherwise} \end{cases}$$

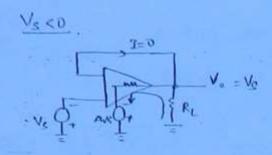
$$\Rightarrow$$
  $7 < \frac{1}{\omega^2 G_0 R_0 R_0} \Rightarrow$   $\sqrt{8} < \frac{1}{f^2}$   $\sqrt{2} = \text{small (relatively more from CLC} + \frac{1}{f^2}$ 

* c	L	LC .	CLC
→ · TX.1/4	rd Nt	Ta' 1	rd 1/43
-> rd//T	rd 1/7	- rd / 7 5-	7× 1. 7. 3.
-A To RLC	T = L/RL		4 5 5 = (Rici) (Rica) x E
> Yd 1 RLC	1d 4/R2.	· raye	= C1C2 LRL  Tol 1  C1C2 LRL

# Precision Rectifiers :-

- Voltage fellower-





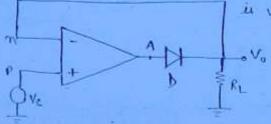
tence, to maintain Vo at a level of input vs, of amp should provide a current ou indicated above. If this current =0, then Vo=0.

### Precision HWR :-

> Assuming Ideal of-amp a practical diade.

. Ns	Và	D.	_ V <sub>0</sub>
Vs>0. (verysmall) = \(\mu \text{V}\)	1 towards +Vsat Reaches tall	. ON.	V <sub>s</sub>
Vs <0	VA = 0.7V  Val (-Year).  Reaches to final value	off	Csince taire is no
	=-Vsat-		to D u RB)

(This circuit is also called superdiode since cut in voltage is very small, ~ uv.



- Till the time Rie about to on!, the op amp will act as opin loop. When I is on, the die to -ve semce, gam very teadback, applying virtual ground, high.

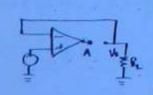
Vp=Vn = Ve = Vo . (see not page Vovs V; peut) 1. VA = 0.7 V + Vo Explus.

=) VA = 0.7V + Vg.

> VA = 07 V.

seence, the diode D will avoid of amp to go into positive.

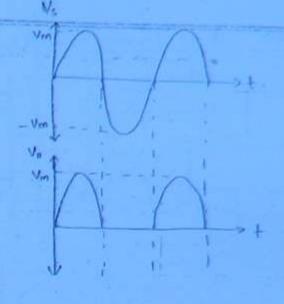
When Voco \_



Op-amp will behave as open look and Av = 106 VA = - Vsat.

-> PIV for the diode D is - Veat.

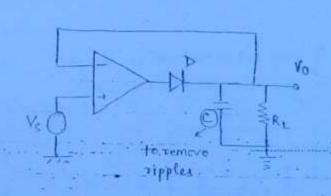
Vi=Ys cutin voltage is

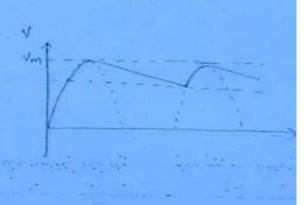


very small, ≈0.7μV

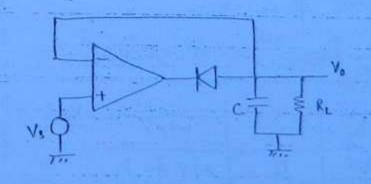
Alhen V; = 0.7 mV, VA = Av. Vi = 106x0.7 mV = 0.7 V }

Drawback : PIV is very high.



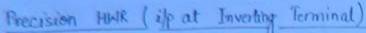


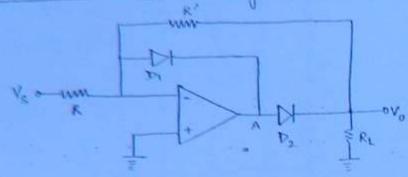
RIC = 00, then above circuit will act as the peak defector



This circuit will avoid -ve saturation for 15 00.

- If Rec = 00, then it will alt as - re peak detector.

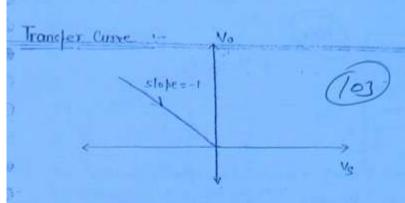


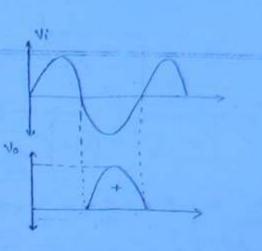


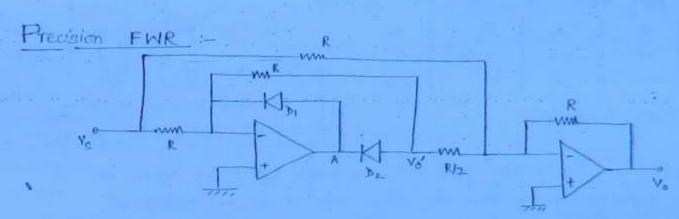
$$\rightarrow V_0 = \frac{R'}{R} \cdot V_S = -V_S + \frac{2}{1} i + \frac{R'}{R} \cdot R^{\frac{2}{3}}$$

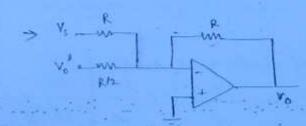
De will avoid positive saturation when if is -ve

Vs	V <sub>A</sub>	D,	D <sub>2</sub>	Vc	PIV
→ - Vs >0	+ towards -Yest (-0.74)	011	OFF.	0	0.7 V for P2
© Wiki Enginee	1 towards	OFF	ON	Vs	b7 V for b, www.raghul.org









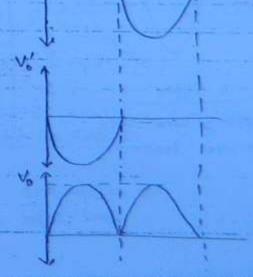
$$V_0 = \frac{-\hat{K}}{R h_{2}}, \ V_0' = \frac{R_{1}}{R} V_0$$

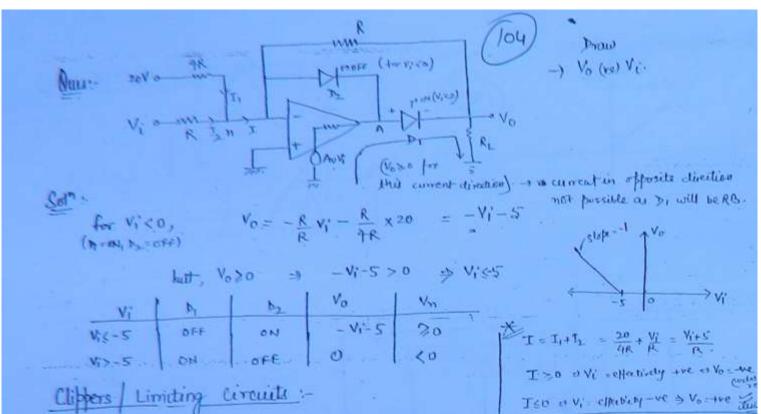
... 
$$V_0 = -2V_0' - V_3 - \Theta$$

			el sue K	
Vs.	٧A	D <sub>1</sub>	D2 "	Vo
Vero	4-Veat	off	0.11	· - Ve
	V-Veat-			

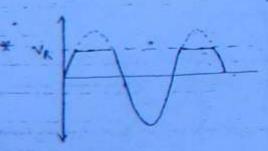


$$V_S > 0 = S(let) : V_0' = -SV$$





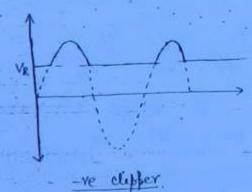
- These are used to select that fort of waveform which lies above or below some reference level. These are also referred to as voltage or owners limiters, amplitude selectors or slicers.



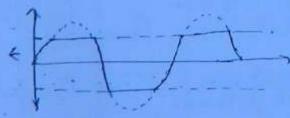
-) clipping above some reference level.

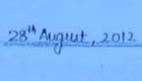
tre Cliffer

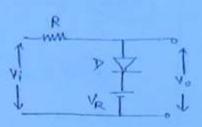
Two independent & level cliffer



-) clipping below some reference level.

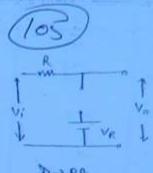




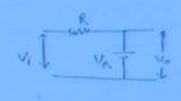


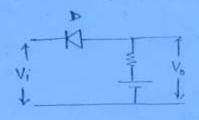
Shunt	chik	ker	LP-	esed	- 5
- coord	cus	PET	CID	Sen	ve)

V;	D	, Y <sub>D</sub>
Yi SVR	OFF	· Vi
Vi >VR	- 6N	VR

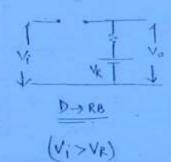


DARB	Į.
( VR > V	



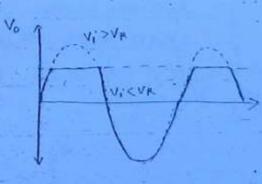


Series Chipper (premive)



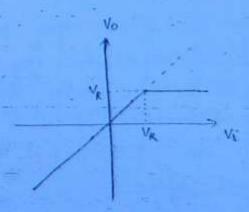
$$\begin{array}{c|c}
\uparrow & \downarrow \\
\downarrow & \downarrow \\
\hline
 & \downarrow \\
 & \downarrow \\
\hline
 & \downarrow \\
 & \downarrow \\
\hline
 & \downarrow \\$$

$$V_i \otimes V_R$$
 ON  $V_i \otimes V_R$  OFF  $V_R$ 

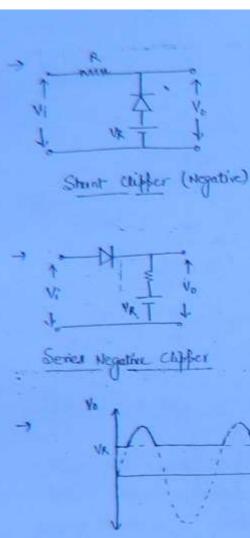


-0/P

\*



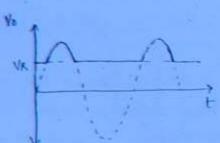
Transfer Characteristic



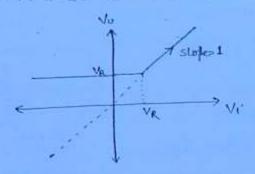
Vi.	D	Vo
Vi >VR	OFF	٧ċ
$V_i \leq V_R$	ON	VR.



ON OFF Vi & VR



Gp curre



Transfer Characteristic

I > 0 -then b -> ON

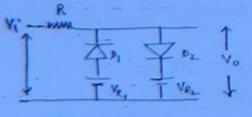
ISO then Do off

= Vi > VR than b + ON

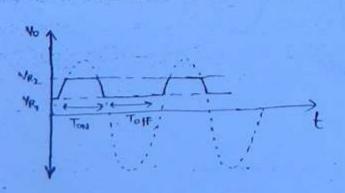
JVISVR the Douff

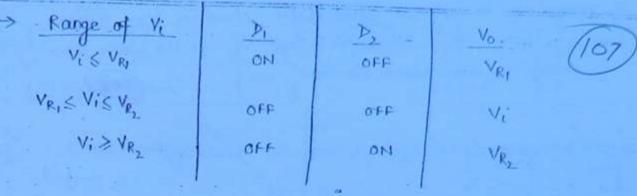
- It is exist way to determine whether diode is on or off. Calculate the current in forward direction of diode and apply the condition.

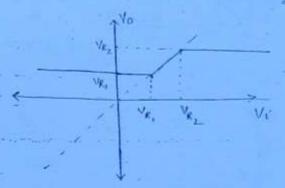
-> Two Independent level clipper in



© Wiki Engineering





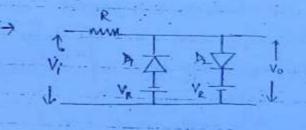


> To conclude that  $V_R$ ,  $2 V_{R2}$  are tye, check polarity at vo inference.

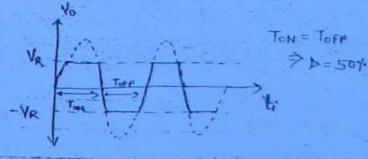
\*/P is  $V_R$ , if some polarity the  $V_R = +ve$ , else -ve.

R.				
†	v <u>E</u>	€ V <sub>e</sub>	3	VR. = +VE ·

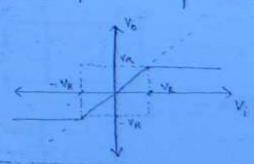
- → from ofp curve, Top > Ton > D < 50%. Subjut is an asymmetrical square wave
- > This circuit is used as a means of converting a sinusoidal waveform into
- To generate a symmetrical square wave,  $V_{R_1}$  and  $V_{R_2}$  are adjusted to be numerically equal but are of official sign.



Vi	_ D <sub>1</sub> .	D.	V <sub>2</sub>
Vi ≸-VR	ON	OFF	-V <sub>R</sub>
$-Y_R \leq V_1 \leq V_R$	OFE	off.	-v2 = _
Vi>VR	off	on	VR.

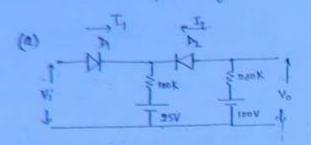


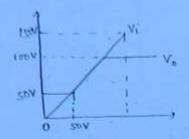
Symorthical Sq. wave Symmetrical Clipping



Transfer characteristic

linearly from o to 1500 Stetch the opp voltage Vo. to the same time scale as the ifp various. Assume ideal divides.





Range of 
$$V_i$$
 $0 \le V_i \le 50$ 
 $0 \le V_i \le 50$ 
 $0 \le V_i \le 100$ 
 $0 \le 0$ 
 $0 \le 0$ 

$$-3 \hat{I}_1 = \frac{V_1 - 2S}{100K} + \frac{V_1 - 100}{200K}$$

For 
$$N = 0N$$
,  $T_1 \geqslant 0 \Rightarrow \frac{V_{1}-2S}{140 k} + \frac{V_{1}-140}{280 k} \geqslant 0$ 

→ When o 
$$< V_0 < V_0 > 0$$

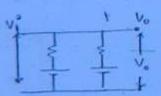
1804  $< V_0 = 100 + V_0 = 2.5$ 

250  $< V_0 = 100 \times 0$ 

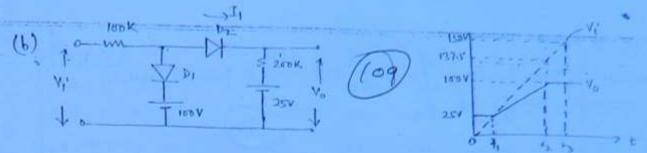
1804  $< V_0 = 100 \times 0$ 

250  $< V_0 = 100 \times 0$ 

250  $< V_0 = 100 \times 0$ 



$$V_o \in V_l'$$



Soll : Since voltage across DI is very high (100V), then De will on before Di.

:. 
$$T_1 = \frac{V_1 - 25}{300K}$$
, for  $D_2 = 0N$   
(Acsuming  $D_2 \circ FF$ )  $300K$   $T_1 > 0$   
 $\Rightarrow V_1 > 25$  — (Breakpoint.)

V <sub>i</sub> '	D,	D <sub>2</sub>	Vo
0 < Vi < 25	OFF	OFF	25V
255 N; 51375	OFF-	0"N	24;+25 3
· V; ≥137.5	019	ои	10 O V

for 4:725, Vo will be-

$$\frac{V_{0} - 25}{20D} + \frac{V_{0} - V_{1}}{10D} = 0$$

$$= 2V_{1} + 25$$

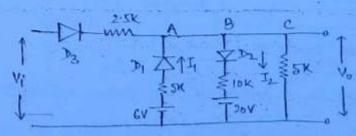
$$= \frac{1}{3} \cdot \frac{V_{0} - V_{0}}{100} = 0$$

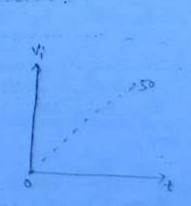
$$= \frac{1}{100} \cdot \frac{100}{100} = 0$$

Now for  $D_2 = 0N - V_0 \ge 100V$ 

Trange of Vi from 0 to sov. Indicate all slopes and voltage levels.

Indicate for each region, which disdes are emdueting.





Soll :- When Vi=0,

voltage across D = to is large (= 204) and A = formand biased. Due to Dr, surrent voltage at A,

Now, this Va is making diode Da RB.

Now, when Vi > 34 than D1 = 0N. La Barrak print

for 0< Vi < 3 , Vo = VA = 3V

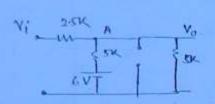
for Vizz3,

$$p_1 = on$$
,  $D_2 = off$ ,  $D_3 = on$ .

$$\frac{V_{A} = V_{i}}{2.5K} + \frac{V_{A} - 6}{5} + \frac{V_{A}}{5} = 0$$

$$\frac{4V_A}{5} = \frac{2V_i}{5} + \frac{6}{5}$$

$$V_A = \frac{V_1 + 3}{2}$$



Now divide  $D_1$  will remain in FB till  $I_1 = \frac{V_A - 6}{5}$  7, 0 for  $D_1 = 0$   $V_A > 6$ 

$$I_1 = \frac{V_A - 6}{S} 7/0 \quad \text{for } D_1 = 0 \text{N}$$

for Vi >9V.

$$b_1 = 0FF$$
 ,  $b_2 = 0FF$  ,  $b_3 = 0N$ .

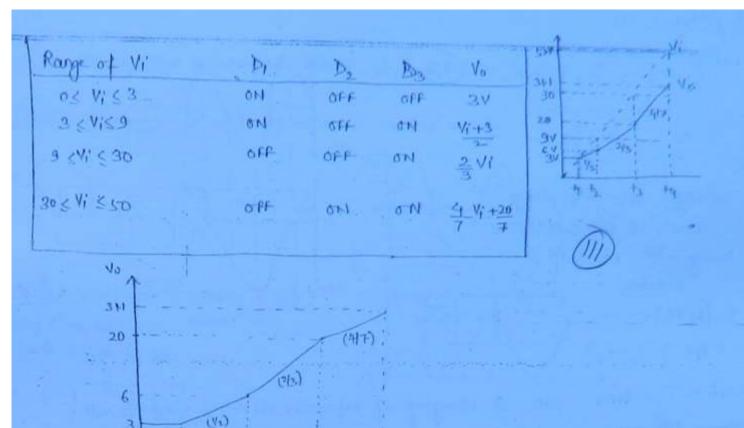
$$V_0 = -\frac{5}{7.5} V_1' = \frac{2}{3} V_1'$$

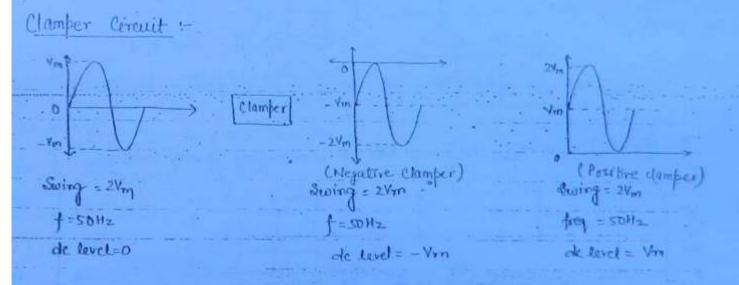
on afflying KCL,  $V_0 = \frac{4V_1 + 20}{7}$ 

$$V_0 = \frac{4V_1 + 20}{7}$$

$$V_{i} \geqslant 9V$$
,  
 $D_{i} = 0$  of  $D_{2} = 0$  of  $D_{3} = 0$   $D_{3} = 0$  of  $D_{4} = 0$  of  $D_{5} =$ 

Now for D2 to be ON, (2 V; 7, 20V) 3 Vi 7, 30V. - Break point.



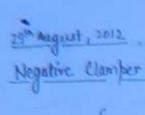


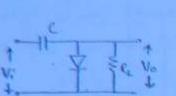
SDV

? Champer circuits are also called as do translator, do restorer, do inserfer.

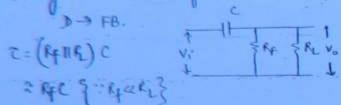
30

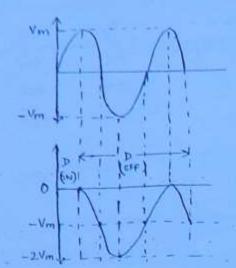
- The circuit which are used to add a delevel as for the requirements to ac off signal are called clamper circuit.
- -> These are of two types Hegative Clamper -> adds -re-level to acolpsis





Initially, v. (0-) = v. (0+) = 0. hence, a will act as sic During Ist we fall

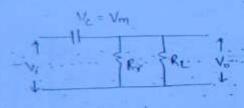




k Rece T - Hence, rate of charging of capacitor is very high It will charge till maximum value Vm.

-> At t=T/4, Vi=Vm & Ve=Vm.

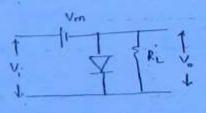
" D-ON, Rf = 0 and hence, Vo =0. " Vo = VD=0.



Vb = Vi- Ym and Vi+ and when Vi < Vm D- RB.

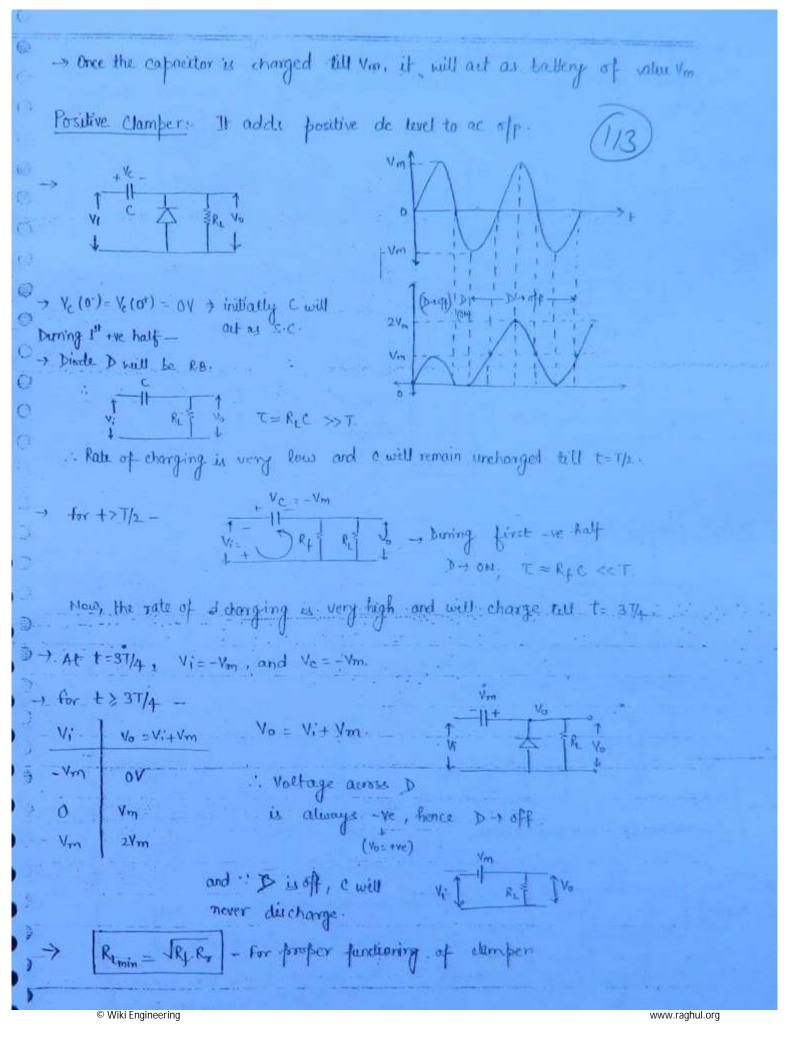
T = (RollR1) € & RLC >> T => Rate of discharging is very small x0.

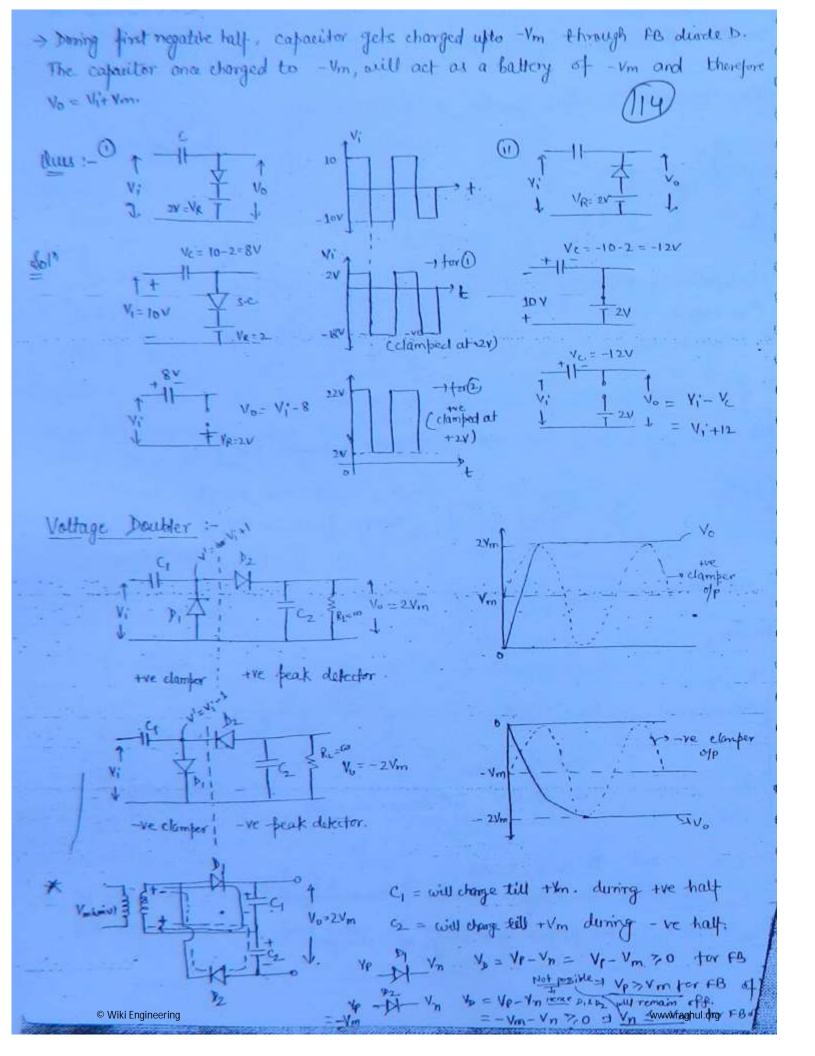
$$\begin{array}{c|cccc}
 & V_1 & V_0 = V_1 - V_{m} \\
\hline
 & V_m & O \\
 & & - V_{m} \\
 & & - 2V_{m}
\end{array}$$



- Diode will romain off. after this instant:

\* He cannot use a dc battery instead of capacitor as the value of battery will vary with the feak value of signal.



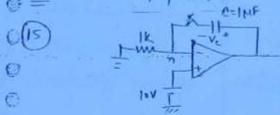


#### Morkbook

O Vi	D,	) Dr.	V <sub>O</sub>
V <sub>1</sub> ' < 0	211	OFF	0
0 < V1' < 20	ON	OFF	Vi/2
Vi >28	ON	ON	lov

(3)	d
(0)	Ь



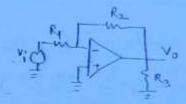


$$\begin{cases} V_0 = 16.3 V \\ V_0 = 20 V \end{cases} \times Cann$$

3

3

$$\frac{0 - V_1}{R_1} + \frac{0 - V_0}{R_2} = 0 \Rightarrow V_0 = -\frac{R_2}{R_1}$$



# C Conventional

(1) When switch is ON, gain -1; s-off, gain = -2.

R1=3KR1. R2=2KR

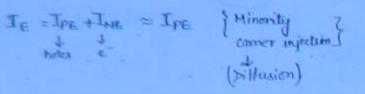
R = dc resistance seen by inverting forminal; R = R/11R2116K = 1K

30" August, 2012.

Bibolar Junction Transister :-

p-n-p transition in active made :-

116



$$I_E = I_C + I_B$$
;  $I_C = \alpha I_C$ .  
 $I_{E} = I_C + I_B$ ;  $I_{C} = \alpha I_C + \alpha I_C$  this direction)

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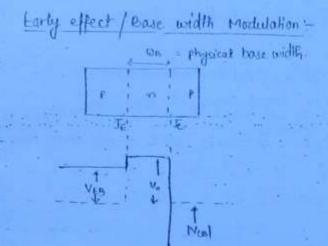
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Note:- Guys Be Cool Dude I am here for help You ©

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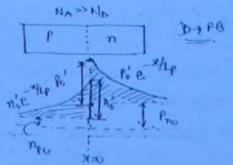
#P	Common Emiller	(Emiller follower) Common Collector	Common Base
1) Input Terminal	В	В	E
2) Output Terminal	С	E (117)	C
3) Common Terminal	E	c	В
4) Current Gain, AI	high (moderate)	very high.	very sow (s1)
5) Voltage Gain, Av	high (moderate)	very low (31)	voy high
6) Input Resistance, Ri	high (moderate)	very high	Very Caso
7) Output Resistance, Ro	high (moderate)	very law	very high
8) Power Gain (Ap = Av · AI)	Highest	Moderate.	Moderatz.
9) Phase Shift	180°		i o
(° ) Normally used as	Amplifier in multidoge	Buffer (voltage).	High freq. applicatio
0			Buffer (turnet)

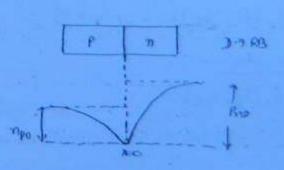


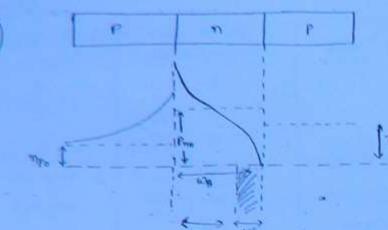
Wes we will the re-

We g = effective base width =  $\omega_{\infty} - \omega'$   $\omega' = depletion width.$ 

As IVal 1; Je becomes more RB and well to therefore recombination and hence Intrand & 1.







 $T_{E} = q D_{F} \cdot \frac{dF}{dx}$   $= \int_{E} A \frac{dF}{dx} \cdot e^{-\frac{dF}{2}} \frac{dF}{dx}$ 

Inro Now, due to early effect, why to and sewil 1. When weff =0,

then the condition is called reach through or funch through. I will be very lorge.

- The variation of effective base width with I vest it called Base width modulation or early effect. This results in following.

There is less chance of recombination in Base region as effective base width reduces. Therefore, of 1 causing an Tin collector current Ic.

1) conc gradical of injected holes (minority comess in base region) also to due to reduced base width. Since, diffusion cument is directly proportional to conc gradient, IE also 1.

earing thereby large is. This result in breakdown of transistor

and is called funch through on reach through.

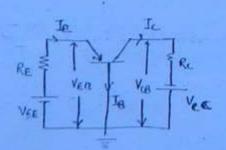
Input and Output Charackristics:

Common Case configuration:

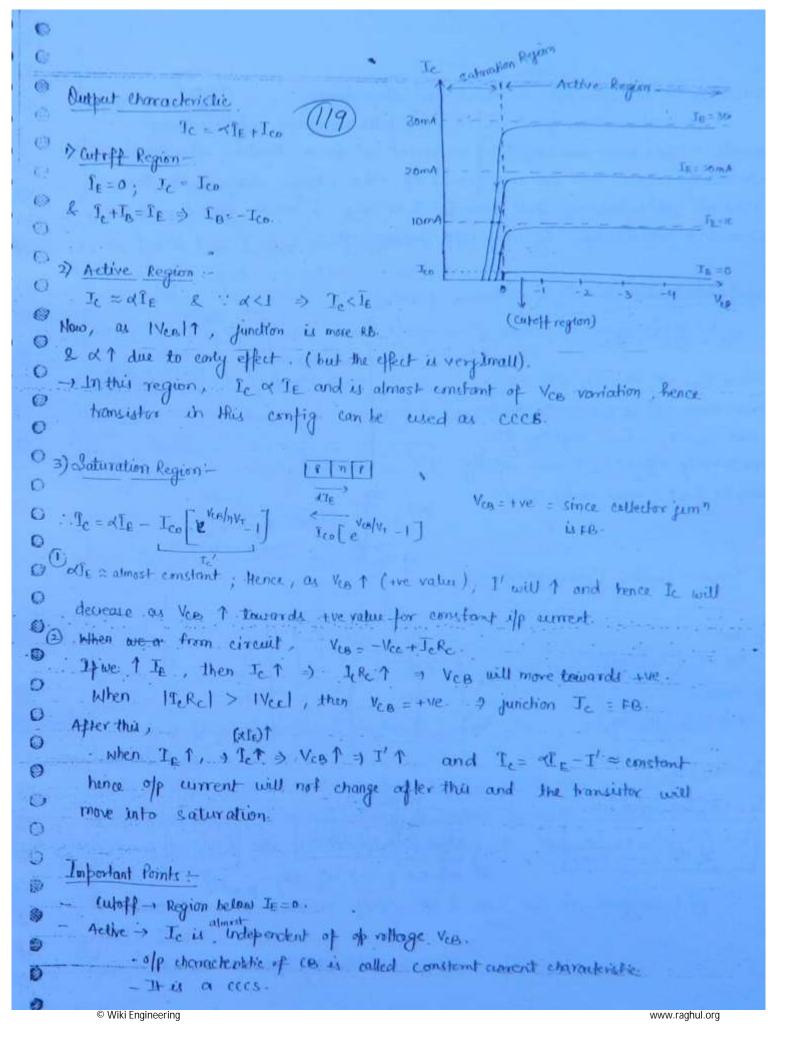
ile characteristic -

VEB = f, (IE, VOB)

of thomatoristic -



Yes = - ve Yes = +ve.



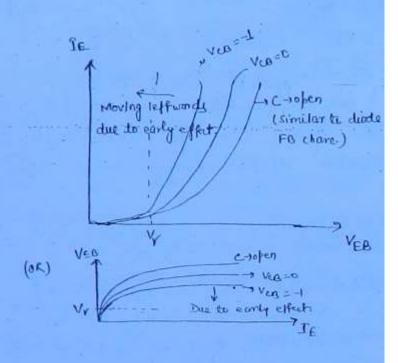
-Saturation -> The region left to Veg=0 and above IE=0.

- As the collector fun" is to , the holes flow from p-type collector towards might base and constitute a current I' in a direction offosite to direction of the. Even for small value of thes, large charge in he take place and characteristics fall towards of as very is made more & more tre Since I' A exponentially, Ic may even become -ve-

Imput Characteristic :-

VEB = + (IE, VCB).

When Ves = 00, in, CB > 0.C. then there will be similar to diode When Vos=0; Tc = slightly RB. Due to early effect, IET more rapidly. Now, 45 Veb 1, more early effect



COMMON EMITTER CONFIGURATION -

1/p charc -YEE = f, (Is; VCE) olp charc -

VIc = f2 (Te, Vce)

Ic = ale +Ico Ic = < (Ic+IB) + Ico

Ic= Ble + (p+1) Ico

Dutput Charackeristic

(121)

Sal- 1 Setive In 1904

cutell

Active Region

Ć.

0

- Ic = BTB+(B+1) Ico = BTB

- Vce = Vc-VE = Vc.

As VCE 7 => Vc 1 - Jc more RB > width & & < 1

Now, & - 280.0 - 280.0 - 0.54.1

P - 49 - 63 - 34-1.7 - can't be neglected.

0 - current gain is high, to, small change in IB results in large change in Ic

Cutoff legion.

hines

0 - When IB=0, Ic = (B+1) Ico -> Fc + Ico and translator is not in cut off

 $T_{CEO} = (\beta+1)T_{CO} = \frac{T_{CO}}{\sqrt{k-ck}}$ 

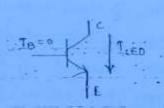
TCEO >> TCO , : \$ >>1.

O-Now, for Ic=Ico; IE should be o

- When IE=0

In To Icoo

Ico > Ico > Ico



- The Ic in a physical (real) non-idealised) device when Is = a is designated

g symbol Icao.

- Cutoff is defined as a condition where Ic = Ico and Ie=0. In order to testoff translator, it is not enough to reduce IB to 0. instead it is necessary to RB the emitter functionally, ie, VBE = - ve.

VBE = - 0.1 for Se; 0.0 for Si.

The actual Ic with collector jurch RB & base on is designated by symbol Iceo.

9 - Tean = reverse collector saturation current.

Two factors cooperate to make I can larger than I co-

a) There exist a lookage current which flows not through june", but around it and through surfaces and it is or to vottage across the pane".

3) Now carrier may be generated by collision in Ic transition region leading to avalanche multiplication of cument.

Icao = MA for Ge

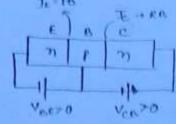
I can approximately doubles for every 10° vise in semp for both be disi and Si can be used upto about 200°C and se up to about 100°C.

31 August, 2012 :

- Saturation :-

TEARS, JUAN.

It = ple ; New = Vec -Teke (from ext.).



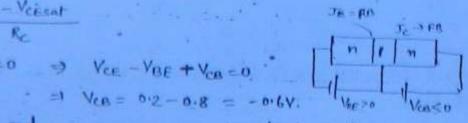
Hen HE TYPE, then To I (due to barrier seworing), then Jet and Ver to

Liber VAE - 0.8 V & Yes = 0.2 x and is constant for further this Vae.

\*\* \* VCE sat = 0.24 . .

Ictat = Vcc - Vcesat

New, Ver + Ver + Vec =0 > Ver - Ver + Ver =0



Now, Je = Fo and a reverse current will start flowing which will offerse IE and the dust transister will go into saturation T= In [e Walsh ] }

If You stept constant and Yes is changed without yout, a Vert

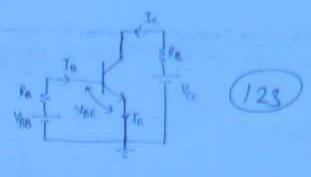
> VCE = VEE - VCE > VCO b and when it is -ve then Jc -> RB. leave, to drive will be in saturation. © Wiki Engineering www.raghul.org

Checking Transistor for saturation s

\* let O in in saturation.

Then Ver - Wester & You - You sat

1. I cant = Vcc - Versat



Now, if In > I point, then transister is in caturation.

To bring transister in saturation -

D Increase Is by TVBB to that In- Ismin

2) If In - constant, then to Inmin to that Innin - In by the and/or the.

s) If In - constant & I exat = constant, then Ip so that Tamin = In-

At 
$$\beta = \beta_{freed}$$
,  $T_{Brain} = \frac{T_{cent}}{\beta_{freed}} = T_{B} \Rightarrow \begin{bmatrix} \beta_{freed} & T_{cent} \\ T_{freed} & T_{freed} \end{bmatrix}$ 

Important Points for saturation-

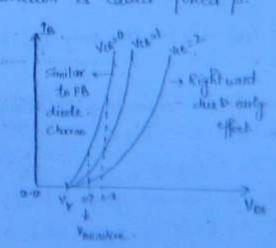
- BOFR It & To are FB by cutin voltage Vr ...

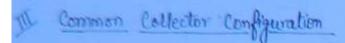
design the ext, so that Is I I min by a fador of 2 to 10.

-> The ratio of Icut & To to ensure saturation is called fored p.

Emput Characteristic :-

Then VCE = 0, of the similar to divide when VCE + ) vc + 9 "VE = 0 f and alue to early effect (VEB more RB), Inv.





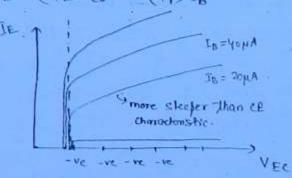
I/p char:  $V_{ec} = f \left( I_{e}, V_{ec} \right)$ 

of the 
$$I_{E} = \int (\bar{I}_{0}, V_{EC})$$

### Output chmackristic .

-When Vect (-ve), Veet & Ie is more RA. & due to early effect of and pt.

-time is more steeper than cf emfig, since (B+1) varian is > p varian.

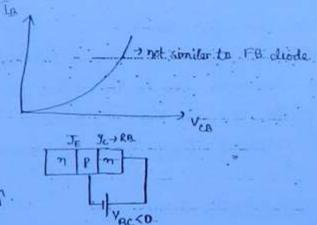


Vcc -> To RB collector funct

### Input Characteristic

forward briased diode charae since the it is taken across RB junction.

- Voc 1 = Voot = Je less RB, early effect & & In p.



Important froms. regarding (c emfig. -- Highest & (50 Kl - 500 Kl)

- lowest Ro (< 100 12)

- Highest Ai (current gain);  $|AI| = \frac{I_E}{I_B} = (1+\beta)$  } lowest for CB = 0 } - lowest Av (<1); Explical value = 0.78. Max. Av = 1 (ideal cond), hence it

- Ha is also called emitter follower.

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Emiller follower is analogous to voltage follower in op-amp and source follower in FET.

Voltage follower & source follower are VCVs. (28)

Procest Power gain: Typical value = 48.

Proceshiff = 0°.

Application -

i) Highest i/p resistance device.

11) As a buffer amplifier, i.e., an impedance morthing device the high resistance & low resistance device.

111) As an audio forg power amplifien

## inforfant Points for CB configuration.

- lowest Ri (<1000L)
Highest Ro (>1MIL)
Lowest AI (=d).
Highest Av.

Mederate Ap typical value = 68.

Phase shift = 0.

CB amplifier will offer largest bondwidth & hence more suitable for high freq. applications.

#### Affication -.

- (i) As a constant current source
- ii) As are non-inverting rollage amplifier

iii) As a high frequency amplifier

iv) As an impedance matching device blu low resistance & high resistance.

Duc to\/

Re-3K find transister currents in ext.

B= 100, Ico = 200A, Si transistan.

Typical June?	voltages for nor	translator at 25°C
	31	Ge
Voesat	8.2	0-1
lessel = Ve	0-8	6-3
Ves active	6.7	0.2
SE culin = Vy	0.5	0-1
Vectobell	0.0	-0.1

\* for purp transister, sign of all the entires should be reveneed.

6

6

Sol7 - 1 Re= 200kg.

Vopadore VEGAN

" VAR = +re= EV =) VRE = +re =) JE = FB.

at dis in active region -

Ic= pla+ (1+p) Tco : -

0.0215 mA

1c = pIB = 2.15mA.

VCE = 10- 3K. 7c + VCE = 10-3×2-15 = 3-55V >> 0.2V teence, transcitor

701

is in active region.

Atmoliety, VCB = VCE - VBE = 3.55 - 0.7

= 2-85V > junction is definately RB.

(2) he= 50K.

= 5-0.7 \_ 0.86 mA

IC=86mA > VCE = 10-3K(8.6) = -15.8 < 0.2 => Tr > saturation.

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. VBE = VBESU = 0.8

VCE = VCESAT = 0.2

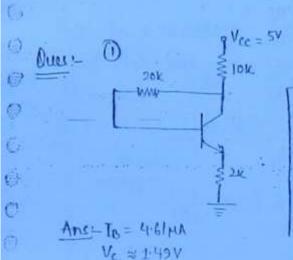
IB = 5-0.8 = 0.084 mA

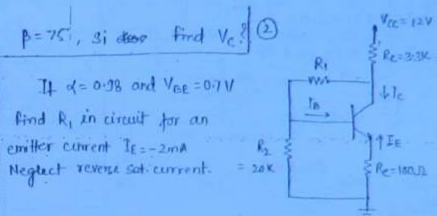
+ Overdrive factor = 
$$\frac{1}{I_{Bmin}}$$

By  $I_{Bmin} = \frac{3.27 \, mA}{I_{Bmin}} = \frac{0.0327 \, mA}{I_{Bmin}}$ 

(27)

overdrive factor = 0.084 = 2.5 times + tence, transister is well in saturation





8019

63



Dues In the given ett, determine the value of Ri, Ri and Ri so that collector current through the transistor is Im A. Vq=3V, Vc\_=6V. Take VBE = 0.7V. and let B of transistors are very high.

$$V_{1} = V_{8E} + J_{c} \ell_{E}$$

$$V_{1} = \delta \cdot 7 + \delta \cdot 2 \times 1 = \delta \cdot 9 V$$

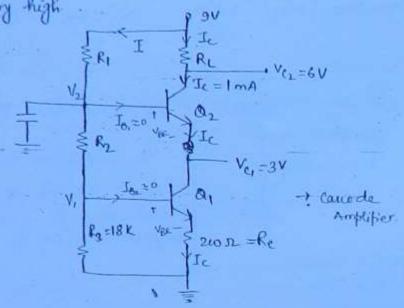
$$V_{2} = V_{8E} + V_{c} \ell_{E} = \delta \cdot 7 + 3 = 3 \cdot 7 V$$

$$2_{\bullet} = \frac{V_1}{R_3} = \frac{6.9}{18} = 6.05 \,\text{mA}$$

$$R_1 = \frac{9 - V_2}{T} = 106K$$

$$R_2 = \frac{V_2 - V_1}{I} = 56 \, \text{K}.$$

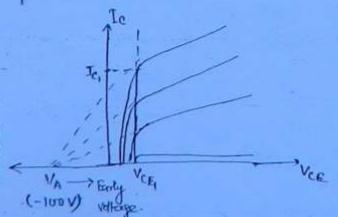
$$-R_{L} = \frac{9-6}{1m\Lambda} = 3K.$$



Early Voltage:

- It helper in finding of resistance of transistor.

$$\overrightarrow{Slope} = \frac{\underline{I_{C_1}} - o}{V_{CE_1} - (-V_A)} = \frac{\underline{I_{C_1}}}{V_{CE_1} + V_A} \stackrel{?}{=} \frac{\underline{I_{C_1}}}{V_A} = \frac{1}{\gamma_o}$$



→ VA = very high for CB. > To = very high. 2 M.M.

→ VA - for CC is slightly less than VA of CE. =) Tocc < Toce

→ VACON VACE > VACC or Toce>> Toce > Tocc

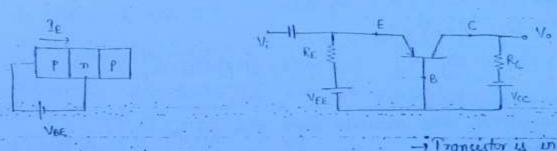
03 d September, 2012.

(129)

Out In a certramuster, at Vce=1V, Ver is adjusted to give a collector current of ImA. Keeping Ver constant, Vce is 1 to 11V. Find new value of Ic if VA = 100V.

$$\frac{8017}{-150-1} = \frac{9L-1}{11-1} = \frac{110}{101} = \frac{109 \text{ mA}}{101} = \frac$$

### Transistor as an Amplifier :-



$$V_{e} = \frac{\eta V_{T}}{I_{E}} = \frac{V_{T}}{I_{E}} = \begin{bmatrix} \text{dynamic resistance} \\ \text{or incremental} \\ \text{resistance} \end{bmatrix}$$

Jc + FB, JE -> RB

Ic = o(let Ico = o(le.

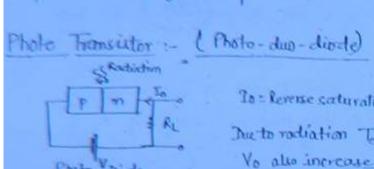
Ac analysis - On applying signal at  $V_i$ . If  $V_i$  1 by  $\Delta V_i$ , then  $\Gamma_E$  1 by  $\Delta \Gamma_E$  =  $\Gamma_C$  also increases ·  $\Gamma_C + \Delta \Gamma_C = \propto \left(\Gamma_E + \Delta \Gamma_E\right)$   $\Rightarrow \Delta \Gamma_C = \propto \Delta \Gamma_E$ 

Now, Vo will also 1, > DYo = DIc. Rc > DYo = X DIE. Rc.

Charge in  $\sqrt{p}$ ,  $\Delta V_i = \Delta T_E \cdot Y_E$ .

Yallage gain ,  $\Delta V_i = \Delta V_0$   $\Rightarrow \Delta V_i = \Delta V_0$ © Wiki Engineering  $\Rightarrow \Delta V_i = \Delta V_i = \Delta V_i$  www.raghul.org

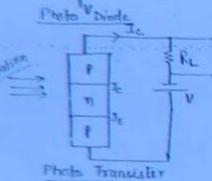
> Transistor provides power gain as well as voltage or current amplification Current in tow resistance if cht is tomeformed to high resistance of akt. The word transfer which originated as a contraction of transfer resistor is based upon above physical fictine of device.



To - Reverse caturation current

Ducto radiation Total by STO

Vo also increases by AVO : AVO = DIO. R.



FRE V. JE - FB, JC - RB > Photo transister is in active region

Ic = pIB + (+p) Ico but IB = 0, since base is open.

= 1c=(1+p) Ico

New, due to radiation. T1, lot; let by DIc.

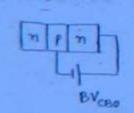
ΔIC = (1+β) ΔIO

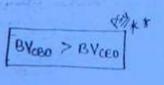
Vo Tee by . AVO = AIC. RL => (Itp) AICO. RL

Therefore, Photo translutory more sensitive than photo diode by a factor (1+B).

Maximum Voltage rating of Transister:

) Avalanche Multiplication -





Bless - maximum reverse bising voltage which may be applied before breakdown blo che of transistor, keeping E open, ie, Is=0. © Wiki Engineering

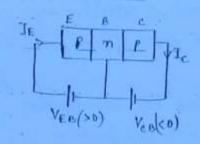
 SVCEO → For CP configuration, collector to emitter breakdown voltage with spen circuit base.

1 Note

0

- In a particular transictor, voltage limit is determined by funch-through or breakdown (due to avalonche multiflication) rehidever occur at the lower voltage.

### Ebers Moll Model -



(Forward or Normal Active mide) (xt or all)

parameters Kni di, Ico, IEo are not independent (experimentally).

each other as  $A_{H}.I_{ED} = \alpha_{T}.I_{ED}$ 

$$\frac{\alpha_{N}}{\alpha_{I}} = \frac{I_{CO}}{I_{EO}} \Rightarrow \left[ \alpha_{N} \geqslant \alpha_{I} \right]^{N*}$$

$$\begin{array}{c|c} & & & & & & & & \\ & & & & & & & \\ \hline I_E & & & & & & \\ \hline & & & & & & \\ \hline I_{EO} & & & & & \\ \hline \end{array}$$

Eleas Moll · Model

(Revenue or Inverse Active Mode) (c(x)

$$I_{E0} = 0.5I_{C0}$$
 to  $I_{C0}$ . {re,  $I_{E0} < I_{C0}$  as conc. of E> conc. of C

Now, if 
$$\alpha_{x} = \alpha_{x} = 0$$
;
then

- Model involves two ideal diodes placed back to back with reverse saturation current Ico & Teo and two dependent cccs shunting ideal diodes. 132

observe from the figure that, defendent current source can be eliminated from this figure provided of = on for eg., by making base width much larger than difficulty length of minority carrier in base, then all minority earners will recombine in base and none will survive to reach collector. For this case current gain of will be o. Under this condition transistor action ceases and we shortly have two diodes placed back to back.

This discussion shows why it is impossible to construct a transistor by

- This discussion shows why it is impossible to construct a transition by simply connecting two separate or isolated diode in series ofposing.

A cascade of two p-n diode exhibits transcitor properties like amplification only if carrier injected across one function diffuse across and junction.

Cutiff Mode:

JE&JC - RB. > 1=0.

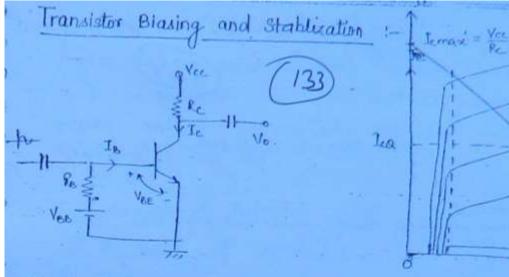
from egn O - Ic = Ico

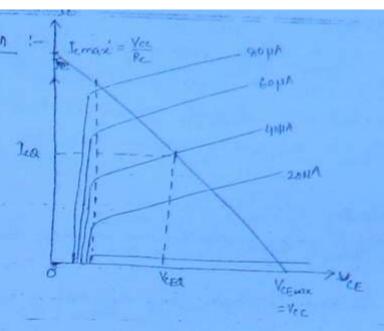
Saturation

JE & Jc - FB.

From egn 1 -

 $I_{c} = c I_{r} I_{E} - I_{co} \left[ e^{V_{co}/V_{T}} - 1 \right]$ 





$$V_{CE} = V_{CC} - I_{C}R_{C} \Rightarrow I_{CR} = V_{CC} - V_{CE} \Rightarrow I_{C} = -\frac{V_{CE}}{R_{C}} + \frac{V_{CE}}{R_{C}} - 3$$

$$\downarrow_{A} p_{C} \text{ lead line}$$

from eqn (1); set Io = 40 mm, then

$$B = \frac{I_{CQ}}{I_{B}}$$

$$\Rightarrow Q = Q_{Uescient} Point/operating point.$$

$$\Rightarrow 0 = f(I_{B}, I_{C}, V_{CE}).$$

On application of input \_

$$I_b = \frac{I_B + i_b}{(Pc) (Ac)} \Rightarrow I_c' = \beta I_b = \beta (I_B + i_b) = I_C + i_c$$

How, let IB= 40MA & ib = 20 simutps, then Ib = 40 + 20 simut

- : Ibmax = 60 μА , Ibmin = 20 μ А

Hence, a point lies well within the active region. Harefore,

no distortion in the output.

Hence, transistor is just in active region.

1<sub>bmax</sub> = 90 μA, I<sub>bmin</sub> = -10

, Now , there will be distorion in the off.

Adjusting IB = 20 MA, is = 20 simult.

There = 40 MA / Itemin = 0 A.

The sound,  $L_b = 40 \sin \omega t$ The sound  $T_{bman} = 60$ ,  $T_{bmin} = -20$ 

In=bops, ib = 30 sin wit =) Ibmax = \$0, Ibmin = 30

#### Important Prints:

- The collector chare or ofp chare of homistor is divided into saturation, cutoff and active regions.

- Transister can work as a switch when operated in saturation and cutoff region, ie, extreme ends of the characteristics.

## - Procedure to plot De load line & point -

- Dint on given charac
- 2) Draw a shought line joining some de Vac & this strought line is called de load line.
- s) find the operating value IB, Ie & Vee for the given chit I locate there values on given charac.
- 4) Project three operating values on de load line & the intercapting point is called 9 print
- The transistor is said to be under quescient cond' when zero i/p signal is applied.

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Transistor can work as an amplifier if a point is within active region but a point is temp sensitive, i.e., as It, Ict and VCE to, so that a point will be morning towards saturation region and if entered into saturation region, transistor will stip working as an amp.

I in will provide more fower gain or amplification, when a point

is in middle of de load line.

tion of ilp signal. a point is plotted to get faithful reportue

> 4 shape of ofp signal differs from shape of up signal, it is

said to be distorted.

- for a stable circuit, the variation in a point due to temp-must be small.

## Bias Stability :-

- Stability is effected due to -

1) Temp Butability

(a) Ico -> It doubles for every 10° rise in temp.

TA > Ico 1 > Ich . > a point shift towards saturation.

(b) 
$$\frac{V_{BE}}{c}$$
  $\rightarrow$   $\frac{V_{b}}{c}$   $\frac{dV_{b}}{c} = -2.5 \text{mV/°C}$ , is  $\frac{dV_{BE}}{dt} = -2.3 \text{mV/°C}$ .

: 
$$I_B = \frac{V_{BB} - V_{BE}}{R_B}$$
 . As  $T \uparrow$ ,  $V_{BE} \downarrow$ ,  $I_B \uparrow \Rightarrow I_C \uparrow \& V_{CE} \downarrow$   
=10 -> contraction.

Note - BI with temp but change is negligible.

2) Replacement of Transistor - B is highly affected due to replacement of transistors

(: Since small change in or results in large change in B)

## Stablisation Techniques

Bioling Techniques

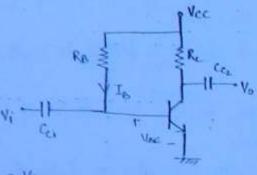
- (1) C-B Bitaing.
- (a) Self-Bioled

Compensation Techniques

- () Diode compensation
- (a) Sensister d'Tromister compensation.
- (3) Transistor compensation

### Fixed Biased Circuit -

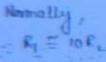
$$\rightarrow \quad \Gamma_{B} = \frac{V_{cc} - V_{BE}}{R_{B}} = constant$$



$$\Rightarrow V_{TR} = \frac{R_{\perp}}{R_1 + R_{\perp}}, V_{ex}$$

$$R_{TR} = R_1 H R_{\perp}$$

$$R_{TR} = R_1 \Pi R_2$$



$$= \frac{R_{TH} - R_B}{V_{Th} - V_{BA}} = \frac{R_{TH} - R_B}{V_{Th}}$$

## Stability factors :-

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0

0

(\$0)

0

(3

0

8

In active region,

$$\Rightarrow S = \frac{1+\beta}{1-\beta \cdot \frac{dT_{B}}{dT_{C}}}.$$

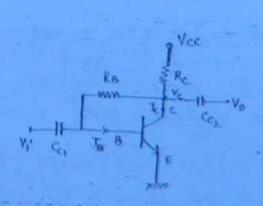
$$S \to 1$$
 TB = constant,  $\frac{dIB}{dI_C} = 0 \Rightarrow S = (1+p)$   $\to ckt is unstable  $\to fixed Blasse$$ 

If Ic 1 then IB should 
$$\psi$$
 , i.e.,  $\frac{dI_B}{dI_C} < 0$ . In ideal case,  $\frac{dI_B}{dI_C} = -1$   $\Rightarrow$   $S = 1$   $\rightarrow$  trighty stable.

Range of 
$$S \rightarrow \left[1 \leqslant S \leqslant (1+\beta)\right]^{44}$$

# Techniques :-

- During De analysis, Ce, & Ce will act as open circuit.



When transistor is in active region—

Le = pIp + (1+p) Ico. —  $\square^n$ .

On manipulating  $\square$  —  $S = \frac{dI_c}{dI_{co}} = \frac{1+p}{1-p \cdot dI_0}$  —  $\square$ . ( keeping Voe & p emulant)

Applying KVI at  $i/\rho - V_{cc} = (I_c + I_B) R_c + I_B R_B + V_B E$ Differentiating with  $I_c - O = (R_c + R_B) \frac{dI_B}{dI_c} + R_c + O$   $\Rightarrow \frac{dI_B}{dI_c} = \frac{-R_c}{R_c + R_B} \qquad (3)$ 

S=  $\frac{1+\beta}{1+\frac{\beta-R_c}{R_c+R_B}}$  < (1+B) Hence circuit is stable.

 $S = (1+\beta) \cdot \frac{R_c + R_B}{R_B + R_C (1+\beta)}$ 

The Re (1+p) >> RB, then 
$$S = 1 + \frac{R_0}{R_0}$$

- → It Rc1& Rp + then SI; tunce & depends on load resistance.
- > It is voltage shout feedback, hence Rit and Rot.
- -> There is unccessary -ve feedback, circuit is not preferable.

Theoretical Analysis—

from circuit,  $V_c = Vcc - (I_c + I_B)R_c$  and  $I_c = pI_g + (i+p)I_{co} \approx pI_g$   $= Vc \approx Vcc - I_cR_c - 0.$   $= I_B = Vc - V_{BE} - 0$ from 0 + 0 - 11 T1 [1.18 Vac+] and/or p1, then Ic 1]

from DID- If T1, [Icol & VOE+] and for p1, then Ici) - re feedback.

then Vc + but IB+ with Vc1 > Ic+.

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Therefore, Tise in Ic is compensated and Ic is almost constant. (139)

This circuit will compensate for all type of variations, i.e., Teo, Vee or B.

Ö

$$S = \frac{1+\beta}{1-\beta \frac{d \log \alpha}{d \log \alpha}}$$

$$V_{cc}$$
 $R_{c}$ 
 $R_{c}$ 

$$\Rightarrow \frac{dT_{B}}{dT_{C}} = \frac{-Re}{R_{D}+RE} - 3$$

Substituting in eq. 
$$S = \frac{1+\beta}{1+\beta RE} \times (1+\beta) \rightarrow \text{Hence clet is}$$

$$S = \frac{1+\beta}{RB+RE} \times (1+\beta) \rightarrow \text{Hence clet is}$$

$$0 \rightarrow 4 \quad (1+p)RE >> Ro, then, 
$$0 \rightarrow 4 \quad (1+p)RE >> Ro, then, 
$$0 \rightarrow 5 \quad \text{Trick-pendent of boad res}$$

$$0 \rightarrow RE$$$$$$

7 Input & ofp reinformer will increase.

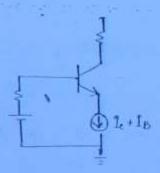
\* It is current series feedback.

From DRD, when It, [Icot, Veet Jandler gt, then Ict > VET. => IB + + Te + -> It will control variation due to all factors. A Rise in It is compensated, It is almost constant.

\* 4 he is replaced by an ideal, current source, then s will become 1. (as internal resultance of active (current) source is very high, ideally a)

Ideal current source,

fractical current source, he = very high.

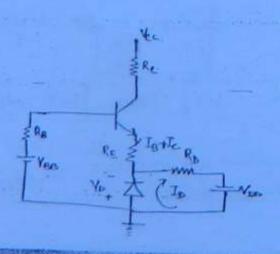


\* Self-biased circuit is also called as voltage divider / Potential divider or emilter bias circuit

Compensation Techniques: (Bias Compensation)

refers to use of temp sensitive devices like diode Mamistar, sensister etc

> Diede Compensation



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If  $I_b = V_{bb} - V_b$  (10+  $I_c$ ) } From eq<sup>7</sup>, for diode to be  $f_b = I_c$ .

If  $I_b = V_{bb} - V_b$  (2) \text{From eq<sup>7</sup>, for diode to be  $f_b = I_c$ .

If  $I_b = V_{bb} - V_b$  (14)

Rena, if we set  $I_b$  based on eq<sup>7</sup>(2) then we can make D forward bias.

- When D-18, then

- Fransistor is in active region

= Te= pro+ (1+p)100 -0

md, <u>Jc - (μ+β) Ico</u> = IB — ②

form checuit, VeB = IBRB + VBE + (Ic+IB)RE - VD - 3.

from (2) & (3) ÷

 $1_{c} = \frac{\beta \left[ V_{00} - \left( V_{00} - V_{0} \right) \right] + \left( R_{0} + R_{E} \right) \left( 1 + \beta \right) I_{10}}{R_{0} + R_{E} \left( 1 + \beta \right)} - 4$ 

· by transister & diode are of similar materials - dvee dvo = -2.5 mv 9°c

To dépende on (Vac-1/0)

for 1°C change in T, (Vac-2's) - (Vb-2's) = (VBE-Vb),

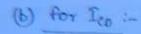
Hence, I'c will remain constant, even if YBE is changing.

- The change of Ver with temp contribute significantly to change in I.e. of Silicon transistor, therefore circuit is useful for stabilising.

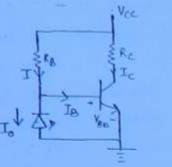
  Si transistor.
- If the diode is of same makinal & type, voltage vo across diode will have some temps coeff as VBE., then from egn (1) it clear that Ic will be insensitive to variation in VBE.

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-) For Ge, Ver = 0.2V = voltage across ) I (diode) since they are in parallel I (



- I = Vcc - VBE \_ constant } considering Voe = constant }

$$\Rightarrow I_{c} = \beta[I-I_{o}] + (i+\beta)I_{co} \Rightarrow I_{c} = \beta I - \beta I_{o} + \beta I_{co}$$

$$\Rightarrow I_{c} = \beta I + \beta (I_{co}-I_{o})$$

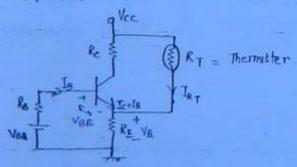
2 " B>>1 }

$$= \sum_{\alpha} \left[ \hat{I}_{\alpha} = \beta \hat{I} + \beta \left( \hat{I}_{\alpha} - \hat{I}_{\alpha} \right) \right] + \sum_{\alpha} \sum_{\alpha} \hat{I}_{\alpha} = \beta \hat{I}_{\alpha} + \beta \left( \hat{I}_{\alpha} - \hat{I}_{\alpha} \right) \right]$$

- for he transistor, change in Ico with temp play more important role in collector current stability, therefore, this ext is useful for stabilising he Fr.
- If the divide & Fr. are of same type, then To of divide will result to a same rate as few. Therefore, It will be invensitive to variation.

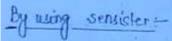
  In Ico.
- 2) Thermister and Sensister compensatur:
- Thermister -> NTC of resistivity -, Th of
- (highly doled) PTC of resistinty; T1, o-1

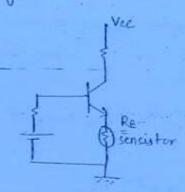
$$= I_B = \underbrace{V_{0B} - V_{BE} - V_{E}}_{R_B}$$



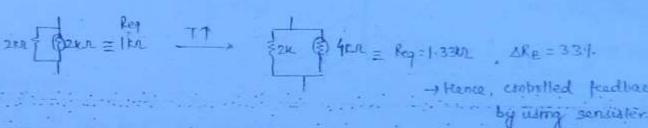
-> 
$$V_E = (I_B + I_C + I_{RT}) R_E \approx (J_C + I_{RT}) R_E$$

Now, When TA, (Scot, VBE ), then Ict, RT + & TRTT > VEM > IB+ = Ic+ Hence, rise in Ic is compensated.



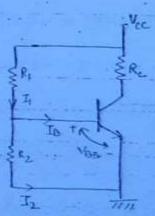


\* Re replaced by a sergiter or we can place a sonsister porallel to RE.



IB = I1- I2 T, = Vcc - VEE

$$\hat{T}_2 = \frac{V_{BE}}{R_2}$$



Noo, When T.T. (Icols Voel) then Ic T, then to compense we want Is 4 . or 1 4 and/or 12 1

= R1 1 and/or R2 1

cence, R, can be replaced by sensister & R2 can be replaced by Thermistor or RI can be replaced by sensister in 11 & Rz with thermister in 11.

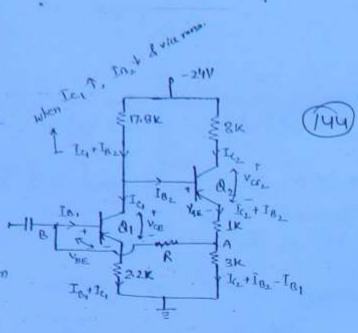
B= 100 for each tourselver

(a) betemine R so that

quescient conditions one  $V_{CE_1} = -4V$ ,  $V_{CE_2} = -6V$ 

(b) Explain how Q-point stabilisation is obtained.

Tala VAE = 0.2V.



Sol Since B>>1, 1 B2 << Tc2 & To1 << Tc4. D we will night I 8, & To2

Ey IVI —  $-24 - 17.8 (34) - V_{0E_1} - 2.2 (5c_1) = 0 = 9 - 24 - (-4) = 17.8 (c_1 + 2.2 3c_1)$ 

=> - 20Tc, = 20

7 Ty = -1 mA

By EVL-

 $R = \frac{V_{A} - V_{B}}{\Gamma_{B_{1}}}, \quad V_{A} = 3 \times x (-1.5) = -4.5 \text{ V}$   $V_{B} = V_{BE} + \Gamma_{C_{1}} \times 2.2 = -0.2 - 1 \times 2.2$   $4 V_{B} = -2.4 \text{ V}.$   $T_{B_{1}} = T_{C_{1}} = -0.01 \text{ mA}$ 

$$\Rightarrow \qquad \text{Te}_1 = \frac{\text{Te}_1}{p} = -0.01 \text{ mA}$$

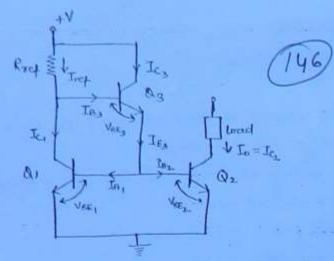
$$R = \frac{-4.5 - (-2.4)}{-0.01} = 210 \text{KJ}.$$

(b) When TA, Iscalt, Ivolt, Iscalt, Iscalt, Iscalt, Iscalt, Iscalt , Iscalt

04th September, 2012 0 Current Mirror Circuit :-The outfut current is forced to equal the ifp current, i.e., ofp current is a mirror image of if current: They are widely used in designing of differential amplifiers & Ics. Their major advantages area) Simplicity in circuit design. b) Easy to fabricate. e) Minimum no. of components are regd. d) was cost. - Basic Diagram :-Regd conditions :-Ice = Io 1 pose -> Both Tr. are in active > Both Fr. gre identical, ie, pr- B2= B. R Voe, - Vera - Vera of B should be very large 4 Writing KVL 0- Tref Rief - VEE = - VEE 2) Iref = VEE - VEE = independent of bood. from figure \_ IB = IB \_ ? I is divided among two identical paths } B1 = B2 > Ic1 = Ic2 Since, Tref = Ic+1' > Tref = Ic2 + 2182 -> Iref = To + 2Tc. > Tref = Is if B is very large.

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By applying KVL-

New,

from fig., IB, = IB2 & identical paths for IE3 }.

$$\exists T_{B_3} + T_{C_3} = T_{E_3} \Rightarrow T_{E_3} = T_{B_3} + \beta_3^T B_3$$

$$\exists T_{E_3} = T_{B_3} + \beta_3^T B_3$$

$$\stackrel{\text{all}}{=} \frac{2 I_{C_2}}{e} = (\beta_3^{+1}) I_{B_3}$$

$$\Rightarrow \boxed{I_{B_3} = \frac{2 I_{C_2}}{\beta(1+\beta_3)}} \qquad \boxed{4}$$

from 3 & 4 - in 2 -

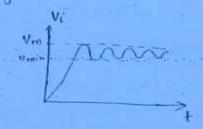
Since 8>>1 -

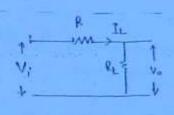
$$I_0 = \frac{I_{ref}}{1 + \frac{2}{\beta^2}} \Rightarrow I_0 \approx I_{ref}$$

$$\Rightarrow \int I_0 = \left(\frac{\beta^2 + \beta}{\beta^2 + \beta + 2}\right) \cdot I_{ref}$$

The necessary that 
$$Q_1 Q_2$$
 are identical. If  $Q_3$  is not identical then
$$\frac{T_0}{1 + \frac{2}{p(1+p_3)}} \quad \frac{1}{p(1+p_3)} \quad \frac{1}{p(1+p_3)}$$

- In this circuit, it is not required to have very high B, since a term of B is affecting in denominator which will be very large.
- > Voltage Regulator Circuit :-





- I'me variation :- variation in Vo due to variation in line voltage Vi-

Line Regulation :- Vi = varying, Re= constant, Vo should be constant.

" Yo & TLRL , hence It should be constant for Vo to be constant.

Hence in Line regulation, line voltage is varying but load current certains constant.

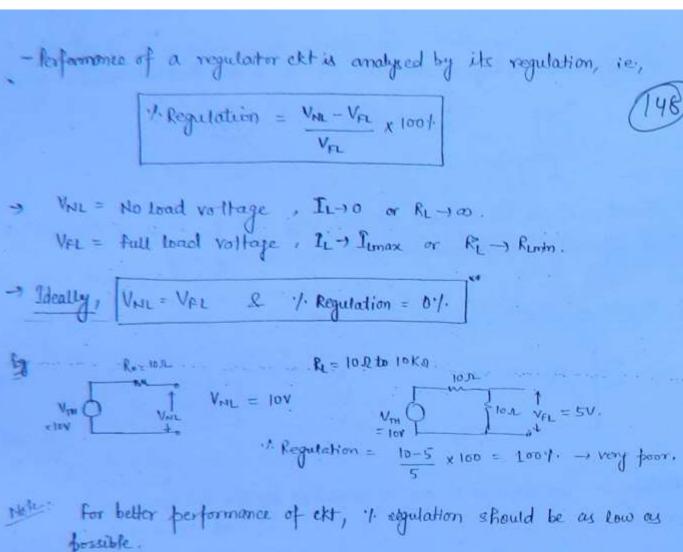
load Regulation 1. Vi = constant, R\_= varying,

for Vo to be constant, when RLTIL should be and vice versa. Hence, in load regulation, RL ranging but Vo remains constant.

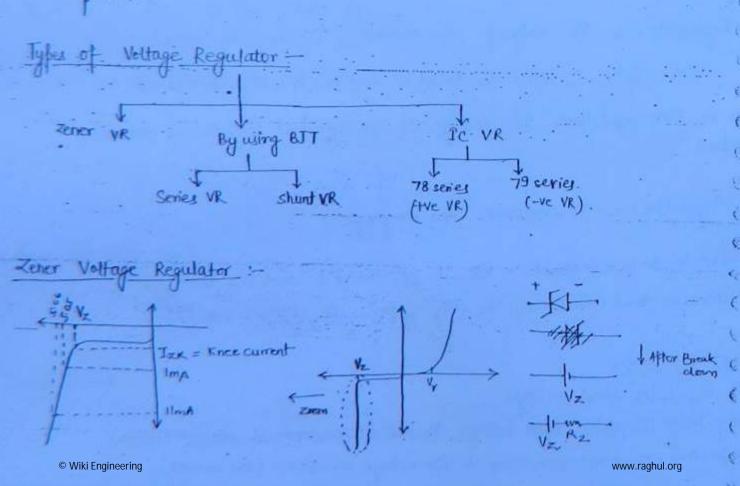
Voltage Regulator:

It regulates load voltage.

- In regulator circuit, load voltage to will be maintained almost combant irrespective of load variations & ilp voltage variations (the variant www.raghul.org



possible.



\* Ize = knee current or minimum current regd for zener clinds to go in breakdown  $0 \rightarrow P_{zmin} = T_{zk} \times V_{z}$ - Izman = maximum current across zoner diode without damaging it. -) Pamore = Iamore x Vz. => Iamore = Variore > 1/2 is almost emutant but not exactly emutant. I from flot, slope =  $\frac{1}{R_Z} = \frac{11-1}{5.06-5.05} = 1000 \text{ m A/V} = 1A/V$ => R2 =15L Hence, exact representation of zoner dirde BD is battery followed by Rz. - Zener Voltage Regulator -Vi = unregulated voltage Yo = Regulated " -) for voltage regulation, zoner diode should be in BD for entire range of Vi (Vmin to Vmore). 1. - 5. Vo = Vz  $T = \frac{V_1 - V_0}{R} \quad \text{and} \quad I = I_2 + I_L$  $T_{L} = \frac{V_{D}}{R_{L}} = \frac{V_{D}}{R_{L}} = \frac{Cantont}{R_{L}}$ , then  $T_{L} = constant$ Now, Vi - varying then I - varying & IL = constant . Iz = varying teence for satisfactory performance of ext 9 .: Range of Iz / In 3 Iz & Izmax ? I > TzK + IL to be working in BA  $\Rightarrow \text{ 1 Imin} = \frac{V_{\text{imin}} - V_{2}}{R} \cdot \int_{R} I_{\text{max}} = \frac{V_{\text{imax}} - V_{2}}{R}$  $T_{min} \gg I_{ZX} + I_L.$ 

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Case I : Vi = correlant , Re = varying-

= g = construct - Vi-Ve\_

IL = Variable

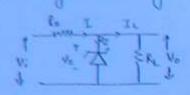
-> combining both cases, the egn for satisfactory operation of regulator circuit

-> Power dissipation across zener diade & Pman , Hence the following condition should be satisfied -

Workbook - Unp. 1. Pg. 29. Que. 13 !- Wil = 30V , VFL = 25V y. Regulation = 30-25 x100 = 20%.  $V \stackrel{t}{=} V_{NL} = 30V, \qquad \Rightarrow \qquad \begin{array}{c} T & R_{a} \\ \hline \end{array} \qquad T = 14.$ · Runin = 25 = 2552., ofp resistance 0  $= R_0 = \frac{SV}{10} = S\Omega.$ Vin DEL VZ = Vo = 10mA. Dues 15 " 0 0 Vin = 30 to sov. for satisfactory ofp = 1 > I -xx + 12 0 > Vmin-V2 > (1+10)mA = 30-10 > 11mA 0 =1 R < 1818 KD 0 Que 16: IL - 100-to 500 mA. & France V/2 Roma Morriso Vin-V2 > Izk+ Irnax Vim = 12V (d) JEK 20. > 12-5 = 0+500mA → R = 14 12. 0 Duy 17 . V1 - 20 to Soy. 9 (c) load current man => him zener current. Virsin-Vz > Tzk+ Iman = 20-5-8 > 0.5mA+ Piman 0 0 79 ILMAR & 14.2-0.5 = ILMAX < 13.7 mA Ques. 19 : 2000 0 when V: = 100ā i= 10-7 = 1/70 A 1  $V_0 = 7 + \frac{1}{70} \times 10 = 7.14 \text{V}$ 3 when vi=16V -I 1= 16-7 = 3170 8 Vo=7+3 x10=71

9

- Line Regulation using zoner diode -



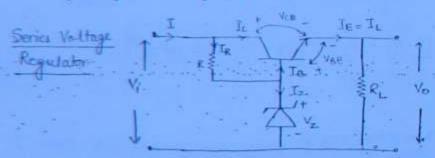
$$I = \frac{V_{i} - V_{e}}{R} , \quad I = I_{e} + I_{e} \Rightarrow I_{e} = I - I_{e}$$

When Vit, It, V= 1 (slightly), Iz 1+, It remains complet When Vit, It, V2+ (elightly), I2 to , It " ",

lond legislation using Zener diede

when RL I, Vo I (seightly), Vz I (slightly), IzIto, ILT. i. Vo = ILFL = constant.

Voltage Regulation by wing BJT:



→ BJT should be in active region & zener diocle in . Breakdown region for tull range of Vi trom Vmin to Vmore.

from ext -

$$\rightarrow I_R = \frac{V_i - V_z}{R}$$

pener dissipation:

Across Rener divide: 
$$R_z = V_z \cdot I_z \leq P_{zmax}$$
.

Across BJT :-  $R_T = T_c \cdot V_{cc}$ .

Line Regulation -

 $Y_1 \rightarrow Vary - R_L = constant \cdot I_B = I_R - I_2$ .

(153)

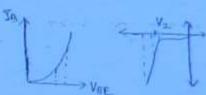
Vit , It , IR \ (Ic is not controlled by Vi, it is controlled by IB), then Vz \ (slightly) Iz\ = IB = constant = IE = constant

TE = Iz = almost constant , therefore Vo = constant.

Vi = constant, R\_ = vary. Vo = Vz - VBE, IR=1 = + IBb = constant.

RLT, VOI, (VET JET), SET & : TOTS, ILT

. Vo = ILRL = constant.



\* The circuit is in common collector configuration and hence this regulator is also called emitter follower VR.

Note.

\* let Iz variation is STz= 1 to 11 mA = STz=10 mA.

ATL = 10ml. } for zener diede ett

ΔIZ=10mA = ΔIB

ΔIE = (HB) ΔIB = 1000 MA for BIT CKF

to zener akt.

But, for Vi variation, same froblem is present in both.

for BJT, As Vit, IRT, IzT hence for large Vi variation, Iz will vary to Izmax and Pz will cross Pzmax.

Shunt Regulator :-

AVO = VZ+VBE - RV

 $I = \frac{V_{i} - V_{0}}{R}$   $\begin{cases} = \frac{URV - RV}{R} \end{cases}$ Ly timiting resisting

-> PT = VCE. Ic

-) 12 = V2, 12

Tr - Active

Vz > Bp

\* Transitor is in common emiller configuration.

-> IB=IZ

Te= BIB.

- I= Iz+I+IL -0

line Regulation + Vi = vary, R\_= constant

When Vit, It, { Y27 I21}, Tet I due to Is}, IL (constant).

\$= 6+ DI = 1000 WA, then DIZ = AIR = 10 WA.

Ever the total charge is distributed by Iz & Ic & from (1) }

load Regulation - Vi = constant, Re= vary.

a Visconstmit of Is constant. =

+ when RLT, Vot, { Vzt IzT}, Ict, ILV. 2 I= Ic+ IL+ Izelongtout}

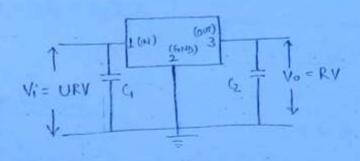
.. R. IL = Vo = constant.

-> This ext is suitable for high variation of RL as well as vi.

# Regulator:

three terminal voltage regulator,

IN, OUT and GROUND.



C, & C2 is connected to bypass high frequency moise.

78	series
(-tve, c	1 voltage)
	Vo
7805	+5 V

+10V

79 series	
(-ve output voltage)	
V <sub>0</sub>	

1 80.00	Karana
7812	+12V
7915	+15V
70.2h	+24V

7210

# LOW frequency Analysis of BJT :-

(156)

h-parameters :-

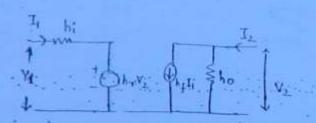
$$V_1 = h_1 T_1 + h_{12} V_2$$
  
$$T_2 = h_{21} \hat{T}_1 + h_{22} V_2$$

$$\rightarrow$$
 hn =  $\frac{V_L}{L_I}$  |  $V_{z=0}$  = 1/p impedance when of is se.

$$\rightarrow h_{12} = \frac{V_1}{V_2} \Big|_{\Sigma_1 = 0} = \text{Reverse voltagegain when if is o.c.}$$

$$\frac{h_{11} = h_1^*}{h_{21} = h_1} = h_1 = h_0$$

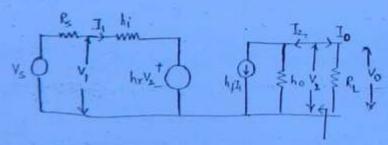
Hence, 
$$V_1 = h_1^* I_1 + h_2 V_2$$
  
 $I_2 = h_1^* I_1 + h_0 V_2$ .



# Derivation of AI, Ri, Av, Avs, Ro :-

#### Current Gain AI

$$A_{\overline{I}} = \frac{I_0}{\overline{I}_1} = -\frac{\overline{I}_2}{\overline{I}_1}$$



from 0 20-Iz (1+ hore) = hf I,

$$A_{\rm I} = \frac{-h_{\rm f}}{1 + h_{\rm o}R_{\rm L}}$$

$$\begin{array}{c} ( \rightarrow \quad \forall_{1} = h_{1} I_{1} + h_{T} V_{2} . \\ ( \rightarrow \quad \forall_{2} = -I_{2} R_{L} = A_{I} I_{1} R_{L} \end{array}) \begin{array}{c} \forall_{1} = h_{1} I_{1} + A_{I} I_{1} R_{L} h_{T} \\ ( \rightarrow \quad \forall_{2} = -I_{2} R_{L} = A_{I} I_{1} R_{L} \end{array}) \begin{array}{c} \forall_{1} = h_{1} I_{1} + A_{I} I_{1} R_{L} h_{T} \\ ( \rightarrow \quad \forall_{2} = h_{1} I_{1} R_{L} h_{T} \\ ( \rightarrow \quad \forall_{2} = h_{1} I_{1} R_{L} h_{T} \\ ( \rightarrow \quad \forall_{2} = h_{1} I_{1} R_{L} h_{T} \\ ( \rightarrow \quad \forall_{2} = h_{1} I_{1} R_{L} h_{T} \\ ( \rightarrow \quad \forall_{2} = h_{1} I_{1} R_{L} h_{T} \\ ( \rightarrow \quad \forall_{2} = h_{1} I_{1} R_{L} h_{T} R_{$$

$$\Rightarrow$$
  $R_i^* = h_i + h_t A_L \cdot R_L$ 

$$A_{YS} = \frac{V_0}{V_S} = \frac{V_2}{V_S} = \frac{V_2}{V_1} \times \frac{V_1}{V_S} . = A_V \cdot \frac{V_1}{V_S} .$$

$$v_s$$

$$V_s = \frac{R_s}{R_i + R_s}$$

$$V_s = \frac{R_i}{R_i + R_s}$$

$$V_s = \frac{A_V \cdot R_i}{R_i + R_s} = \frac{A_T \cdot R_L}{R_i + R_s}$$

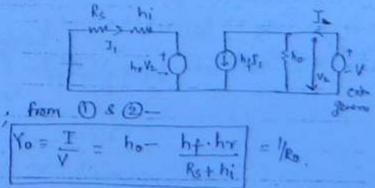
$$\mathbf{I}_{\underline{s}} \bigoplus \{ \underbrace{I_{\underline{s}}}_{I_{\underline{s}}} \mid \underbrace{A_{\underline{T}_{\underline{s}}}}_{I_{\underline{s}}} = \underbrace{-\frac{T_{\underline{b}}}{I_{\underline{s}}}}_{I_{\underline{s}}} = \underbrace{-\frac{T_{\underline{b}}}{I_{\underline{s}}}}_{I_{\underline{s}}} = \underbrace{A_{\underline{T}} \cdot \underbrace{T_{\underline{t}}}_{I_{\underline{s}}}}_{I_{\underline{s}}} = \underbrace{A_{\underline{T}} \cdot \underbrace{T_{\underline{t}}}_{I_{\underline{s}}}}_{I_{\underline{s}}}$$

$$\frac{U}{T_s} = \frac{R_s}{R_s + R_i} \quad \therefore \quad A_{Ts} = A_T \cdot \frac{R_s}{R_s + R_i}$$

$$\frac{1}{8} \frac{\text{KVL at } |P \rightarrow -h_Y \vee_2}{R_S + h_i} = I_1 - 2$$

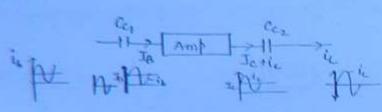
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$$V_0 = \frac{T}{V}$$



$$\frac{\alpha}{n!} = \frac{1}{R_{D}}$$

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 $T_{c} + \dot{t}_{c} = \beta_{c} T_{B} + \beta_{c} \dot{t}_{b}$   $|Ar| = \frac{\dot{t}_{c}}{\dot{t}_{b}}$ 



Tr in active region .

\* We can neglect be sources in ac analysis as long as they are keeping next in

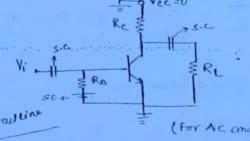
\* During AC analysis -

- All De sources =0, i.e, Voltage source = S.C., current source = D.C.

- Compling apparitors ca & Cez (Ch, & Cbz) & bypass capacitor acts as

S.C.

Pac = Isel ; Pac = libl = hije

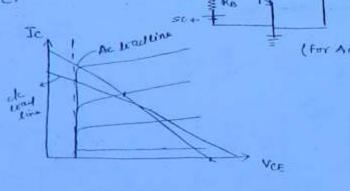


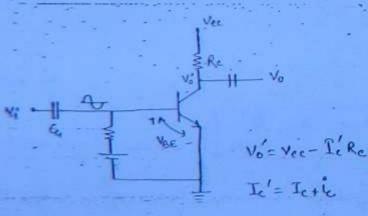
AC toad line +

\* Stope of de load line = - 1/Rc

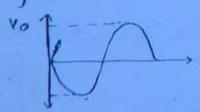
RL' = RellRL < Re.

Slope of ac load line = - 1/RL





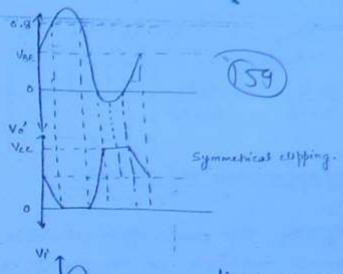
for the ife eyele, Vec 1, let = lc1 = Vo'1 ? = 180° phase chift.



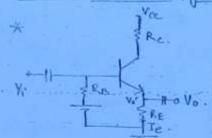
# Symmetrical clipping -

Ideally, voltage swing = Vcc

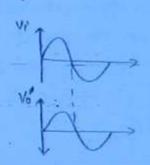
Practically, " = Vcc-Vcesat



Common Collector Config :



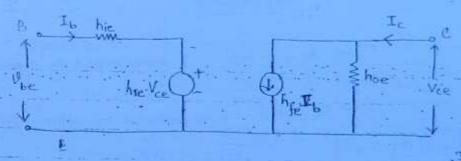
Vo = Ie. RE . \_ {VBE 1, IB1, IE1, Vo 1 }.



teanco, for cc configuration,

Common collector

# Hybrid Model for Common Emiller Configuration :-



Vbe = ble Ib + bre Vce - (1)

-\*

state due to conty offert

educto early

$$Avs = \frac{AvRi}{Rc+RL^2} = \frac{AIRL}{Rs+RI}$$

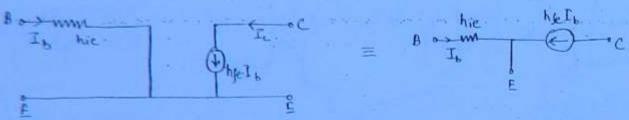
$$Y_0 = \frac{1}{Ro} = \frac{hoc}{Rc+hie}$$

$$Y_0 = Y_{R_0} = h_{0e} - \frac{h_{vehje}}{R_{s} + h_{ie}}$$

# Simplified Approximate Hybrid Model-

+ If here soil, then error in approx calculation \$ 10%, therefore we can use approximate midel , ie, we can neglect early effect.

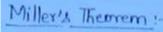
hre = 0, hoe = 0 (=) admillance = 0 =) resistance = 0 = open)



-> It is valid for CE, CC & CB configuration and for ripm as well as prop Fr.

#### Exact

#### Approximate



$$\begin{array}{c|c} K_{c} \frac{V_{2}}{V_{1}} & \begin{array}{c} \sum_{i=1}^{3} & W_{i} - W_$$

from Agus

$$T_1 = \frac{V_1 - V_2}{z} = \frac{V_1}{z_1} \quad (\text{from tig 2})$$

$$|z| = \frac{V_1 z}{V_1 - V_2} \Rightarrow |z| = \frac{z}{\frac{z}{V_1} - \frac{z}{V_1}} \Rightarrow |z| = \frac{z}{1 - K}$$

Surilority ,

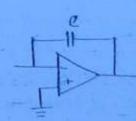
$$\mathbf{I}_2 = \frac{\mathbf{V_2} - \mathbf{V_1}}{\mathbf{Z}} \quad \stackrel{?}{=} \quad \frac{\mathbf{V_2}}{\mathbf{Z_2}}$$

When Z = capacitor \_

$$z_1 = \frac{z}{1-\kappa} \quad \Rightarrow \quad \frac{1}{\omega c_1} \quad = \quad \frac{1}{\sqrt{\omega c}} \quad \Rightarrow \quad \frac{c_1 = (1-\kappa)c}{1-\kappa}$$

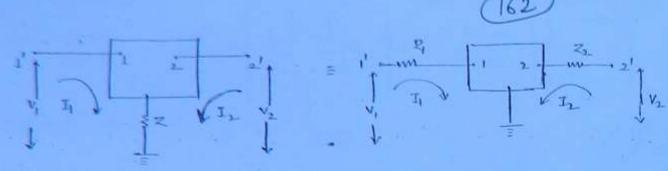
$$\vec{\beta}_{2} = \frac{k'z}{k-1} = \frac{1}{\omega_{\zeta_{2}}} = \frac{k(1/\omega_{\zeta})}{\kappa-1} = \frac{1}{\zeta_{2}} = \frac{(\kappa-1)}{\kappa} \cdot c$$

Workbook.



> Hence if & ofp capacitances increases. and impedance will decrease

Due to this capacitance, if p path will be short (low impedance) of ye to emperate op one will be son I gain will to



$$\frac{\mathcal{I}'}{\mathsf{Y}^{L^{\pm}}} - \frac{\mathcal{I}'}{\mathsf{I}^{T}}$$

from the 
$$A = V_1 = (I_1 + I_2)Z = J_1 Z$$

$$\Rightarrow Z_1 = \begin{bmatrix} 1 + J_2 \\ I_1 \end{bmatrix} Z \Rightarrow Z_1 = (1 - A_1)Z$$
Simularity,  $V_2 = (I_1 + I_2)Z = J_2 Z_2$ 

$$\Rightarrow Z_{\perp} = \left(1 - \frac{1}{A_{\perp}}\right) Z \Rightarrow \left[Z_{2} = \left(\frac{A_{\perp} - 1}{A_{\perp}}\right) Z\right]$$

## Advantage of h farameters :

1) They are real nos at low frequency sy They are graphically obtained from its 4 of characteristics of transistor.

Pladvantager -

is All four h-parameters are temp sinsitive

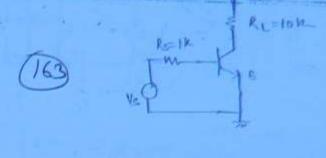
Afflication -

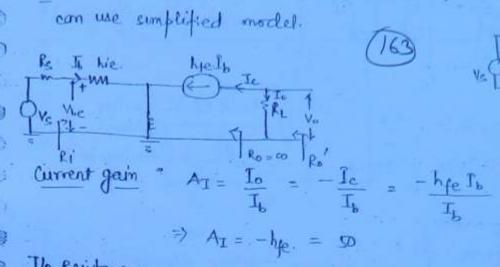
1) They are obtained only for small signal analysis of a transictor amplifier.

Ans If Re=toker, Rs=1 ke. find the various gains & if & off superdomes.

hie=11ka, hge=50, hre=hoe=0,

301h ance hoe = hre = 0 then we can use simplified model. 0





Current gain " 
$$A_{I} = \frac{I_{o}}{I_{b}} = -\frac{I_{c}}{I_{b}} = -\frac{h_{fe} I_{b}}{I_{b}}$$

I/p Resistance.

0

0

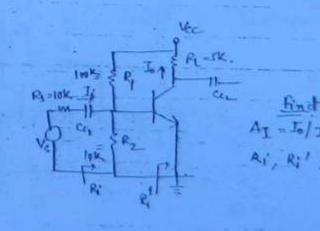
6

0

$$\frac{Ri'=\frac{V_{be}}{I_b}}{I_b} = hie = 1.1 \text{ Kg.}.$$

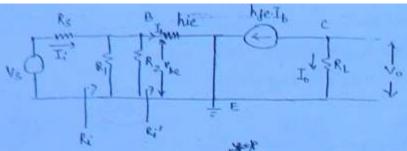
$$\Rightarrow Av_S = Av_1 \frac{Ri}{Ri + R_S} \Rightarrow Av_S = -237$$

- of resistance -



$$A_{I} = \frac{T_{0}}{T_{k}} = \frac{-h_{fe} \cdot T_{k}}{T_{k}}$$

$$A_{I} = -h_{fe} = -T_{0}$$



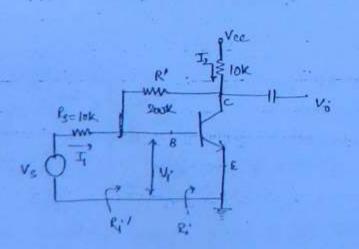
$$\rightarrow R' = \frac{V_{ke}}{I_k} = hie = 1.1t$$

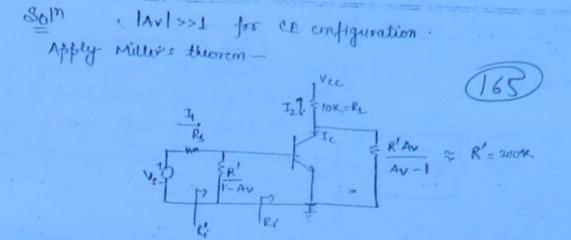
$$\Rightarrow A_{I} = \underline{J_{0}}$$

$$= \frac{-h_{1}e^{I_{1}}}{u^{\prime}} \times \underline{J_{b}}$$

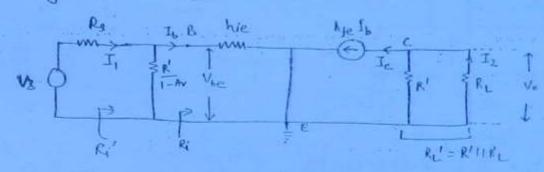
$$= \frac{-h_{2}e^{I_{1}}}{I_{1}} \times \underline{J_{b}}$$

$$= \frac{J_{b}}{I_{c}} \times \frac{I_{b}}{I_{c}} = \frac{9.09}{1.1+9.09}$$





Using approximate model -



Av = 
$$\frac{V_o}{V_{bc}} = \frac{\frac{1}{16}R_c}{\frac{1}{16}R_c} = \frac{\frac{(R^{\prime}R_c)^{\prime}}{R_c^{\prime}R_c}}{\frac{1}{16}R_c} = \frac{(-h_{fe}I_b) \cdot R_c^{\prime}}{\frac{1}{16}R_c} = \frac{-h_{fe}R_c^{\prime}}{h_{i'e}} = -432$$

$$A_{\underline{T}} = -\frac{2}{2} = -k_{\underline{f}} = -50$$

$$\Rightarrow A_{I}' = -\frac{T_2}{T_1} = \frac{V_0/R_L}{8V_S/R_S + R_1'}$$

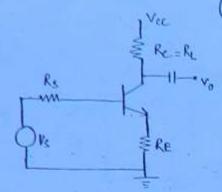
Ave = Vo Wo x Vhe

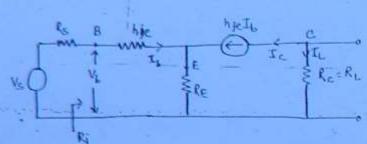
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Common Smith with unbyfassed emiller resistor,



-> If hoe (RE+R) < 01 thin we can use approximate model.





AI = -help = - hee = it will remain unaffected

yp resistance Ri = Vh -

Av = No = -hfe 16. Re. Av = -hfe Re hie + (1+hfe)Re Av + due to -ve feedback

If (I+hfe) 
$$l_E >> hie$$
 & hje>>1, then  $A_V = -\frac{R_L}{R_E} = \frac{-\frac{R_L}{R_E}}{R_E}$ . (approx),

> Due to -ve feedback, gain is highly stable as it is independent of In farameters (which in turn defends on temp.)

$$Av_s = Av \cdot \frac{R'}{(R_i + R_s)}$$
; if  $R_i > > R_s$  then  $Av_s \approx Av \approx -\frac{R_c}{R_E}$  (approx).

Effect of wing Re-

-> Current gain will remain unaffected.

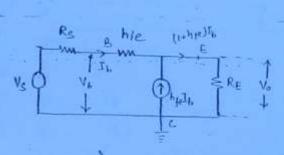
160

- if resistance les by (1+hge) RE

-> Voltage gain is stablised, i.e., Av is independent of any Tr. parameters.

-> of resistance les. I current series feedback, check dual of miller elet).

## Common Collector or Emiller Follower:



$$\rightarrow A_{\underline{I}} = \frac{T_0}{T_b} = \frac{(i+h_{fe})T_b}{T_b} \Rightarrow \boxed{i+h_{fe} = A_{\underline{I}}} / \phi = 0$$

$$\frac{\text{Voltage Gain}}{V_b} : \frac{V_0}{V_b} = \frac{\text{(1+hje)} R_E \cdot T_b}{R_i T_b} \Rightarrow A_V = \frac{\text{(1+hje)} R_E}{h_i e + \text{(1+hje)} R_E} \tag{1}$$

$$\Rightarrow A_{v} = \frac{(1+h_{fe})R_{E}}{h_{ie} + (1+h_{fe})R_{E}}$$
 (2)

CE	-	CE with RE	cc (168)
-hfe		-hfe	(1+hje)
hie		hie+ (1+hje)Re	hie+(1+hje) Re
AI. RL		-hje-Rc	(1+hfe) RE
Ri		hie + (1+hje)Re	hie + (1+hfe) Re
63		CO)	hie + Rs
		* 1	1+hfe
RollRL = RL		Rolle RL	RollRL
	-hge hie AI. RL Ri	-hfe hie AI.RL Ri	-hfe hie hie + (1+hje)Re  AI.RL -hfe-Rc Nie + (1+hfe)Re  Do

#### Cascaded Amplifier :-

$$\rightarrow A_V = \frac{V_0}{V_1} = \frac{V_0}{V_3} \times \frac{V_3}{V_2} \times \frac{V_2}{V_1} = A_{V_3} \cdot A_{V_2} \cdot A_{V_1}$$

\* " 5/p is delivering voltage, then last stage should be common collection of the common base current."

\* All the infermediate stages should be common emitter config.

\* CC is used in first & last stage due to high Ri & low Ro respec

\* CB " " " wow R; 2 high Ro

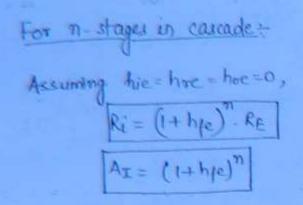
### Darlington Pair (cc-cc) :-

### Riz & (1+hje) RE

$$Av_2 = \frac{Ar_2 \cdot R_L}{Rr_2} \Rightarrow Av_2 \cdot a \leq 1.$$

### Overall current gain-

$$A_{T} = \frac{\underline{I_o}}{\underline{I_{b_1}}} = \frac{\underline{I_o}}{\underline{I_{b_2}}} \times \frac{\underline{I_{b_2}}}{\underline{I_{b_1}}}$$





Advantage Very high current gain Darlington integrated transactor fairs are commercially available with his as high as 30,000, thoefore this is also called super p transactor.

- Very large if resistance.

Disadvantage:

- Highly expensive circuit.

- leakage current of first transister is amplified by second, hence the operall leakage current may be high and darlington connection of 3 or more transister is usually impractical.

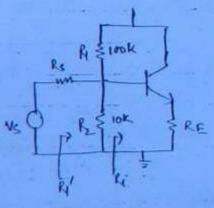
Biasing Problem :-.

for cc -

Rishie + (H He) RE

fet hie=1k, he=99, le=2k

7 Ric 200k.

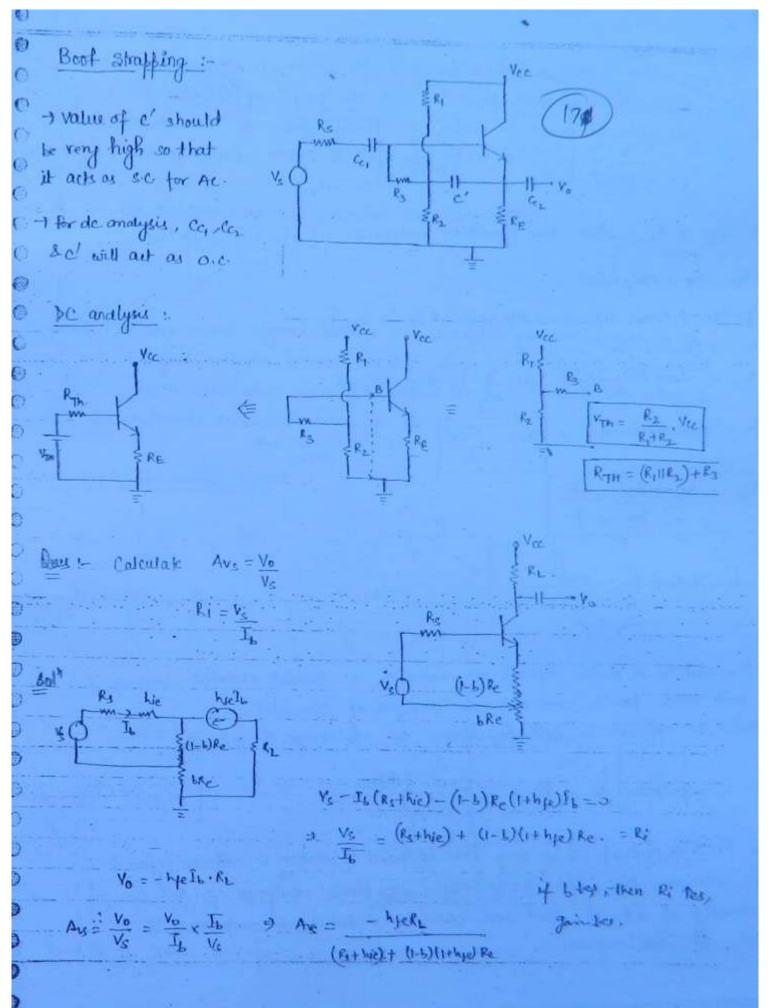


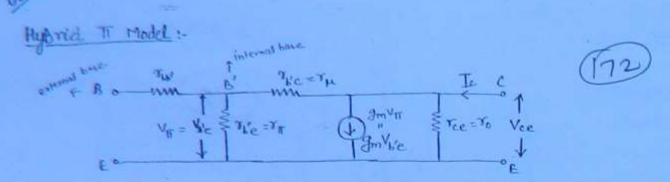
How the Ri = RillR, IIR, and Resultant Ri' < lok. But we need Ri' to be high so that whole is is transferred to i/p.

From it a dontingform four is attached with Ri = 2.5 MJZ, then also - Ril Klok. This is called biasing problem.

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-> The or The ohmic base spreading resistance (small A, Rt for base).

-> m Vye => shows dependence of Ic on VIB (or VBE).

- The - shows early effect for Je junction - high.

$$\frac{1}{\sqrt{2}m} = \frac{1}{\sqrt{2}m} = \frac{1}{\sqrt{2}m}$$
;  $V_T = \frac{1}{11600} \text{ Volt}$ 

$$\frac{1}{\sqrt{2}m} = \frac{1}{\sqrt{2}m} = \frac{1}{\sqrt{2}m}$$

- ⇒ gm and m in model depends on value of dc quiscint current ica and hence provide more accurate analysis of transistor.
- Model is applicable to both prop & non to who change of polarities.
- Tr. is represented as a vccs.
- \*\* Base region of Tr. is very thin companed to emiller & collector region of the resistance lies How 40-to 400s. The ohmic resistance of E&C is usually of order of 10se and can be reglected in companison to that of base region.

TIT - Incremental resistance of E-B disde which is FB in active regis

if It accounts for feedback from off to iff, due to bace width modulation or early effect. The value of The is usually very

high (several MSL) and will be neglected in analysis.

$$T_0 = \frac{V_A}{|I_{CQ}|}$$

- gmVT - any small signal voltage Vr at emitter junction results in a signal collector current grown when Voe = 0. BIT is represented as a vecs when committed current is gon VIT & controlling voltage is VII. Im represents transconductorice of Tr.

### Simplified/Approximate Model :-

$$g_{m} = \frac{h_{fe}}{g_{m}} s \cdot \frac{\beta}{g_{m}}$$

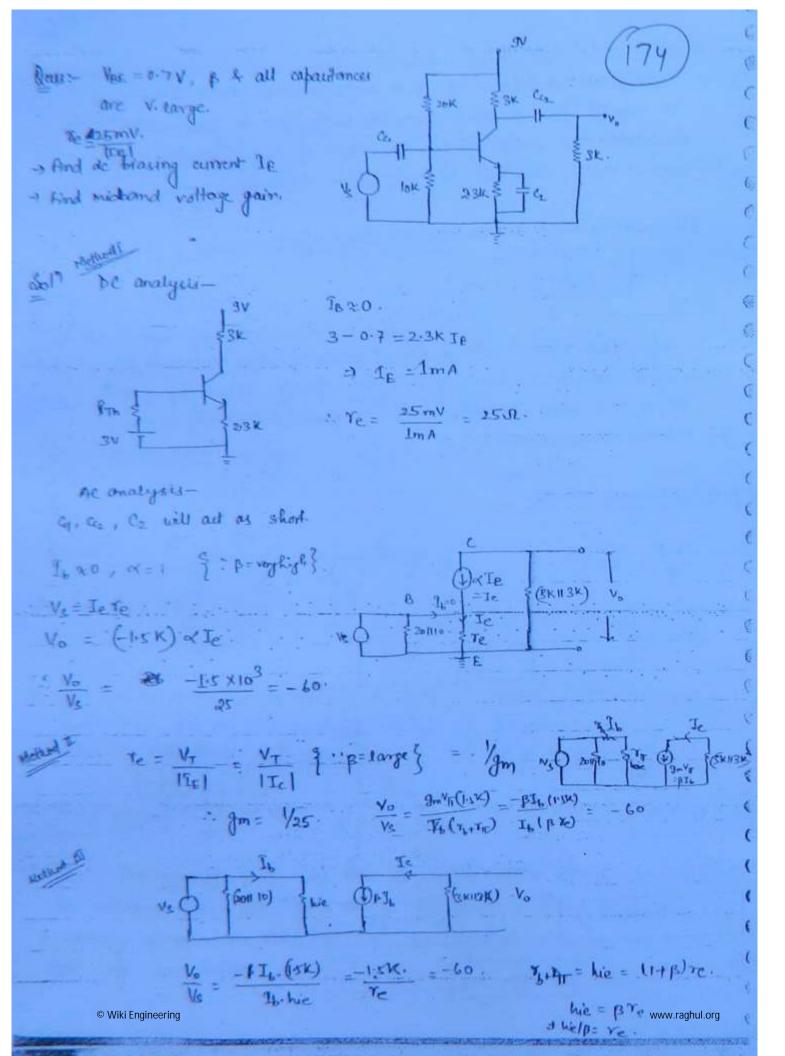
$$R_{i} = \frac{\sqrt{be}}{I_{b}} = \frac{\gamma_{b} + \gamma_{ii}}{I_{b}}$$

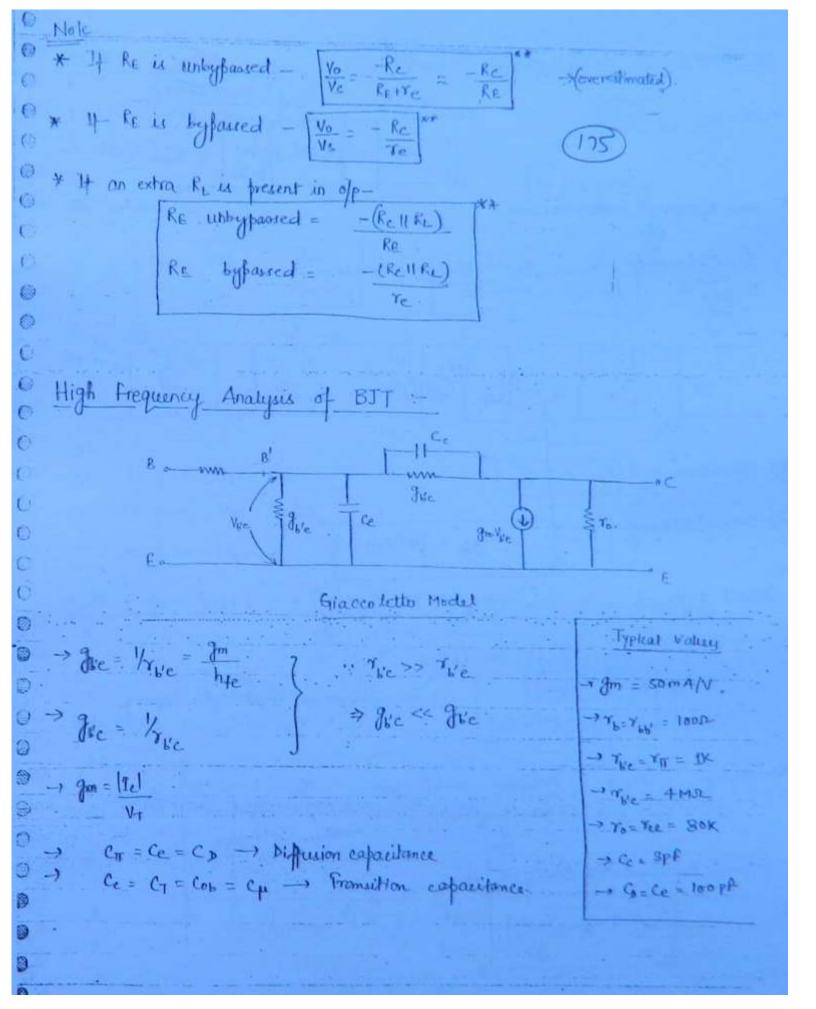
#### Te of T- Model :

$$\frac{V_{be}}{I_b} = \frac{R_1 = (1+\beta)r_e}{I}$$

$$\gamma_b \ll \gamma_{tt}$$
 ,  $\beta >> 1$ 

$$\gamma_b \ll \gamma_{tt}$$
,  $\beta >> 1$ .  $\gamma_{tt} = \beta \gamma_e = hie$ .

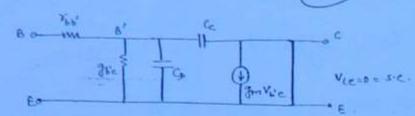






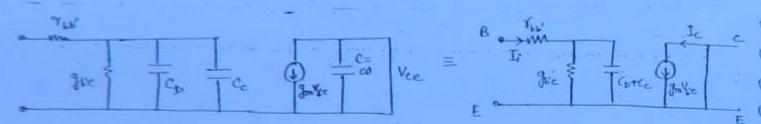


$$\Rightarrow A_{v} = \frac{V_{ce}}{V_{k} t_{e}} = 0.$$



Now applying Miller's theorem -

$$C_1 = C_C (1-Av) = C_C$$
;  $C_2 = \frac{C_C (Av-1)}{Av} = 00 (short)$ 



i/p conductonce = 
$$Y_i = \frac{I_i}{V_{ke}} = g_{be} + j\omega(c_b + c_e)^{At}$$
.

Cornert gain 
$$=$$

$$A_{1} = \frac{I_{0}}{I_{1}} = \frac{-g_{m} V_{He}}{V_{Le} Y_{1}} \rightarrow A_{1} = \frac{-g_{m}}{Y_{1}}$$

Remaining, 
$$A_{I} = \frac{-g_m/g_{se}}{1+j\omega}$$
, Moso " Ye =  $\frac{1}{g_{se}} = \frac{h_{fe}}{g_{m}}$ 

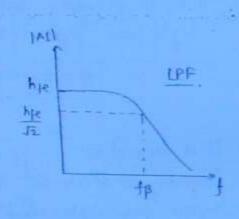
$$\frac{1+j\omega}{g_{se}} = \frac{h_{fe}}{g_{se}} = \frac{h_{fe}}{g_{m}}$$

On solving . -

$$\omega_{\beta} = 2\pi f_{\beta} = \frac{g_{b'e}}{c_{b+c_{e}}}$$

or 
$$\int \beta = \frac{1}{2\pi \tau_{ge} \cdot (c_b + c_e)}$$

$$A_{I} = \frac{-h_{fe}}{1+j(\omega/\omega_{p})} = \frac{-h_{fe}}{1+j(f/p)}$$



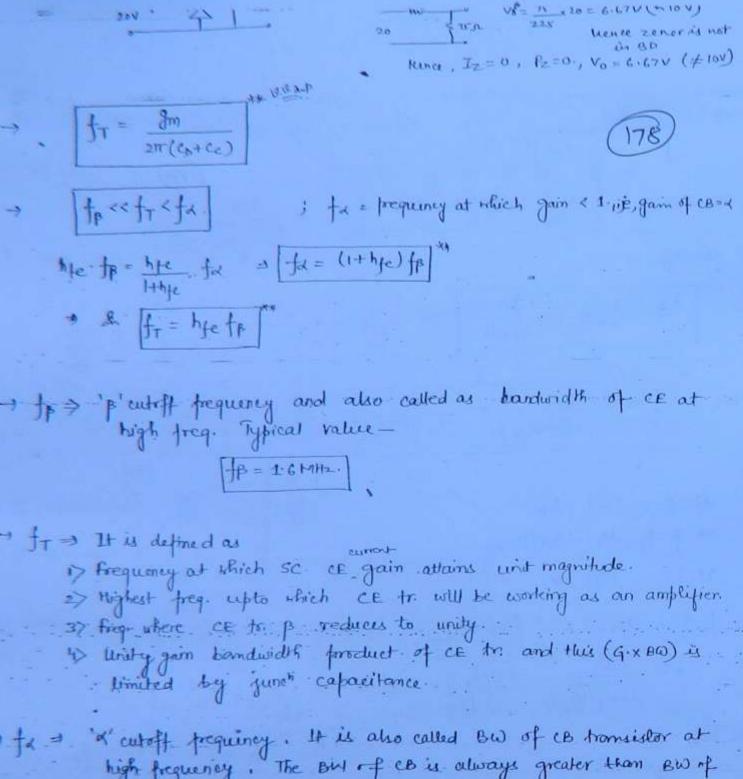
$$= -\left(\frac{f_1}{f_B}\right)^2 = h_f^2 - 1$$

Bode Plot :

$$gxBw = constant$$
  
 $gxhx \cdot fp = A \cdot fi = Az \cdot fz = f_T = a' \cdot fx$ 

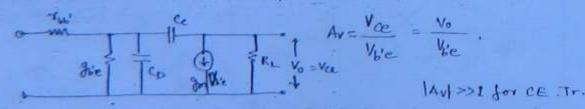
IT = wity gain bandwidth products

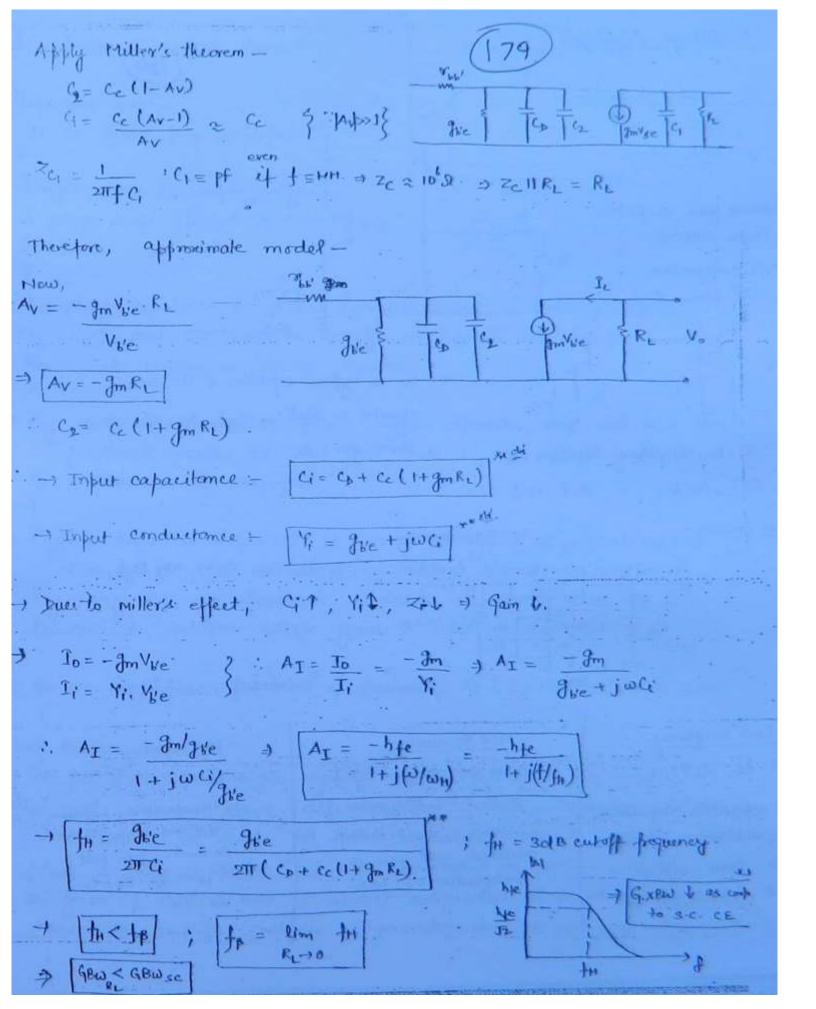
1



to = " cutoff prequincy. It is also called BW of CB tromsister at high frequency. The BN of CB is always greater than BW of CE or BW. of CC. to

Common Emitter with Resistive load







1) Single stage -

-Audio freq. amplifier (20Hz - 20KHz).

→ CE configuration, ic, 180° phase shift

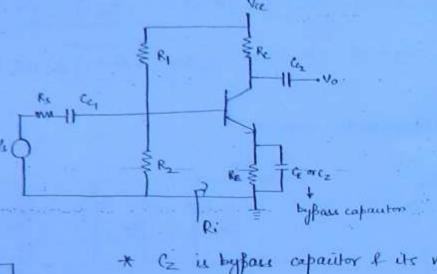
- Karana

Ri= hie + li+p) RE R

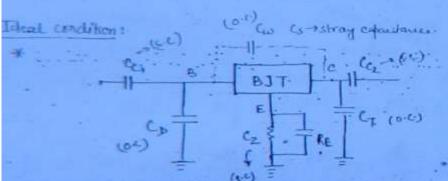
RIT, AV J

e Jc2

Ri= We+ KA



\* Cz is byfass capacitor of its value should be high so that its will act as short for AC.



Co, Co - 10-14 f.

Ze = 1/211fc

Low Frequency

At fl. Zel.

All capacitive impolancy

as, and they will act as

O.C. Gain will of

Lee to Cy, Co. & Cz.

Mid frequency

Ze is not decided by f,

decided by the value of

C'. Hence, ideal condh

achieved and gain is

independent of freq.

High Frequency.

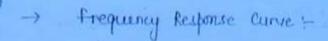
All of 1, Et,

All apacitive Impedome

on and they will act
as short. Jain will

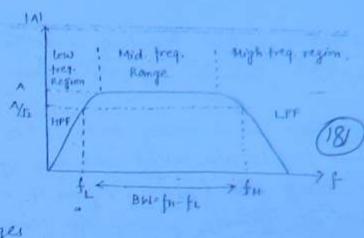
by due to Co, Co,

Co, Co.



Important Print -

- > It is audio freq amplifier.
- -> Single stage RC couple introduce a phase shift of 180° 2 two stages introduce 360° or 0°.



- Coupling capacitors (48 Ca) aire also called de blocking capacitors. (48 Cb) and are used to couple ac signals and simultaneously block de current or biasing current.
- Thy using emitter resistor, who a byfase capacitor, there will be a -ue feedback across RE. and this reduces the voltage gain and to if resistance of amplifier.
- through it for do current or brasing current, Gis open.

  By using Cz, we freedback (dur to ac signal) across Re is eliminated, therefore voltage gain 1 and if resistance to
- -) In an amplifier, for better performance, Relection is used.

freq. Response Curve +

- The fall of gain in low freq. region is due to effect of co, co and ca.

- On mid frequency segim, all soupling & byfass capacitor will be treated as ac short. All june" capacitors (c, 24), cutring capacitor (Cw) & stray capacitor (Cs) will be breated as open.

. The gain of amp is more & almost independent of fact mid-page and hence the amplifier analysis is generally done at mid page range.

- ) The fall of gain at high freq is due to the effect of jumps capacitor (4,4) & Cw. Cs. and early effect.
- High freq. fall is mainly due to CDRCc.
- cutoff freq is also called 3dB freq, or half power freq.
- At cutoff freq. (front), gain of omp reduces to 70.7.1. of peak value, ive, |Amil/52. and ofp power of omplifier is reduces to 50.1. I peak value.
- -) At cutoff frequency, the relative gain of amp is reduced by 3dB

### Sondwidth :-

- It is the bound of if signal forguencies where the gain of amp is abmost
- -> BW= fH-fy
- larger BW indicates better reproduction of its signal ...
- In an amplifier, gain bondwidth foroduct is always constant, ie when one Tes, other by I vice versa.

Fleadrantage: Smaller gain x BW.

- Forplifiers are connected in carcade to get larger gamx ow products

Cabulation of fi -



-> fe due to Cc, 1. Assume Ce & c2 - 00 & act as sec

- He can replace transistor with its input recistance

$$C \rightarrow R_1'' = h_1'' = \beta v_e = \gamma_m + \gamma_b$$
.

$$V_{S} = \begin{bmatrix} R_{S} & R_{S} & C_{c} \\ W_{i} & R_{i} \end{bmatrix} = \begin{bmatrix} R_{S} & C_{c} \\ W_{i} & R_{i} \end{bmatrix}$$

3 7 Ri'= Ri 11 R2 11 Ri ≈ Ri

to as high an possible. (Rs should not be high as it will I poss

-> fe due to Co :- Assume Cod Co - on . & asks as se

\* It to due to eq & cer is different then take the bigger value.

\* If for due to coules or couler ... " " smaller value

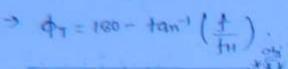
Low frequency Analysis

-> RC coupled acts as HPF for low peg.

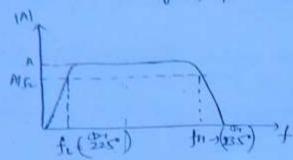
High freq analysis :-

184

- A = 1 1+j(1/h) : Re completed amplifier ack as LPF at high page







# Cascaded Amplifier/ Multistage Amplifier :

) Amplifiers are empected in caucade to get larger gain x ero.

-> When amplifiers are connected such that off of one is given to if to the . Then, they are said to be carcaded.

in this stages so that -

1) of pail not be distorted

2) Max power will be tromsfored from one to another slage.

If microstch is more in amplifier, of will be highly distorted.

Different types of coupling-

) Re coupling - for vottage amplified

1) Francismer coupling - (for power amplifiers)

m) direct coupled -> ( basically used for de amplification).

- In a multidage amplifier, GXBW = constant.

the multidage aup, BW reduces.

Bardwidth of Multistage Amplifier:

6

0

0

lase - m-identical non-interacting (proper impedance matching) stages in case 0

Derivation of fit -

for m-such stages, 
$$1A^*1 = \left[\frac{1}{\sqrt{1+\left(\frac{1}{2}/\frac{1}{2}n\right)^2}}\right]^{n}$$

$$0 \to A+ f = f_{H}^{\dagger}, |A'| = |f_{\overline{L}}| \Rightarrow \frac{1}{\sqrt{2}} = \left[ \frac{1}{1 + (f_{H}^{\dagger}/f_{H}^{\bullet})^{2}} \right]^{m/2}$$

0 Derivation of fr 1-

$$\rightarrow AL f = fc^*$$
,  $|A^*| = V_{f_2} \Rightarrow \frac{1}{\sqrt{12}} = \left[\frac{1}{1+\left(\frac{f_1}{f_1^*}\right)^2}\right]^{n_1}$ 

Case - non-identical interacting (ie, no proper impedance matching).

$$\frac{1}{f_{H_1}^{*}} = \frac{1.1 \times \sqrt{\frac{1}{f_{H_1}^2} + \frac{1}{f_{H_2}^2} + \dots + \frac{1}{f_{H_n}^2}}}{\frac{1}{f_{H_1}^2} + \frac{1}{f_{H_2}^2} + \dots + \frac{1}{f_{H_n}^2}}$$

-> BW +

 $\int_{L}^{*} = 1.1 \times \int_{L_{1}}^{2} + \int_{L_{1}}^{2} + \dots + \int_{L_{n}}^{2}$ 

→ Rise time T (due to multistage .: (Slow response)

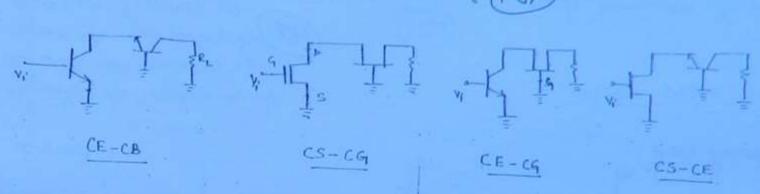
-> Rise time, tr= 11 x J tr2+ tr2+ --+trn2

The fise time of signal 
$$\int tr^2 = h_1 \times \int tr_0^2 + ts_1^2 + h_2^2 + \cdots + h_n^2$$

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Cascode Amblifier .. "



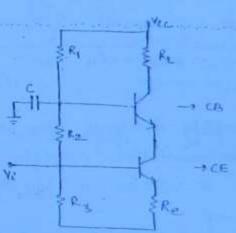
-> These all are series connections.

# Basic Diagrams

→ C→ Bypase capacitor; its value should be very low so that it

charges quickly.

? Purpose of this 'c' is to maintain CB in active region.



Transconductance

$$g_{m_1} = \frac{T_{\sigma_1}}{V_S}$$

Bess for CB, Az = 1, it acts as

buffer for amount.

$$\therefore g_m = \frac{I_0}{V_S} = \frac{\sqrt{I_{01}}}{V_g} \Rightarrow \left[ \frac{g_m = \frac{\beta}{I + \beta}}{g_m} \cdot g_m \right] - (\text{exact}) \quad g_m \approx g_m$$

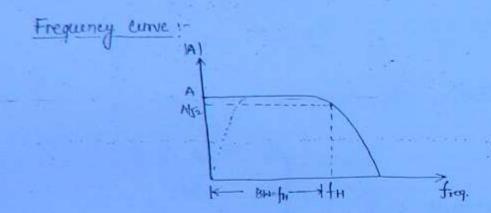
$$\downarrow \beta = |a_m|$$

Imp Prints :

It is specially designed multistage amplifier the type of coupling provider is direct coupled, therefore suitable to amplify as I do signal but major application is as a high frequentities.

- The if resistance is equal to up resistance CE & of resistance is decided by off resistance of CB.

# Direct coupled Amplifier:



- It is suitable to amplify de signal along with a widebond of Al signals.

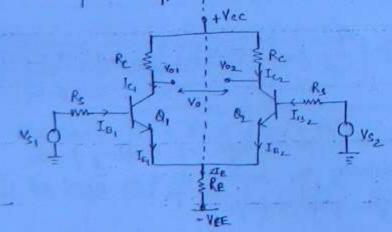
- widely used as instrumentation amplifier.

There is no proper de infation in b/w the stages, therefore stability is loss. I direct complete

Any De amplifier suffer from drift forblem. Drift forblem is mainly due to Ico. I gain of or op of amp drift with temp of Ico changes &

- Popularly used direct coupled amp is emiller coupled differential amp. .

### Emilter coupled Differential Amplifier:



yo=Yo1-Yo2 - Balanced ofp

(a), a are almost identical)

Mode of operation-1) Dual 4p balanced ofp. 2) Dual if p unbalanced of 3> Single if p balanced ofp. 47 Single if unbalanced ofp. DC Analysis: -0 -> 1/51 = 1/52 = 0 Applying KVL. TE. 0 - (because of feedback) E2RE IBR + VOE + (1+p) IB1 2RE - VEE = 0 . - (1) (potential, should be equal to 21 ERE 0 - VEE but IE, carnet be doubled , home V = 1c, Rc + VcE + (1+β)18, 2RE - VEE . - 2 Testistomes in doubled) 0 1 = B Is, -3 O New, if VCE > 0.2, transister is in active region. O AC malyris - VEE = Vec = 0. , Ky 165-16. 0 - A- common mode galn. - Ad differential "\_\_\_ ٥ Now; For Ac - Vs = Vs = Vs 2RE 1 V2 = V5, - V62 = 0 - > V0 = AcVs YEE = O . Ve= V5+V62 = Vs. = 1 Ac = Vo 0 Cammin emitter with emiller resultance The 9 From circuit, AI = - he , Ris hie + (Hphy (2RE) 0 D  $A_{VS} = \frac{V_o}{V_S} = \frac{A_L R_L}{R_c + R_c^2}$  =)  $A_c = \frac{-h_f e \cdot R_c}{h_{con} \cdot l_{con}}$ D hie+ (1+h/e) 28= 0

Approximate value, Ac = -Rc -> when he >>1.

-Ideally , Ac=0 , > Re - w. (Possible with current mirrorakt),

- AS RET, AC V.

for Al- Xx Vs2 = -Vs/2 ., Vs1 = Vs/2

: Va= Vs ; Vc = 0.

At = Vo

fro Ago

M=- he, Ri = hie

2 2-Ad = - hye. Rc

> Ad = -hee Re \_\_\_\_ (Is dies not depends on RE) 2 (Re+ hie)

Ve . O PRE > Mence, Re com be remercal or

Now, dividing the ext.

MRR = Rethie + [1+hfe] 2RE 2 [Rethie]

if (4thge) 2Re >> Rethie , then

OMRR = [1+hje] - RE Rethie

(As RE -100, CHRR -100) (Ideal value)

Effect of increasing RE :-

\* gm= |Iel = as RET, VENT - tentback

Disputive kedback across RE Tes.

I A des, OARR Tes, got , gaint } igain of gong 8> RT

- It is used as the first internal stage in op-amp.

- As an instrumentation amb.

- As a very good clipper

- As a linear amplifier, i.e., we can apply superposition theorem.

- It is used in designing of AVC (Automatic voltage control) or AGC (auto-

gain control).

- Any w

\* Any ideal diff. amplifier can be designed by connecting an ideal surrent source in place of RE.

Archive DIE

Ideal source - co = RE
Ac = 0

CHER - D

Practically le= Very high very low very high.

In a practical diff. amplifier, active load is connected to get best performance In place of passive load he; pup transmitter is used to get maximum teak to beak of voltage or maximum swing.

3 100 Re- Passive

Ideal swing = Yec

Prac swing = Vec-Icook - Vesat

a Ideal to Practically

Vi>>0 Saturation O Yes sat

Viceo cutoff Vec Vec- IceoRe

W - Zue Co. I View

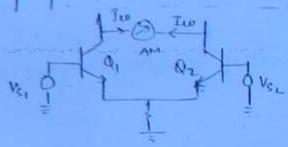
 $V_1 \otimes_1 \otimes_2 R_{02} = V_0 | R_{01}$   $V_1 >> 0$  on off  $\cong G$  Vessat

vicco off on 20 2 Vec

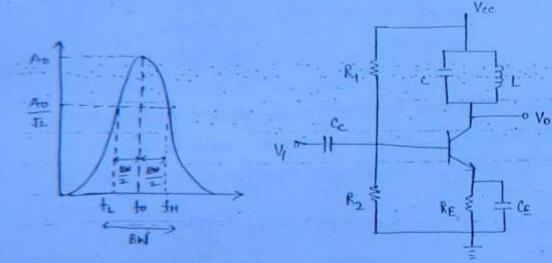
awing 1 - I less is still present

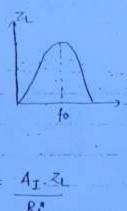
> Differential amplifier is often used in de application. It is difficult to design de amplifier using Tr. because of drift due to variations of type, Vox & Icao with temp.

A with of and of having almost identical characteristic, any parameter charges due to temp will cancelled out and ofp will not vary. For eg., leakage unrent of of leakage unrent of of leakage are equal in magnitude but flowing in offsite direction into ammeter of they get cancelled, and hence drift problem is eliminated in emiller empted diff. amp.



Tuned Amplifier (class c amplifiers):





Ri

ZL - LC tomk circuit

To change the BW, a should be changed and not for as changing for well change the centre frequency.

(93)

-> It is also called tuned voltage amplifier.

- Typ signal freq. range - 30KHz to 300KHz. (RF band, hence also called RF amplifier)

-) Working frinciple is parallel resonance.

Ability of amplifier to reject unwanted frequencies is called seketinity of the ability to select a particular station signal for amplification by rejecting all other unwanted station signals, i.e., selectivity is very high.

-) front end selectivity of receiver is done by RF amplifier, therefore tuned amplifier is first stage in superhetendyne receiver.

- Tuned amp is class c amplifier and it is a non-linear amp.

or for a tank circuit. A is very longe (100-500).

- But is very small and this is due to -

i> larger Q.

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11) larger gain ( : Bainx BW = constant).

It is also called Harrow Band amplifier.

Disadvantage: Narrow Bri. ( with 1 in quality, But requirement the but with ted Bw, gain lies).

And (Double sheet)

And And I have the sheet of the sheet

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In double timed amplifier, too tank circuits which are tured to rewmant greg are inductively apubled and placed in collector ext.

- BN can be Ted w/b reducing gain of amp, hence gain x BW is not a constant

Advantage: - A larger BW when emponed to a single tuned valage amp.

#### AMPLIFIERS FEEDBACK

$$\rightarrow \bigvee_{V_i} A \longrightarrow_{V_0} A_{0L} = \frac{V_0}{V_i} = A$$

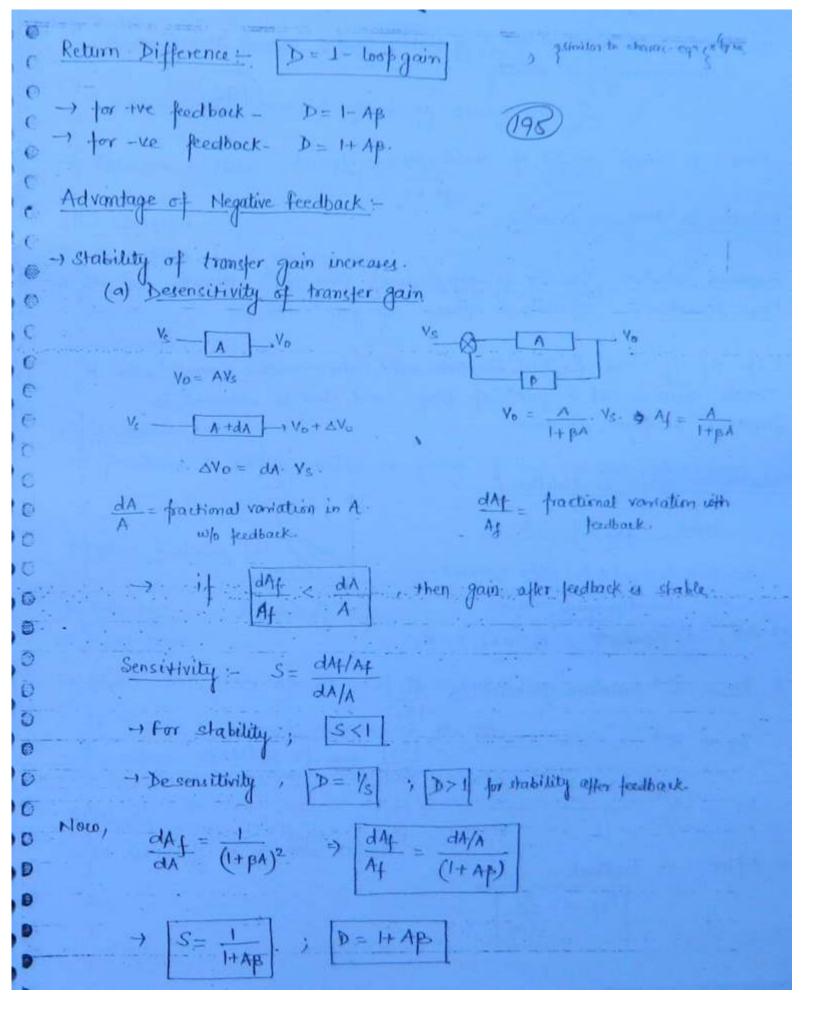
$$\mapsto (R_0)$$

4 feedback factor

H (Regenerative feedback) for the feedback - Af = 1+BA (>A)

For -ve feedback - 
$$Af = \frac{A}{1+\beta A}$$
 (CA)  
(Degenerative FB)  $\frac{A}{1+\beta A}$ 

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Hence, B should consist of stable passive elements.

Reduction in Frequency Distortion:

Frequency Distortion: Variation in magnitude of gain with frequency.

Phase Distortion: Variation in phase of gain with peq.

If Af = 1/B and feedback now closes not embain reactive element, then overall gain is not a funch of preg, and there is reduction in frequency & phase distortion.

### Reduction in non-linear distortion:

No - Bra + By cosw + By co

→ w1, Amplitude +., B1>> B2 >> B3--.

$$\rightarrow$$
  $p_2 = 2^{nd}$  Harmonic Distortion =  $\frac{|B_2|}{|B_1|}$ 

$$D_3 = 3^{rd} - B_3$$

$$D_{4} = 4^{14} - \frac{1}{181}$$

$$D_{2\uparrow} = \frac{D_2}{1+Ap} \bigg|_{1+Ap} = \frac{1}{1+Ap} \bigg|_{1+Ap} = \frac{1}{1+Ap$$

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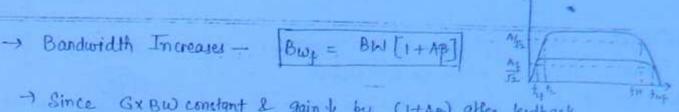
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Note:- Guys Be Cool Dude I am here for help You ©

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- Since GXBW constant & gain to by (1+Ap) after feedback.
- → Reduction in Noise :-Nof = No

other advantages -

- > It modifies i/p & o/p resistance.
- -) It Tes thermal stability & freq. stability of ofp signal.

Disadvontage -- It reduces gain

Application -- we feedback is widely used in designing of amp-ckt and embot system.

### Positive feedback :-

- -> Advantage les gain of amp.
- -) Disadratage :-
- -) Reduce BW, hence reproduction of ilp signal is very bad.
- It I noise & harmonic distortion at the off.
- It reduces stability of amp.

Application - In designing of oscillator consults. Que An amplifier w/o feedback gives a fundamental ofp of 36V with 7%.

and harmonic distortion when i/p is 0.028V. (198)

a) It 1-2-1 of ofp is feedback into itp in a -ve voltage series feedback ett, what is ofp voltage.

b) 4 fundamental of is maintained at 36V, but the 2nd harmonic distortion is reduced to 1%, what is if p voltage.

$$\frac{A_1}{V_5} = \frac{A}{I + A_1^A}$$

$$D_{2f} = \frac{J_2}{1+Ap} - \frac{V_4 \times J_7}{1+Ap} - \frac{V_6 \times J_7}{1+Ap} - \frac{J_2}{1+Ap} - \frac{J_2}{1+Ap}$$

$$\frac{1}{1+Ap} = \frac{A}{7} \qquad \frac{V_{s_1}}{V_{s_1}} = \frac{A}{A_f} \Rightarrow V_{s_2} = 7 \times 0.028 = 0.19 \text{ 6V Aus}$$

$$\frac{V_{s_2}}{V_{s_1}} = \frac{A}{A_f} \Rightarrow V_{s_2} = 7 \times 0.028 = 0.19 \text{ 6V Aus}$$

6

8

C

C

0

0

Ö

dus: An amp with open wob voltage gain of 1000 delivers 1000 of ofp power at 10%. 2nd harmonic distortion, when ifp is 10 mv. If 40 dB -ve voltage series feedback is applied and ofp power It to remain at IOW, determine

- (a) Required i/p signal.
- (b) 1. harmonic distortion.

$$\begin{array}{ccc} & & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & \\ & & & \\$$

$$\frac{1}{100} = \frac{10}{1+48} = \frac{10}{100} = \frac{0.11}{100}$$

$$\frac{1}{2} \rightarrow \frac{V_1'}{1} = \frac{1000}{10} \frac{V_1}{1} = 100 \times 10 \text{ mV} = 1 \text{ V}$$

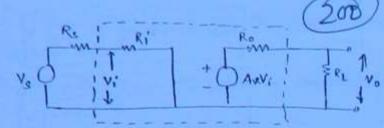
# Classification of Amplifiers -

D

0

# Voltage Amplifiers :-

- Riss Rs, Ri= 00 (ideally)
- Ro <= RL, Ro=0 ( ideally).



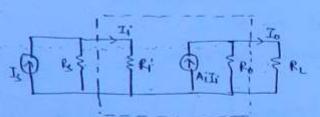
- Av - internal gain, Av - external gain.

$$\rightarrow V_0 = \frac{A*V_i \cdot R_L}{R_0 + R_L} \Rightarrow A_V = \frac{A_V \cdot R_L}{R_0 + R_L}$$

When RL = 0, external gain = whermal gai

# Correct Amplifier:

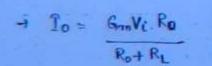
- -> Ri << Rs, fie, Ri=0 (ideally)
  so that whose current powers through hi
- so that max current is delivered to load.
- AI = ext. gain, Ai = internal gain.



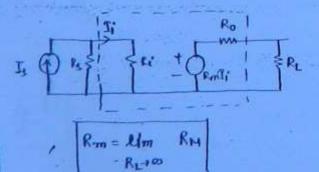
$$A_{I} = \frac{I_{o}}{I_{i}} = \frac{A_{i} R_{o}}{R_{o} + R_{L}}$$

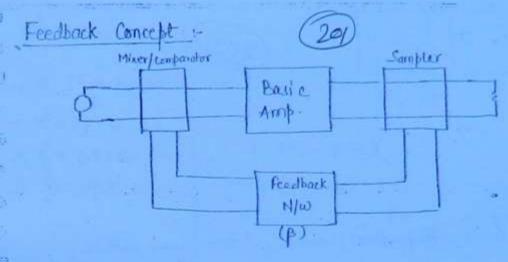
$$A_{L}^{\circ} = \lim_{R_{1} \to 0} A_{I}$$

#### Fransconductance !-



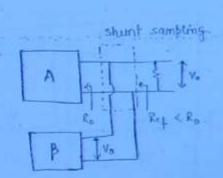
### Trans resistance :



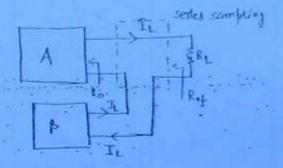


Sambler :-

- a) Voltage Sampler:
- sampled voltage in feedback is same as ofp voltage.
- → Rof < Ro

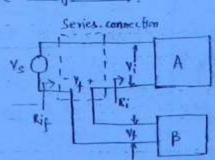


- (b) Current Sampler:
- -> Rof > Ro.
- is sampled current in feedback is some as of current.



Mixer :-

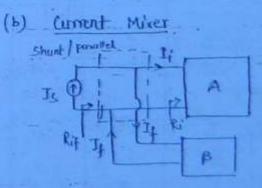
(a) Vollage Mixer



Pelare mixing Vi=Vs

Ni=Vs-Yj

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Rif < Ri, Before wixing > Ii=Is

After - -> Ii=Is-

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### Feedback Topology:



- 1) Voltage Series feedback.
- 27 Current Series "
- 37 Vollage Shunt "
- 4) Current Shunt "

Derivation of Rif (input resistance with feedback) and Rof (of presistance with FB) for Voltage Series feedback:

$$\beta = \frac{V_{+}}{V_{0}} = \text{unities}$$

$$A_{\overline{J}} = \frac{Av}{1+\beta Av} = \frac{1}{\beta} \cdot \left\{ \beta Av >> 1 \right\}$$

-> Rof < Ro & Rif > Ri

Cakulation of Rif -

Before feedback

Vi=Ys

$$\frac{i/p}{I_i}$$
 resistance =  $\frac{V_s}{I_i} = \frac{V_i}{I_i} = R_i$ 

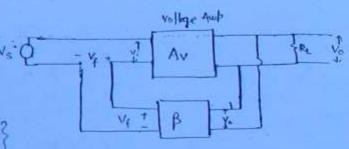
After feedback 1-

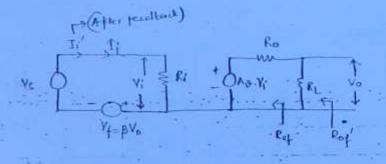
(There is -ve feedback).

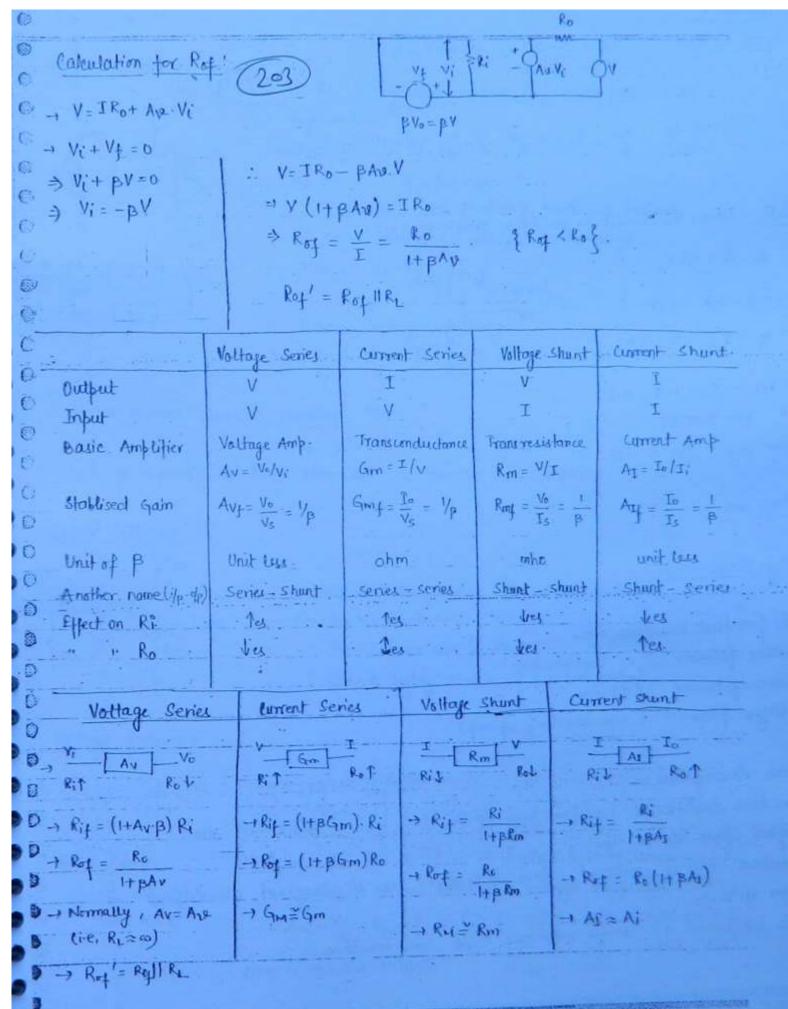
i/p resistance = Rij = Vs

Applying kvi -

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Merkbert

$$I_B = \frac{5 - 0.7}{10^3 \text{ k.s.}} = 4.3 \times 10^{-3} \text{ m A}$$

204)

$$\frac{V_8 - 12}{2K} + \frac{V_0}{4} + \frac{7}{4} = 0 \quad \Rightarrow \quad \frac{V_0}{2} + \frac{V_0}{4} - 6 + 0 \cdot 43 = 0$$

Q-17 Since, the circuit is amplifier, then VCE >0.2.

10950,2012

Vollage Series Fredback -

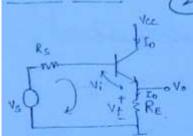
Best practical examples are-

- emiller follower (cc configuration)
- cource follower (corain ...)
- voltage follower ( Non-inverting of amp)

-> Basic Assumptions -

- The basic amplifier is unilateral from i/p to ofp, i.e. it does not allow signal from ofp to i/p.
- Fredback now is unidatoral, from off to ity. , ie., it does not allow signal para if to off
- PLO Wiki Engineering 1 of source regularce Rs & Load resultance RL. www.raghul.org

Emiller Follower:

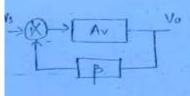


Let Re is very small, hence drop across Rs can be neglected.

hlithaut fb: (or w/o RE) > Vi = Vs.

with fb :- Vi=Vs-Vf

- Since Vit with feedback, hence -ve feedback & series many ( voltage is changing).



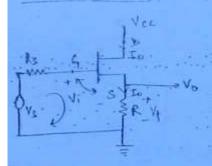
I there is voltage sampling.

 $A_{H} = \frac{V_{0}}{V_{c}} = \frac{V_{0}}{R} = 1$ ;  $\phi = 0$ .

-) If we assume current compling, then

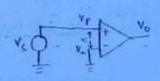
$$V_f = \beta T_0 \Rightarrow \beta = \frac{V_f}{T_0} = \frac{\bar{I}_0 R_E}{T_0} = R_E.$$
 but  $\beta$  defends on  $R_E$ , hence not a current  $T_0$  campling.

Source follower:



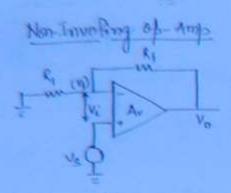
- Results will be similar to Emilky follower
- for both-circuits :-
  - There is max we feedback
  - Gain is highly stable (: p is independent)

Voltage follower:



w/o feedback

with FB Vi = Vs - Vf => Vit , - ve feedback & series miler. Vy = Vo. > p=1 1 there is voltage sampling.



Vi= Vs-Vf > -ve feedback, valtage mixing companion

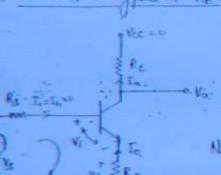
$$V_f = \frac{R_1}{R_1 + R_f}$$
.  $V_0 \Rightarrow V_f = \beta V_0$ .  $\Rightarrow$  voltage sampling.

B is constant (- Right ore neither source occulonce, wor Local resultance) .

$$\rightarrow$$
  $Av_j = \frac{1}{R} = \left(1 + \frac{R_f}{R_1}\right) - \left(a_f + \frac{1}{R_1}\right)$ 

### Current Series Redback :-

(1) CE with unbyfasted RE :-



let drop across Re = 0 W/O RE - Vi=Vs

.. There is series comparision

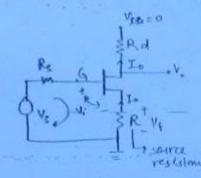
Now, let there is voltage sampling,

$$\Rightarrow Av_f = \frac{V_o}{V_c} = \frac{V_p}{R_c} = -\frac{R_c}{R_c}$$

Re- Re., hence our assumptions are But, : B is dependent on load

Kina , there is current sampling.

Common source with unbypassed source resistance :-



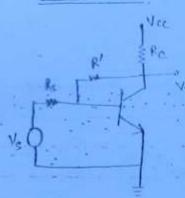
$$\beta = -R$$

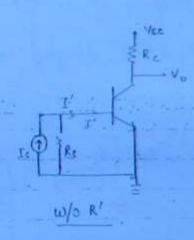
$$GM_{J} = -\frac{1}{R}$$

$$Av_{f} = -\frac{Rd}{R}$$

Vollage Shunt Feedback :-

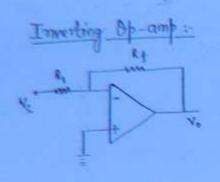
(a) Collector Blaz circuit :-

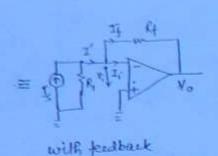


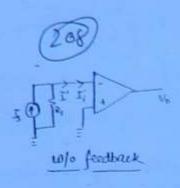


a - polo feedback, I:= I'

$$R_{Hy} = \frac{V_0}{I_s} \Rightarrow \begin{bmatrix} R_{Hy} = -R' \\ \\ R_{S} \end{bmatrix} = \frac{V_0}{I_s R_s} \Rightarrow \begin{bmatrix} A_{Yy} = R' \\ \\ R_s \end{bmatrix} = \frac{V \cdot V_0}{V_0}$$







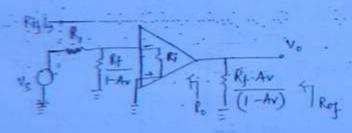
who feedback: 
$$T_i = I' - T_f$$
 => shunt origing comparison

$$\rightarrow I_{f} = \frac{V_{i} - V_{o}}{R_{f}} \Rightarrow I_{f} = -\frac{V_{o}}{R_{f}} \Rightarrow \boxed{\beta = \cancel{R} R_{f}} - (m_{f})$$

$$\rightarrow R_{Mf} = \frac{V_0}{R_f} = \frac{Av_f}{R_f} = Av_f = \frac{V_0}{V_S} = \frac{V_0}{T_S R_S} = Av_f = \frac{R_f}{R_1}$$

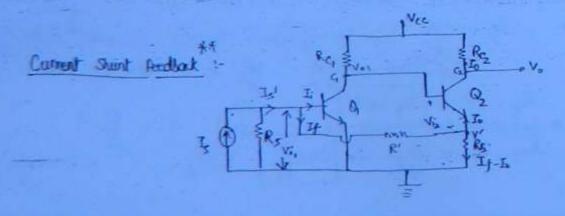
$$\Rightarrow R_{Mf} = -R_f = \frac{V_0}{T_S}$$

To calculate Rig & Roy, applying minters thewsem-



$$Rif = R_1 + \left(\frac{Rf}{1-Av} \parallel Ri\right)$$
of 
$$\frac{Rf}{1-Av} \approx 0 \quad \{ (A) >> 1 \}$$

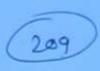
=) Rif = R1 thence Reduced ifp resistance



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w/o feedback > Ii= I's

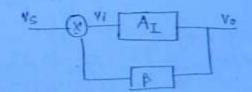
with feedback + I'= Is'- If - shunt waiting comparison-

Now,  $Av_1 = \frac{V_{01}}{V_1^2} \implies 1 \implies V_{01} \implies V_1$  ? CE configuration ?.

How, V' = Vot - Vi2 ≈ Vot ? ? " Vi2 << Vot, Vi2 = small signal }.

$$\rightarrow \hat{I}_{+} = \frac{V_{i} - V'}{R'} \Rightarrow \hat{I}_{+} = -\frac{V'}{R'} \quad , \text{ but } v' = (\hat{I}_{+} - I_{0})R_{E}.$$

$$\Rightarrow 1_{\frac{1}{2}} = \beta I_0 \Rightarrow B = \frac{R_E}{R' + R_E}$$



$$\rightarrow A_{If} = \frac{v_o}{v_s} = \frac{1 + \frac{R^7}{R_E}}{R_E}$$

$$\rightarrow Av_f = \frac{V_0}{V_f} = \frac{\hat{I}_0 \cdot R_{C_2}}{I_3 R_S} \Rightarrow Av_f = \frac{1}{\beta} \cdot \frac{R_{C_2}}{R_S}$$

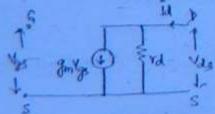
Fransconductonce

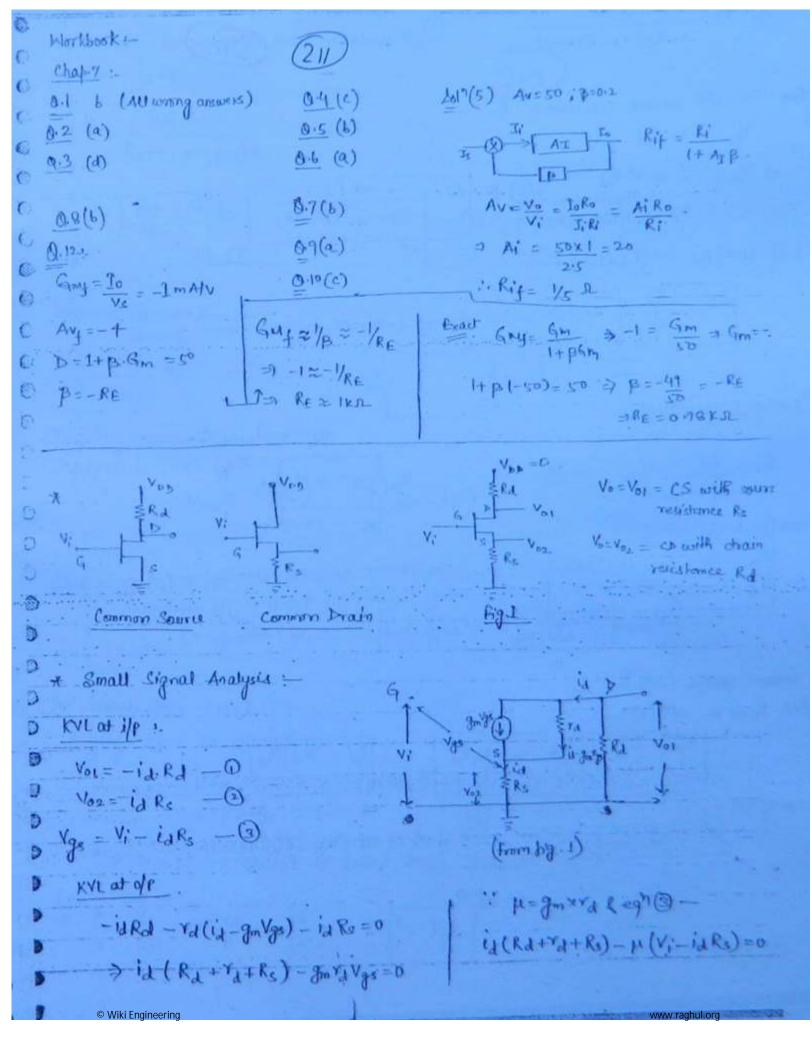
- drain resistance

- 
$$\mu$$
 = amplification factor =>  $\left[\mu = j_m \times r_d\right]$ 

$$\Rightarrow g_{mo} = g_{mo} \left( 1 - \frac{V_{GS}}{V_P} \right) ; g_{mo} = \frac{2 T_{DSS}}{|V_P|} . = g_m \Big|_{V_{gs=0}}$$

Small signal Model :- (at low frequency)





$$\Rightarrow i_A = \frac{\mu \cdot V_i}{R_A + Y_A + (1 + \mu)R_s} - 0$$



for CS with source resistance Rs -Vo1 = - 12-Rd.

$$= \frac{V_{01} = -\mu \cdot V_{i}R_{d}}{R_{d} + r_{d} + (1 + \mu)R_{s}} = \frac{-\mu \cdot R_{d}}{R_{d} + r_{d} + (1 + \mu)R_{s}}; \quad \phi = 180'$$

Thevening equivalent :-

$$V_{o1} = \frac{RA}{R_d + R_{TH}}$$
,  $V_{TH}$  —®

$$= \frac{R_{TH}}{V_{TH}} = \frac{1}{4} + \frac{(\mu \Pi)R_S}{V_{OI}}$$

$$= +\mu V_I^* + \frac{1}{4} + \frac{1}{4}$$

from (5) & (8) =

$$R_{1h} = R_0 = r_d + (\mu + 1) R_s$$

$$V_{7h} = -\mu V_1$$

R<sub>1h</sub> = Ro = r<sub>d</sub> + (μ+1) Rs V<sub>Th</sub> = -μV<sub>1</sub> . Series feedback: (Effect on Up resultance increases due to current ...

- Q is neglected as it is already a) ...

for Common source (w/o hs) = Put Rs=0 in egn (6) -

$$A_{V} = -\frac{g_{m}r_{d}R_{d}}{R_{d}+r_{d}} = -\frac{g_{m}R_{d}}{R_{d}}$$
; 
$$R_{d}' = \frac{R_{d} | r_{d}}{R_{d}+r_{d}}$$

Fram egh (9) - Ro = rd = Kpy

if my is not given , then take it

For Common Drain with drain restatance Rd :-Voz = 10. Rs



$$\Rightarrow Av = \frac{V_{02}}{V_i} \Rightarrow Av = \frac{\mu \cdot R_S}{R_d + Y_d + (\mu + 1)R_c} - D \Rightarrow Av = D$$

Therenin's Equivalent :-

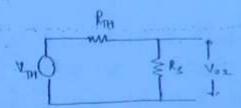
0

D.

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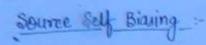
Dividing numerator & denominator

by (p.t) in eqn (12) -  

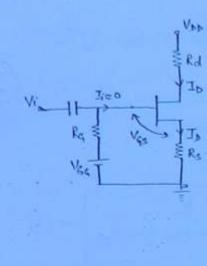
$$V_{02} = \frac{\frac{\mu}{\mu+1}V_{i} \cdot R_{s}}{\frac{R_{d}+Y_{ol}}{(\mu+1)} + R_{s}}$$
 (15)

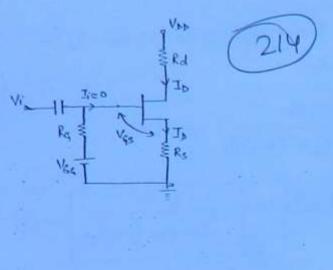
$$V_{TH} = \left(\frac{\mu}{\mu+1}\right) \cdot V_i \quad ; \quad R_{TH} = \frac{R_{d+} \gamma_d}{\mu+1} = R_0 \quad -16$$

$$f_{nom} \cdot eq^{r_1}(16) \longrightarrow R_0 = \frac{r_d}{\mu + 1} \approx \frac{r_d}{\mu} \approx \frac{r_d}{g_m r_d} \Rightarrow R_0 = \frac{1}{4} \frac{1}{g_m}$$



$$V_{GG}=\mathfrak{T}_{i}R_{S}+V_{GS}+\mathfrak{T}_{D}R_{S}$$

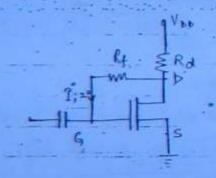




-> Self bias technique cannot be luced to establish an operating point for enhancement type mosfet as voltage aloop across Rs is in a direction to reverse bios the gate and forward gate blas is required for E-MOSFET.

- This is used for JFET or depletion type MOSFET.

Prain-Gate Biasing for Enhancement Type MOSFET :



Workbook (Unap-4)

Quest Voi = -gm Rd', Rd'= rd 11 Rd = 12 11 Rd = Rd 215 =) Pd'= 3KD. · VGG = 0, VgL=-16. Rs  $\int_{M} = \frac{2T_{pes}}{|V_{p}|} \left[ 1 - \frac{V_{Gs}}{V_{p}} \right] = \frac{2 \times 10}{5} \left( 1 - \frac{2 \cdot 5}{5} \right) = 2$ 0 Ay=-2x3=-6 Bury 1 - VG = VGG = - 2 V Durs (a)  $g_{m} = \frac{2 \times 10^{\circ}}{0} \left( 1 - \frac{2}{9} \right) = 300 \text{ mg}. 11875 m S$ Av = - gm Rd1 ; Rd1 = 20K 11 2K Av = -3.41 Quet (b) Av = - gm Rd' = - gm (Rd). talken of for ac analysis, vol = 0, c + short, Ro = 5K115K. 1 Ad= 2x(5115) = 5 Qua 8: (c) R= 2011 100 k 11 00 . Que 9 (d) Av= -80 = -3 = 2.66 (sharkent . Ri' = 16.67 KAL By model Que 10 . Vac = - TD = 10 Danvas uf se vo 1 D = 12 (1+ Vas) D 0 " To not given = 10 = 10 (1+10)2 Vo= -gm Vgs · Rd. (rd:00) - a on solving, Vi = Vgst gm Vgs Rs 1b = 2.26m A.  $Ai = \frac{16}{Vi} = -\frac{9mRd}{1+9mRs} = \frac{-4x6}{1+4x2} = -2.6$  Convertional :-

Assuming FBT is in saturation

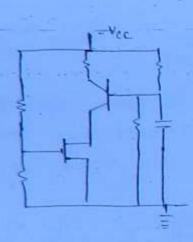
$$T_{bs} = \frac{24-10}{56} = 1/4^{mA}$$

$$T_{bs} = \frac{200(2-(1-\frac{1}{55})^2}{1-(1-\frac{1}{55})^2}$$

$$\frac{1}{1} \left( \frac{1 - \frac{1}{15}}{(-1)} \right)$$

$$= 0.25 = 2 \left( 1 + \frac{1}{15} \right)^2 \Rightarrow \frac{1}{15} = \frac{1}{2\sqrt{2}} = 1$$

Chapter 3:



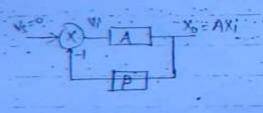
$$g_{m} = \frac{\beta}{1+\beta} \cdot g_{mt}$$

$$= \frac{97}{100} \times 2$$

$$= 1.98 \text{ mMV}$$

1 Set 2012

Oscillators (Sinusoidal)



$$\begin{array}{c|c} x_i & x_0 = Ax_i \\ \hline x_{i'} & A \\ \hline x_{j'} & B \\ \hline x_{j'} & B \\ \hline \end{array}$$

- loop gain = xt' = -AB

Xf'=-BAXi

- 4. finite of p who any its, chet acts as oscillator

- Loop gain = Y = (-Ap) = 1 — Barkhawan Criterian Phase shift  $\phi = 0$ , 360 or 2017.

Now, 
$$A_{\frac{1}{1+A_{\frac{1}{p}}}} = A_{\frac{1}{1-1}}$$
 for system satisfying Bookhawen criteria  $\frac{1}{2\sqrt{2}}$ .

Barkhausen Criterion: It states that

i) Total phase shift around at loop as signal proceeds from its through amplifier, feedback now and back to its again, completing a loop is multiple integral of 211, i.e.,

[ ] = 2nT | ; n = 0,2,2...

2) The magnitude of fonduct of open brok gain of amplifier, A and feedback factor B is unity.

Ap = 1.

Practical Consideration :-

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Practically magnetude of loop gain, ie, IAPI should be kept slightly greater than unity Then amplitude of oscillation is embrilled by onset of non-linearity fresent in system, in other words, in a practical oscillator, loop gain is telf slightly greater than one to overcome the circuits internal losses.

Oscillators:
Describer is basically a waveform generator, used in designing of signal generator and function generators.

- It is also defined as an amplifier with a gain.

1) Gain is finite 27 Hegative feedback 37 Excellent stability of Gain is a.

2) Positive Jeedback.

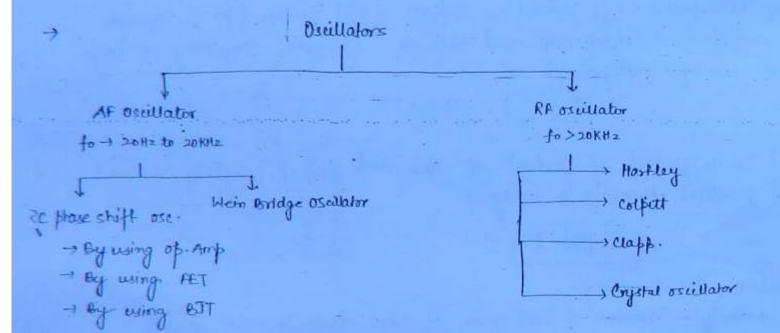
3) less stable.



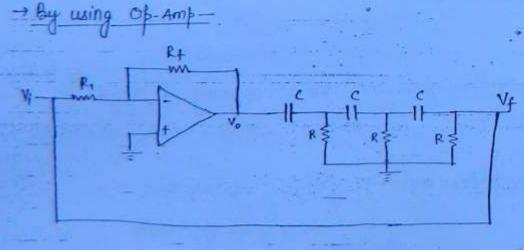
2/p signal will be noise.

Note!

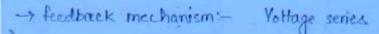
An amplifier can be converted into an oscillator by applying +ve feedback & increasing the gain to as.



## RC Phase Shift oscillator -



→ If Vf=Vi; circuit acts as an oscillator





φ = - tam ( WRC)

-> Preferable as lower values of RRC are registred to mathem higher phase shift.

- To get the overall gain equal to 180°, the phase shift is distributed among all the stages.

In this RC phase shift, three stages are added but the individual phase shift of each stage is not 60°. This is due to loading effect.

Ri, = Ri IIR < R } Hence, phaseshift of Riz = R II Ri, < R. I individual stage will be > 60° in this case and hence, overall of > 180°.

→ To extendate set the overall \$=180°, calculate 1/4 and set imaginary

part equal to 0 and set values of RIC for given we such that

real part = is -ve. In this way, total \$=180° but individual.

\$\phi\$ of stages is not known:

-> We can use buffer in blu the stages to present loading effect but not used due to its complexity:

Voltage follower = Buffer.

> freq. of oscillation +

$$\beta = \frac{1}{10} = x + j \gamma$$
 on butting  $\gamma = 0$ 

- freq of oscillation; 
$$fo = \frac{\omega_0}{211} = \frac{1}{211 \text{ RCJG}}$$



Substituting to in B

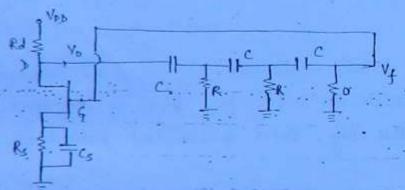
$$\beta = X = -\frac{1}{29}$$

B=X=-1 => -ve real part => 180° phase slift

for inverting 
$$\sigma \beta$$
-amp,  $A = -\frac{R_{+}}{R_{1}}$ 

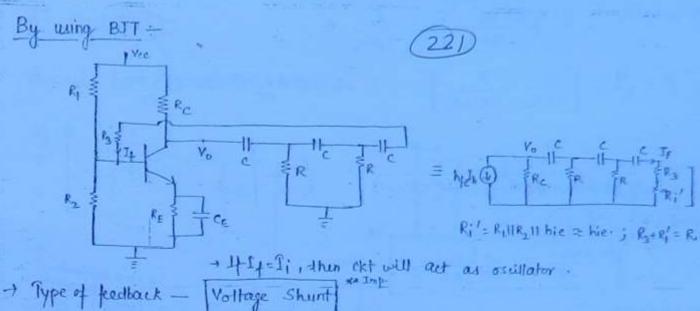
=)  $\frac{R_{+}}{R_{1}} = 29$   $\Rightarrow$   $R_{+} = 29R_{1}$ 
 $\Rightarrow \frac{Imp}{R_{1}}$ 

By Using FET :-



- Voltege Series FB

-> Cordition for oscillation :- | Apl=1



$$f_0 = \frac{\omega_0}{2\pi} = \frac{1}{2\pi Rc J_{4K+6}} ; K = \frac{Rc}{R}$$

-> Putting |Ap|=1; | he = 4K+23+29 |

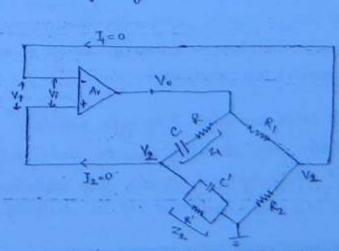
→ Diff wirt K, dhe =0 => | K= 2.7 | hfemin = 44.54

#### Note

- ) An FET with  $\mu < 29$  cannot be used in RC phase shift orullator.
- As The with small signal CE short cht current gain, ie, he less than 14.54 carnot be used in this oscillator.
- or RC phase shift oscillator is considered as a fixed peg-oscillator since to - change to, we have to change value of R&C of all three certions simultaneously, but this is practically very difficult

Wein Bridge Oscillator !-

If Vi=14, then ckt acts as an oscillator



→ 
$$V_f = V_2 - V_1$$
 ;  $\Rightarrow V_f = \frac{z_2}{z_1 + z_2} V_0 - \frac{R_2}{R_1 + R_2} V_0$ 

$$P = \frac{V_{f}}{V_{o}} = \left[\frac{z_{2}}{z_{1} + z_{2}} - \frac{R_{2}}{R_{1} + R_{2}}\right] \qquad ; \quad Z_{2} = R' \prod_{s \in C'}; \quad Z_{1} = R + \frac{1}{Cs}$$

) 
$$Z_2 = R' \prod_{s \in C'}$$
 ;  $Z_1 = R + \frac{1}{c.s}$ 

$$\beta = \left[ \frac{\omega R'C}{\omega \left( RC + R'C' + R'C' \right) - j \left( 1 - \omega^2 RR'CC' \right)} - \frac{R_2}{R_1 + R_2} \right]$$

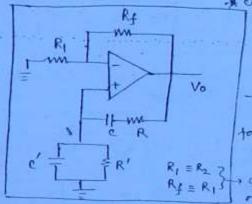
$$\Rightarrow \int_{2\pi} \int_{2\pi} \frac{1}{2\pi \sqrt{RR'CC'}} = \frac{1}{2\pi \sqrt{RR'CC'}} = \frac{1}{2\pi \sqrt{RR'CC'}}$$

\* Neck workbook Que 1 (convertino

Putting we in p -

$$\beta = \left[ \frac{R'C}{RC + R'C + R'C'} - \frac{R_2}{R_1 + R_2} \right]$$

$$\Rightarrow \beta = \frac{1}{|A_V|} = \frac{1}{\infty} = 0$$



Bridge ose-

 $R_1 \equiv R_2$  } analogus from  $R_1 \equiv R_1$ } analogus from

$$\Rightarrow \frac{R'C}{-RG+R'C+R'C'} - \frac{R_2}{R_1+R_2} = 0$$

Condition - 
$$\frac{1}{3} - \frac{R_2}{R_1 + R_2} = 0 \Rightarrow \begin{bmatrix} R_1 = 2R_2 \end{bmatrix}$$

$$R_1 = 2R_2$$

- An oscillator circuit in which a balanced bridge is used as a feedback now is called wein bridge oscillator.

> Advantage: It is a variable freq type oscillator

- Better freq. stability due to wein bridge.

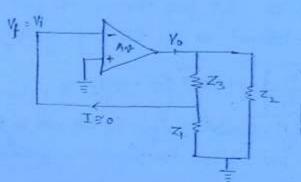
- Application - 1) Popularly used audio freq oscillator

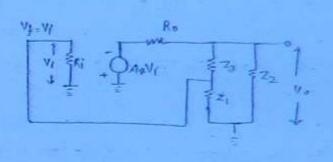
27 As a master oscillator ckt in designing of signal generator

#### RF ascillator :-



General form of oscillator circuit :-





$$\begin{array}{ccc}
 & \forall_f = \frac{z_1}{z_1 + z_3}, \forall_0 & \Rightarrow & \beta = \frac{\forall_f}{V_0} = \frac{z_1}{z_1 + z_3} & -3
\end{array}$$

$$\rightarrow$$
 Overall gain,  $Av = \frac{V_0}{V_i}$ 

From equivalent ckt, 
$$V_0 = -Av. Vi. Z_L$$

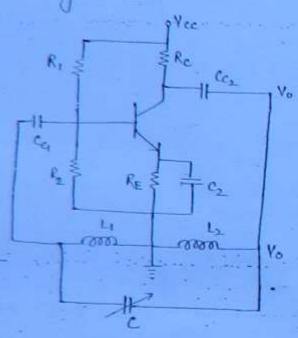
$$Ro + Z_L$$

Now, 
$$AVB = \frac{-AV.Z_L}{R_0 + Z_L} \times \frac{Z_1}{Z_1 + Z_3}$$

for freq. oscillation, 
$$J_m = 0$$
  
 $\Rightarrow X_1 + X_2 + X_3 = 0$ 

$$A_{\nu} \beta = \frac{A_{1} x_{1} y_{2}}{-y_{2}(x_{1} + x_{3})} = \frac{-A_{1} x_{1} x_{1}}{(x_{1} + x_{3})}$$

## Hartley Decillator:



$$z_1 = \int_{0}^{x_1} \omega L_1$$
;  $z_2 = \int_{0}^{x_2} \omega L_2$ ,  $z_3 = \int_{0}^{x_3} U^{x_3}$ 

Freq. of oscillation:  

$$x_1 + x_2 + x_3 = 0$$
  
 $\Rightarrow \omega u_1 + \omega u_2 - \frac{1}{\omega} = 0$ 

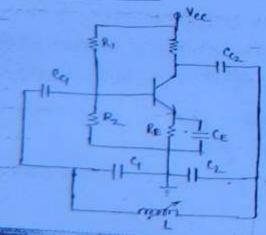
$$\Rightarrow \omega = 2\pi f = \frac{1}{\sqrt{(L_1 + L_2) \cdot c}}$$

$$= \frac{2\pi \sqrt{(r_1+r_2)c}}{\sqrt{(r_1+r_2)c}}$$

Condition for oscillation:

$$A \otimes > \frac{X_{2}}{X_{1}} \Rightarrow A \otimes > \frac{L_{2}}{L_{1}}$$

## Colpitt ascillator:



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$$z_1 = -j/\omega c_1$$
,  $z_2 = -\frac{j}{\omega c_2}$ ,  $z_3 = j\omega L$ 

$$\Rightarrow \omega = \frac{1}{\sqrt{L.GC}};$$

$$\Rightarrow \omega = \frac{1}{\sqrt{\frac{C_1 C_2}{C_1 + C_2}}}; f = \frac{1}{2\pi \sqrt{\frac{C_1 C_2}{C_1 + C_2}}}$$

Correlation: 
$$Au > \frac{x_1}{x_2} \Rightarrow Au > \frac{c_1}{c_2} - Imp (225)$$

Common Points :

-) They are variable freq. type RF oscillator - Working frinciple is no proubled resonance.

Hartley Occillator

-> H is also called Papped inductor type oscillator

Advantage: Capacitive tuning, ie, no wear & tear friblem.

Disciduantage! Bulky & expensive because of two inclustors

Applications: 1) In designing of boal oscillator ext in receiver

Collitt Deullator

- It has better freq. stability and it is obtained by reducing net capacitance of modified tank ext.

Ceq = c,c2 ; Q = 1 ; as ct, Qt a stability T

Achantage:

It is smaller in size and economical

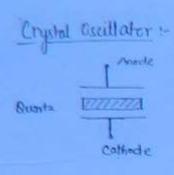
Disadvantage :- Industric Tuning, ie, wear & lear Broblem

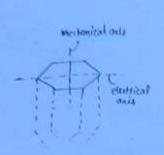
Application :- ) As a local oscillator in receiver

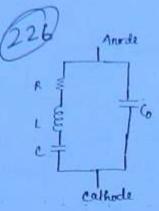
Claff Oscillator:

It is a modification of estill ose where variable inductor is replaced by a variable capacitor C3 in series with an industor & and of is inductively obtained.

tworking principle & series resonance, therefore  $f_0 = \frac{1}{21TJLC_3}$ 







It internal toxics or viscusus daming

Ac equivaent circuit

, lo = capacitance b/w mode & cathode plate.

Series resonance :- Due to RLC en series .

-Impedant => minimum.

$$\Rightarrow \boxed{fs = \frac{1}{2\pi \int Lc}}$$

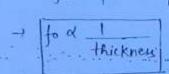
Parallel Resonance -

- impedance marinum

fp>fs , and freq of oscillator varies blw fs and fp.

frequery of sullation

-> fo depends of li, b, t -> Physical dimensions



on higher frequencies, crystal become weak.

-) It is a fixed frequency type RF oscillator.

- It works on faminable of piezoclectric effect.

- It has two resonating freq. , ies for 4 fp. Oscillating frequencijas lies b/w for 4 fp.

- Due to high quality factor a of a resonance ckt, it fororides very good forg stability

- freq. of osculation, generated by crystal depends on its physical dimensions but mainly on thickness.

- on high frq., t should be small but it makes appeal mechanically weak.



Disadvomtage !
- Almed freq type oscillator.

Application : 1) To generate carrier in AM & For transmission.
2) In designing of timer circuit.

Frequency Stability 
- freq stability of an oscillator is measure of its ability to maintain as

rearry a fixed freq as possible over as long a time unknown as possible

- It do is small change in phase angle and corresponding freq change is of, then

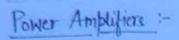
do - figure of ment and its value should be high.

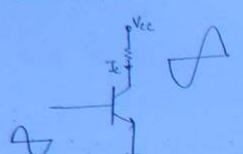
Theally, do do

Inverting of amp is preferred as compared to reminverting as it has p now which is adaptable due to freq change, ie, when of changes due to temp variations, B NW will adjust the its phase so that overall change in preg. is very small.

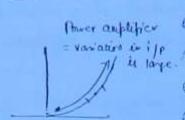
$$df = f_5^{\dagger} - (+f_5^{-})$$
  
 $d0 = 90 - (-90) = 180$ 

$$\frac{d\theta}{dt} = \frac{180}{fe^{t} - fe^{-}} = \frac{180}{0} = \infty \text{ (ideal) for enjetal with above$$





Pole = Vac- Tdc = Vec-Tca.



I) It is last stage in multistage amplifier.

2) Power amplification is defined as ability of amplifier to convert available of de power into ac signal fower with the application of i/p signal.

Small signal Amp.

→ i/p signal amplitudes are

very small (µv or mv)

- operated only in linear region
- Important specifications are-
- Analysis of amp. will be done by using graphical as well as mathematical analysis
- graphical as well as mathematical analysis

- Large signal Amp.

  Ip signal amplitudes are very large, (> 1V)
  - -> operated both in linear 1 nonlinear (
    region of i/p charc. curve. (
- Important specifications are power conversion efficiency of de spower available at ofp ac ...
  - distortions at op.
    - by only graphical analysis

- Transistris used in power amp are called fower tri

- Power amplifiers are designed mostly by BiT & they are generally in character

Harmonic Distortion :

to a power amp, signal auxitudes are very large, hence agral is

operated in linear & non-linear postion of its charac curve, so we get harmonics in ofp& harmonic distrition is present at ofp. Hamonic distribion is a non-timear distribion. (June) constant fourier series expan of collector current of power translictor: -> Lc = Ic + Bo + By cos ws + + By cos 2 wt + ---> wt, Amplitude 1. -) 2nd Hammic distribion - D2= B2 -  $P_3 = \frac{B_3}{B_1}$ , AC power of o due to fundamental component Pac = Imis . Ro = (B1)2. Ro. {= P1} - Notal Harmonic Power- (THP)-PT = B12. R0 + B2. R0+  $\frac{3}{2} \cdot P_{T} = \frac{B_1^2}{2} \cdot R_0 \cdot \left[ -1 + \left( \frac{B_2}{B_1} \right)^2 + \left( \frac{B_8}{B_1} \right)^2 \right] \cdot \cdots$ => PT = P1 [1+ D2+ D3+ ---] Total Harmonic Distortion (THD)-D= 12+D2+ -PT = P, (1+D2) - (mp) for THD = 101., D=0.1 PT = P1 (1+0.01) = 1.01. P1 + PTEP, ie, if THP is Kept < 101, then THP is almost equal to fundamental power. © Wiki Engineering

Thermal Runaway:



No themal

The process where a transistor is subjected to self destruction due to excess heat produced in CB junch

-) It is due to Ico.

→ BIT suffers from thermal minaway. In FET there is no thermal minaway.

Condition to eliminate thernal runaway:

$$\frac{dP_{c}}{d\tau_{j}} \leq \frac{1}{8}$$

, Pc = max. collector power dusipation in W. Ti = june" temp. at collector juc"

0 = Thermal resistivity in (O should be small)

=> T-TA = OPD TA = ambient temp.

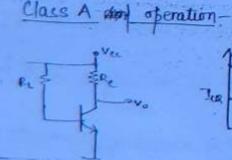
- Area of collector 1., 0.4.

$$1 - 0 = 0 \frac{dP_0}{dT_j} \Rightarrow$$

. Rate of heat dissipation in atmosphere.

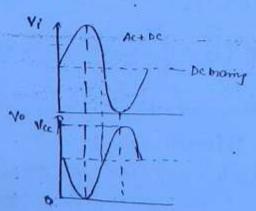
°C/watts.

Classifications of Amplifiers:

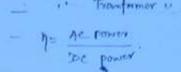


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Cond on the = 21 Peak topeak Tc. = Vec



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-> Collector current flows for entire 360" of ilp signal; anduch angle = III

-> Q point is located at center of all load line (23)

Advantage 1 - - Minimum dictortion

-1 Excellent thermal stability, ie, no thermal runaway froblem

Disadvantage: - Small power conversion efficiency

- Reduced power gain, - Introduces Power drain - When signal is not applied, transistor is concurring more power & it is called power drain. When signal is applied, to is using less Power.

Application : - designing of audio page amp.

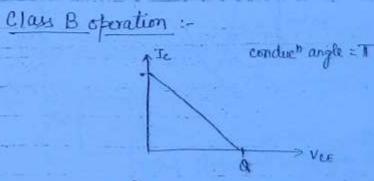
Note - class A amplifier is always designed with a single amplifier, ie, single ended ie, one Tr. per stage.

-) Power rating of transformer Rolman) -> maximum allowable heat alissipation, is defined at norm temp, ie, 2000.

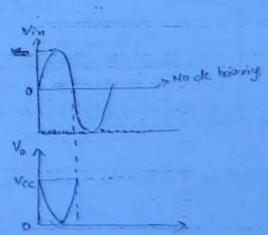
- In clase A operation, power dissipoted by Tr is equal to man signal power

- for class A; . Po = Pomax ; ie, man: power ofp.

for To design a class A amp with 2000 ofp signal power. It must dissipate 2000 of power.



Icq=0; a atcutoff.



- collector current flows exactly for 180° of if signal

(232)

- A point is located at substite.

- It is a double ended amplifier, i'es two tromsister in one stage.

Advantage : - Higher efficiency (78-5 %)

- Power drain is eliminated.

Disadvantage :- - Higher distortion

- Thermal stability is less.

- Introduce crossover distortion (co)) - major disadvantage
Application: - used in designing of Power amp., for ex, push-pull

power amp, complementary symmetry push full fower amp.

- When signal is applied, Tris consuming power & when signal is about, Tr. will not consume any powers, therefore no power drain.

- Power dissepted by single Tr. in ext,

PD = 0.2 Pomore. Pomore = mare ofp signal former.

Power dissipated by iruit, ie, by two tr.

PD = 0.4 Poman.

for eg, to design a class & amplifier, with 20W of signal power, power dissipated by single transistor should be 4W.

Llass AB operation:

Cond'

Pistorhion 1

Eltrainey 1

Cond' 2 V

(a print)

AB

Vea

cond angle - 180< \$<360

De book

T

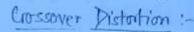
I point is located in active region but very close to cutoff point.

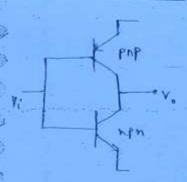
- Aldortion & notice interference is more as compared to class 1 & less when compared to class B.

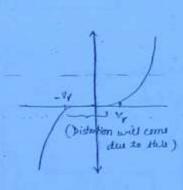
-) at it used in power amp for ex. push full power amp. (

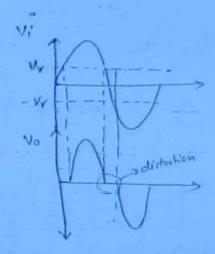
-) The main advantage of class AB operation is it eliminates cop.

- Max. efficiency is approx. 60%.









It is a distration arising then conduction transfer from one to to other.

7 It is a non-linear distortion

- It is due to operating the signal over non-linear charac curve.

-+ Class & introduce cob. and class AB eliminates cob.

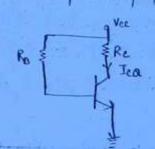
-1. The most suitable remedy to minimise cod is to use go Tr. in

place of Si Pr. But this will reduce power tondling capability of

12/09/2012

\_\_ Class A ambigier :-

Direct Coupled Amplificr :-



De Power :- Pole = Vde . Ide

$$\Rightarrow P_{dc} = V_{cc} \cdot I_{cm} \Rightarrow P_{de} = \frac{V_{cc}^2}{2R_c}$$

$$\underline{\underline{Peak}} \qquad \underline{Pac} = \underline{\underline{Vp}} \cdot \underline{\underline{Tp}} = \underline{\underline{VpTp}} = \underline{\underline{VpTp}} = \underline{\underline{VpTp}}$$

Peak-Rook Pac = 
$$\frac{V_{P-P}}{2J_{2}} \times \frac{T_{P-P}}{2J_{2}} = \frac{V_{EF}, J_{P-P}}{8} =$$

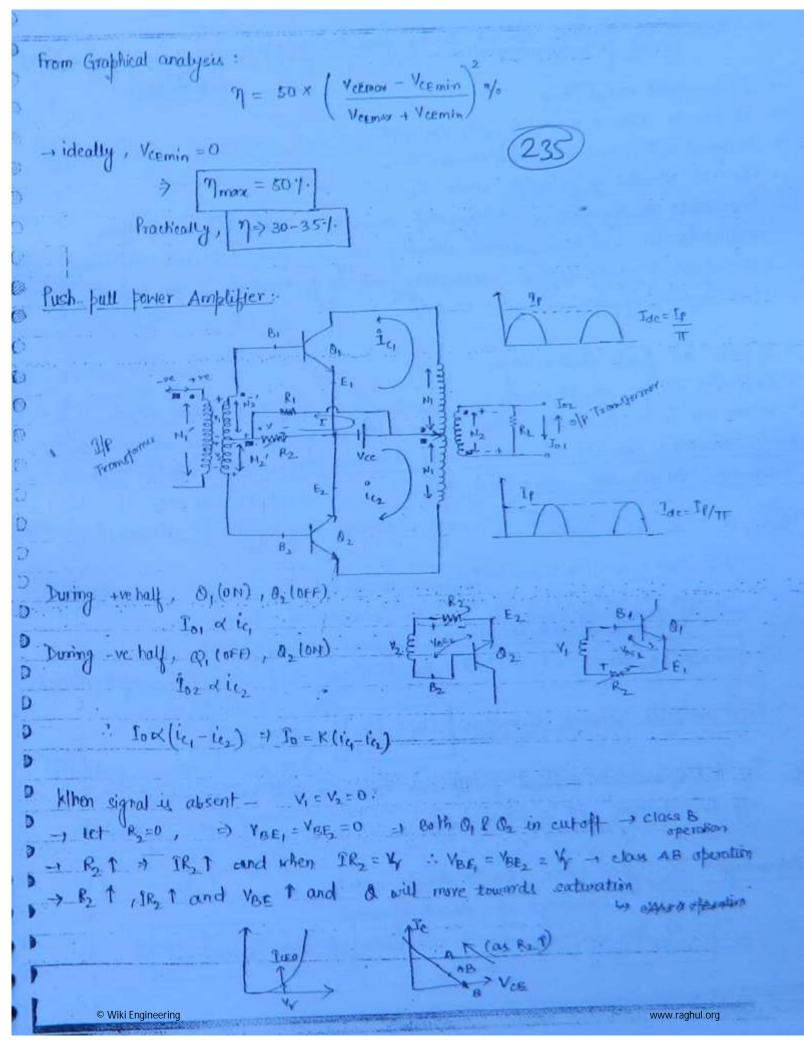
Efficiency: 
$$\eta = \frac{P_{AC}}{P_{bc}} \times 100 \Rightarrow \eta = \frac{V_{P-P}/8R_L}{V_{Ce}^2/2R_L} \times 100$$

Transformer Coupled Amplifier:

$$\frac{V_1}{V_2} = \frac{H_1}{N_2} \quad \Rightarrow \quad \frac{q_2}{T_1} = \frac{N_2}{N_2}$$

$$\frac{V_1}{V_2} = \frac{H_1}{H_2}$$
 ;  $\frac{q_2}{T_1} = \frac{H_2}{H_2}$  ; Rept = optimum resistance or reflected resistance,

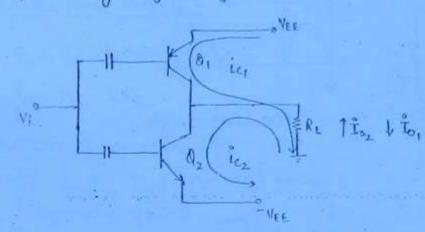
Riopt = 
$$\frac{V_1}{I_1}$$
 = ;  $R_L = \frac{V_2}{I_2}$  = 9  $\frac{R_{Lopt}}{R_L} = \left(\frac{N_1}{N_2}\right)^2$ 



-) Iceo is the stand by current during class AB operation.
· (256)
→ It is double ended amp.
I can be class Bor class AB operated.
-) Designed with identical transformers. Tr.
- The ext operates in class B when R2=0.
- ) for class up operation, vo Hage drop across to is adjusted to be offere.
equal to Vy , where a small stomdby current flows at zero exicitation.
- The funct of centre tapped secondary only of ilp transformer is to provide
two equal & opposite voltages V1812.
> V1 & V2 are push feel voltages
-) Bith the Tr. are in 15 mode.
a lathon one I is in a the other is in satoff
- of Dement consists of only odd harmonic terms since of I, even
harmonic terms are cancelled out.
(county)
Post => " Io = K (ic, -ic) (6 mortes)
ic = ba+ B1 (os (w++11) + B2 cos 2/w++11)+
= B = B, worwst + B2 worzwst +
: 10 = 2K (B, For wt + B3 was sult + Byrostiet+)
Expt available harmer district   No 18 all / www. 101
> First available harmonic distortion , by =   By   = (very small)
se It 0, 1 are not identical, then even harmonics will be present in
olp & distortion will be longe.
o/p
Advantage: 1) Higher power due to double ended. 2) " Efficiency if class & operated 3) less distortion due to concellation of even formunics.
2) " Efficiency if class B operated
3) less distortion due to concellation of even formunica.

Disadvanlage: Very bulky & highly expensive due to requirement of bulky transformer.

# Complementary - Symmetry Push Pull Power Amplifier :-



For  $V_1>0$  -  $0_1=0$  For  $V_1<0$  -  $0_2=0$   $0_1=0$  For  $V_1<0$  -  $0_1=0$  For 0 -

- It is double ended amplifier designed with matched pairs of Tr.
- Popularly used Power, amp ckt.
- Always chis sperated,
- Both Tr. are in CE mode.
- options its of only odd harmonic terms.

Advantage: - - same as bush full. 8 amplifier.

- circuit is smaller in size & economical due to climina

tion of bulky transformer.

Disadvantage: - Requires true power supply - introduces cos

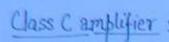
Efficiency: 
$$\eta = \frac{Pac}{Pdc} \times 100 \%$$

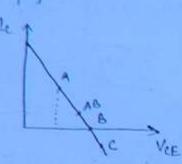
$$P_{ac} = \frac{V_{p^2}}{2R_L}$$

$$\therefore \boxed{\eta = \frac{11}{4} \times \left(\frac{V_p}{V_{cc}}\right) \times 100^{\circ}}.$$

Pole = 
$$\frac{V_{cc} \times \frac{T_P}{TT}}{TT} + \frac{V_{cc} \times \frac{T_P}{TT}}{TT} = \frac{2V_{cc} \times V_P}{TTR_L} - \frac{V_{cc} \times V_P}{TT}$$

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$$\frac{\zeta_{\Gamma}}{T} \times 100 \text{ } 7. = D$$

-> Power dissipation across Fr. during Ep-

- Energy dissipation avoss Tr during tp-

- Avg. power dissipation during one cycle:

$$P_{\text{bavg}} = \frac{E_{\text{D}}}{T} = \frac{P_{\text{D}} \cdot T_{\text{P}}}{T} \Rightarrow P_{\text{bavg}} = P_{\text{D}} \cdot D$$

Class D Amplifier:

- They are special amplifier designed to operate with digital fulse signal. - Efficiency of class Dis above 90%.

I I is not a power amplifier.

- widely used in commercial application

-) conduction angle < 180°

- Distortion is very high.

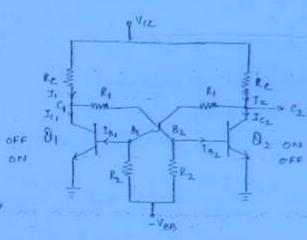
# Multivibrator by ming Transistors:

2,39

Bistable Multivibrator\_

$$V_{c_1} = V_{cc} - I_1 R_c$$

$$V_{B_2}$$
,  $I_{B_2}$ ,  $I_{C_2}$ ,  $I_{C_2}$ ,  $I_{C_2}$ ,  $V_{C_2}$ ,  $V_{B_1}$ ,  $V_{C_2}$ ,  $V_{B_1}$ ,  $V_{C_2}$ ,  $V_{C_3}$ ,  $V_{C_4}$ ,



-> Finally 0, in saturation and 0, in cutoff.

$$Q = V_{c_2} = V_{cesot} = 0 \quad ; \quad \overline{Q} = V_{c_1} \cong V_{cc} = 1 \ .$$

When a -ve fulso is applied-

finally of in cutoff & of in saturation -

When O2 = on; &1 = off - - , O, should be well in saturation & O, should be well in culoff.

0

5

þ

$$V_{e_1} = \frac{V_{cesat} R_2}{R_1 + R_2} = \frac{V_{ab} \cdot R_1}{R_1 + R_2}$$

$$V_{e_1} \approx 0 \quad \text{when } V_{ab} \approx 0.0 \Rightarrow \frac{N_{abse}}{N_{abse}} = \frac{0.5}{10}$$

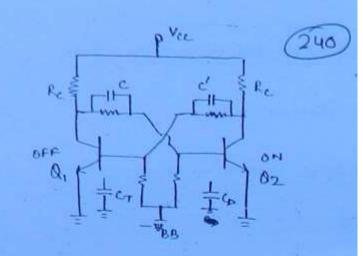
Commutating Capacitors - (C&C')

→Grace transition & diffusion capacitonics of onlock Tr. respectively.

- csc' are speed up capacitors.

- exc' - very small

- Due to cle' - I in transition time or In propagation delay.



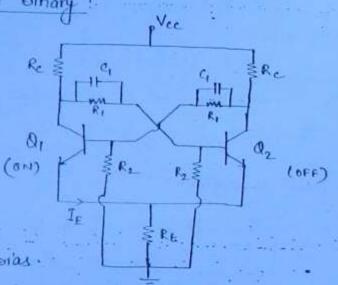
Self Biased Binary / Emiller Coupled Binary :

SEF but there will be drop across Re se ve due to It in on Tr.

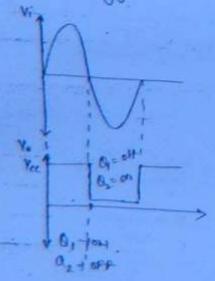
and it min. voltage regd. to on a de is at least (VE+0.5) and hence

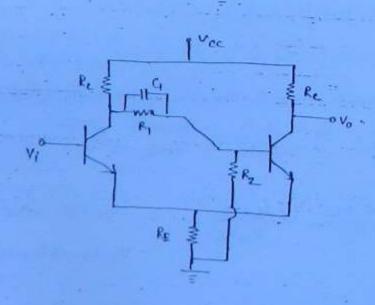
- Ver is not required in this cht.

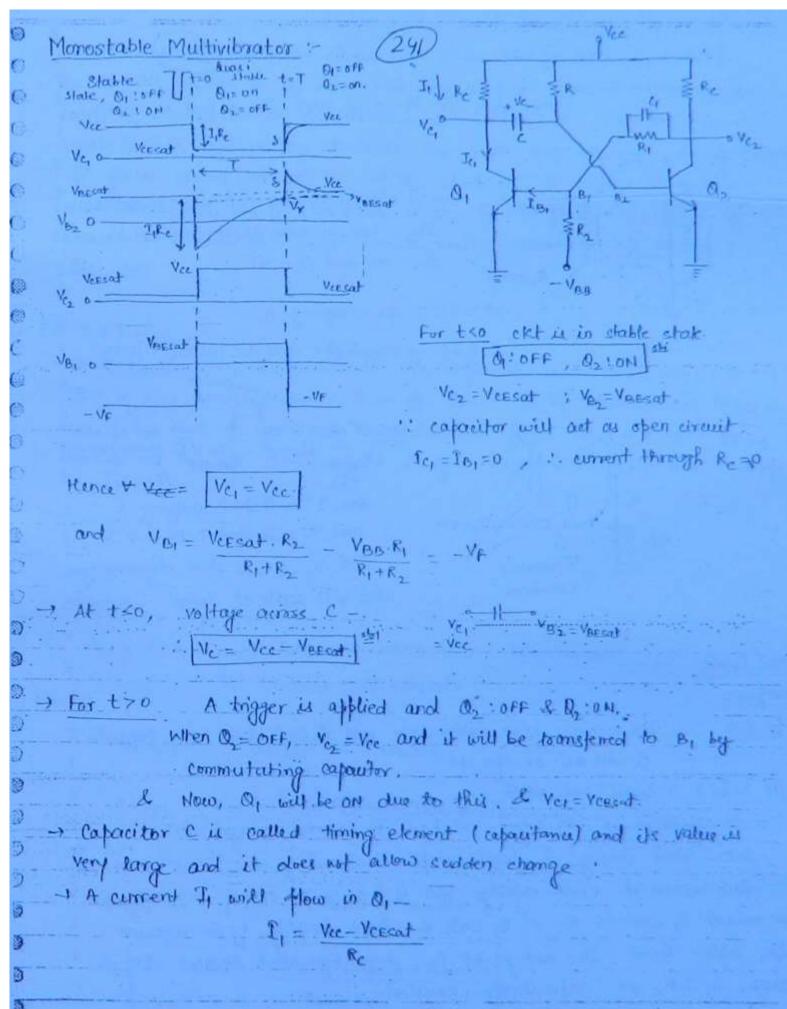
- Other operation is same as fixed bias.

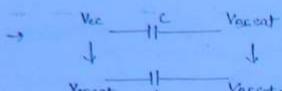


Schmitt Trigger :





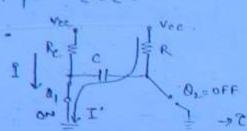




242

Vercat C Vercat-IR, => Vor << 0 and Q2 is well in cutoff.

- Now, for ostst-



I'will start charging capacitor towards

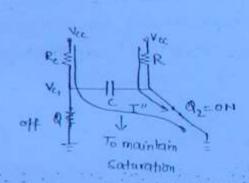
Vec , but as soon as it reaches by

On = on and On = OFF

-> T= RC = -for charging C.

Rec - very high, and are called timing

for t>T
At t=71,



Vegent (S>> Vy)

None, I'' will start changing C

and Vo, will start discharging and vy + 8 will start discharging and vy + 8 will start discharging and vy + 8 will start discharging and will settle at VBEsat. (see graph)

Important Points:

2 Waveform -

to to :- The circuit is in stable state with O2 (ON) & O2 (OFF) Capacitor

C will act on open cht.

for OSTET + Quasi Stable state.

- On application of -ve trigger, at t=0 -to base B2, a regenerative action takes place driving Q2 below entoff. How voltage at C2 vises to Vcc laps and because of cross coupling blow G&B1, Q1 comes into saturation.

- Now current I, exist in Rc of Q1 and Vc, drops abruptly by an amount the lipto Vccsot. The voltage at B2 drops by some amount IRe since C1&B2 are capacitively coupled.

- Now the multivibrator is in Quasi stable state with Q, (on). Q, 1888).

- The ett rull remain in Qs etate for only a finite time T because 240 have be is connected to Vee through a resistance R, therefore Vez starts to rise exponentially towards Vec with time constant RC & when it passes cutin voltage Vr of Q2 at t=T, a regenerative action will take place as a result of which Q, will go into cutoff & Q2 comes into emduction and multivibrator octums to its initial stable state.

#### For toT-

- At t=1t, 01=0ff, 02= conductors. Vez drops to Vessat. Vez returns to - VF Now Vez rises abruptly since 0, is eff. This 1 in Vez transmitted to base of 02 and 02 goes into oversaturation. Hence an overshoot & develops in VB2 at t=1t which decays as End the capacitor-recharge

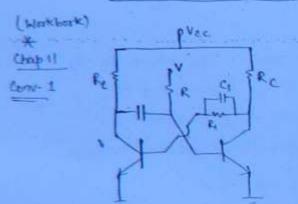
## Derivation of T:

$$V_{cc} - (v_{cc} - v_{BESQ} + V_{cc} - v_{cesat})e^{-t/Rc} = V_{B2}$$

$$V_{B2} = V_{cc} - [2v_{cc} - (v_{cesat} + v_{Besat})]e^{-t/Rc}$$

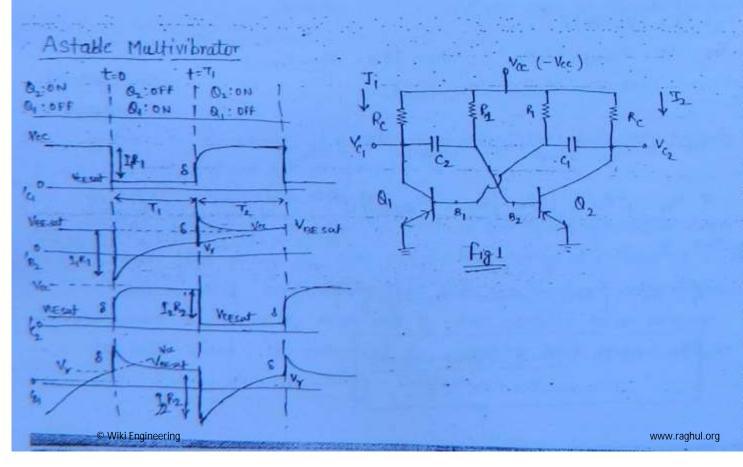
$$\Rightarrow T = R(\ln 2 + R(\ln \frac{V_{cc} - \frac{V_{BE}sat + V_{creat}}{2}}{V_{cc} - V_{r}})$$

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In the above derivation change

Diagram for voltage controlled f (or T)



for too 01:0FF 1 0:00 Vc = Vcesat ; VB2 = Vcesat 10, = 10, =0 ; VC, = Vcc & VB, <0. - Guill charge & Vert till Vr. & then states will change with sudden change in Vox & Vax. for osts Ti - Broff; Of 10H Now Cowill starty charging 2 similar process as above will be repeated. -> for p-n-p Tr 100 02: IFF D1 : 014 a, : OFF 0, : OFF + Vereat + VBE sat VCEAT VCESOF Vec Vce Vacsat © Wiki Engineering www.raghul.org

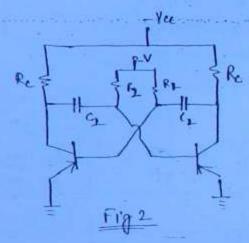
$$f = \frac{1}{T} = \frac{1.44}{R_1 c_1 + R_2 c_2}; \quad \text{if} \quad R_1 = R_2 = R \quad R \quad q = c_2 = c$$

$$\text{For asymmetrical sq wave} \quad \text{then} \quad T = 1.38Rc$$

$$\text{For symmetrical sq wave} \quad \text{for symmetrical sq wave}$$

$$T_1 = R_2 c_2 \ln \left( 1 + \frac{\sqrt{cc}}{v} \right)$$

$$T_2 = R_1 c_1 \ln \left( 1 + \frac{\sqrt{cc}}{v} \right)$$



Important Points for Astable Multivibrator :-

Waveform (Pmp)

for to 0, : OFF , 0, : ON

tence, for t <0, Voj = +Ve, Voj = -Vec, VB2 = VBESAt, Voz = Vocesat + Copacitor C1 charges through R12 VB, falls exponentially towards - Vec. At t=0, V, neaches cutin voltage Vr and a conducts. As a goes to extension, Vc1 rises by IRC with VcEsat. Rise in Vc1 causes equal tise IRC in VB2 since B2 and C1 are capacitively conflict.

Rise in VB2 cuts off Q2 and its collector falls towards - Vce. This fall in Vc2 is coupled through apacitor (1 to have B1 causing undershoot S. in VB1 and abrupt amount of by same amount 5 in Vc2.

The voltage  $V_{B2}$  is  $V_{BESSAT} + I_1R_C$  at  $t = 0^{+}$  and b exponentially with time constant  $R_2C_2$  -lowerds - $V_{CC}$ .

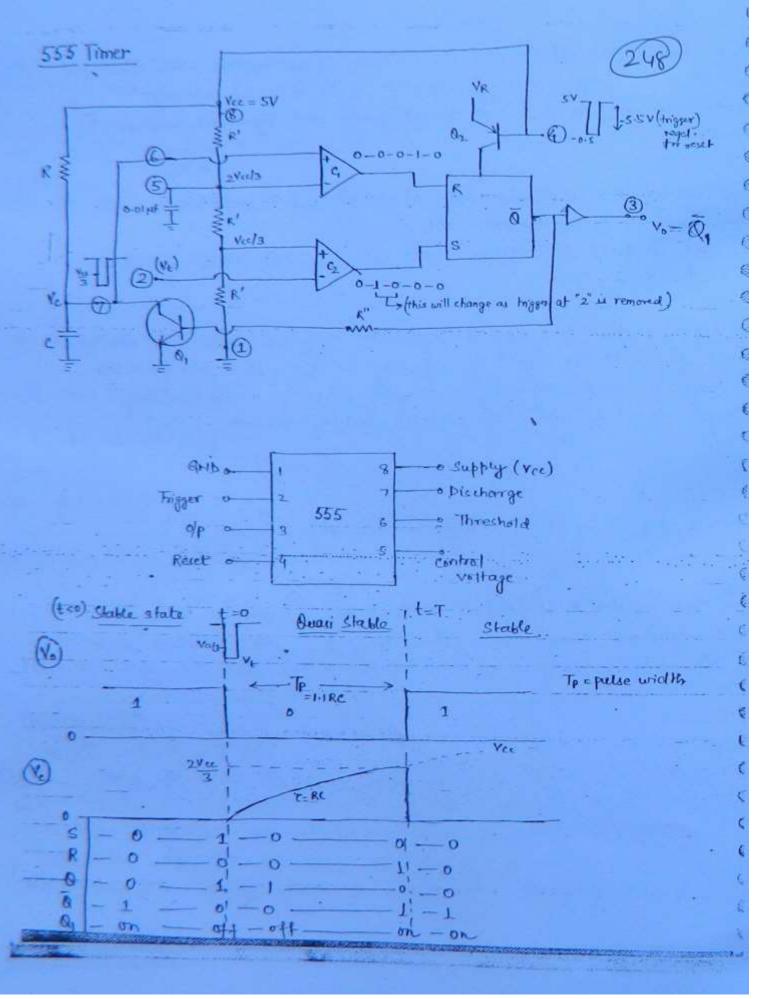
At t=T,; base B2 reaches cutin level by and reverse tromsition takes place

In fig(1), the frequency of oscillation may be voised over the range from Hz to MHZ by adjusting R or C. It is also possible to change T electrically by emmedting R1 f. R2 to an awillong voltage -V (fig.2) (The collector supply remains -Vcc). then,

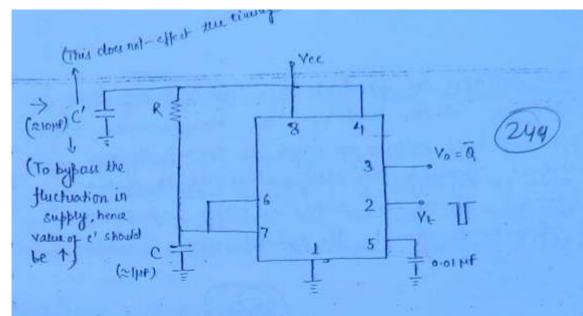
T = 2RC la ( 1+ Yee ).

Such a ckt (fig 2) is voltage to pequency converter.

- It each resistor R (RISR) is replaced by a Fransistor which acts as a constant current source for charging a then excellent sinearity by freq. I voltage may be attained.



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#### 555 in Monostable Mode

$$\underline{At \ t = T_P -} \qquad \underline{2V_{CC}} = V_{CC} \left(1 - e^{-\frac{T}{R}C}\right)$$

The device 555 is a monolithic timing ckt that can produce occurated by highly stable time delays or ascillations.

#### Constructional Details:

The device crossists of two comporators (C12C2) that drive set I reset terminals of a flip flop which interm controls on & ope cycles of discharge tr Q1.

by means of a voltage divider made up of three series resistors R. These reference voltages are regd to control timing.

Timing can be controlled externally by applying voltage to control voltage terminal (pin 5). If no such control is read, pin 5 can be byfassed by a capacitor to ground. The typical value is about 0.014f.

## function :-

- When we voltage is applied at trigger terminal goe grows -ve & passes through reference level  $\frac{Vec}{3}$ , the olp of of changes its state. This change of state (s=1, R=0) will set the flip flop with  $\tilde{a}=0$  &  $\tilde{a}=0$
- When voltage applied at threshold terminal (pin 6) grows the & poises through size, ofp of C1 changes its state (s=0, R=1). This change of state will reset the flip flop with (0=1 and Tr. Q1=01).

### PIN-4 (Reset Pin)

- A separate reset terminal is provided which is used to reset the fit externally. Hormally when Ain 4 is not used, it should be emnected to the suffly tick to avoid any false triggering. Pransistor On acts as a buffer, isolating the cut from false to reset.

## 555 timer in Monostable state :-

- For teo, ett is in stable state. Vt (trigger voltage) = Vec, Vo = Q = 1
- be high. This will set if with  $0 = V_0 = 0$  and  $0_1 = 0$  of  $0_2$  to

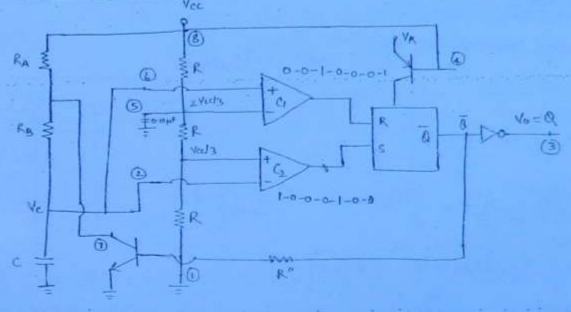
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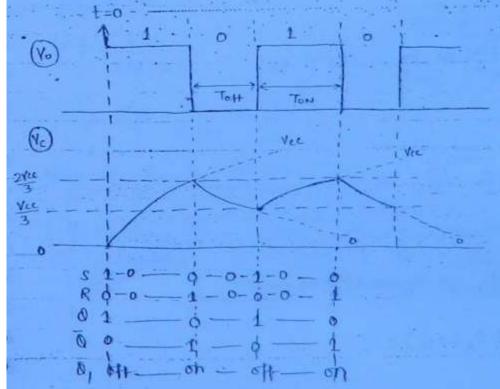
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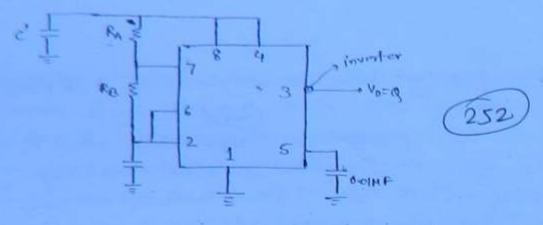
(since s=0, R=0). (25)

- Now, tirring capacitor c charges up towards ver with Z=RC- When Ver reaches threshold level of 2 Vec, c, will switch its state. This change of state (R=1, S=0) resets the ff. with a= Vo=1 and Q= orn. Then the state attraction resistance of discharges C suddenly 4 ckt reach to its initial state.

555 timer in Astable Mode







Astable Mode

## Derivation of Ton:

Capacistor charge from Vec to 2 Vec with C = (RATRB)C  $V_{f} = Vec, V_i = \frac{Vec}{3}$ 

At teton

## Derivation of Topy

Capacitor discharges from 2 vec to vec with 2= RBC.

Vi = 2 vec , Vf = 0.

At t = Toff-

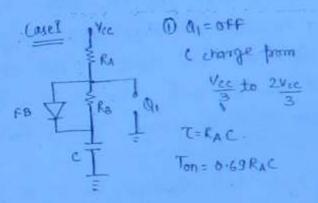
Ton > Toff => > 750%. => Asymmetrical sq wave.

D=50% - but RA cannot be a since pin 7 will be directly connected with Vcc and Fr. will bur

tixed to the state of the state

$$D = \frac{T_{on}}{T} \Rightarrow D = \frac{R_A}{R_A + R_B} \times 100 \text{ f}$$

Now if RA= RB . D=50%.



= Va if RALD

This sawlooth falls is achieved across capacitor and not on off.

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-) Boschiometer is provided in ofp as of duty eyele can be adjusted by changing Ralks. (also all diodes & resistor are not ideal and Rasks can be set accordingly to get symm.

A direct resistor is added to prevent pin 7 to directly connected

to voc even it potentionneter at RA is set at 0.

#### Important Paints:

For Fig (1)

In this mode, timing capacitor C charges up towards Ver through RA+RB. upto  $2 \frac{Ver}{2}$  then C1 switches its state. This charge of state (s=0, R=1) text the FF with Vo=0.0, Q=1, Q=0.0. Then capacitor C alischarges through RB f Q1 upto Vcc, then C2 switches its state. This charge of state (s=1, R=0) set the FF with Vo=0.0=1, Q=0 and Q=0.0. At this point capacitor stards to charge again, these completting the eyele

- Duty eyele will always be < or > 504. for fig 1). To achieve 504 duty yele we should make RA=0, thowever with RA=ON. for 7 is directly connected to + Vac and this may damage tro 9, is on.

In fig (1)—

Capacitor changes through RA and diode Dupto 2Vae and discharge through Re and Qi upto vec. Then cycle repeats.

tied resister & potentioneter to that potentioneter can be adjusted for exact sq. wave. Fixed resistor will avoid direct connection of pin 7 to vice when fotentioneter is set at 0.52.

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Tuing pin 5). We vanishing to the from Application 1) It is used as Frequentulator, ie. voltage to frequenter.
2) It is used as missing pulse defector.

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